

# TPS25772-Q1 車載用 デュアル USB Type-C® パワー・デリバリ・コントローラ、昇降圧レギュレータ付き

## 1 特長

- 以下の結果で AEC-Q100 認定済み:
  - デバイス温度グレード 1: 動作時周囲温度範囲: -40°C ~ +125°C
  - デバイス HBM ESD 分類レベル 2
  - デバイス CDM ESD 分類レベル C2b
  - 拡張コネクタ・ピン ESD 保護
- プログラマブル電源 (PPS) サポート付き USB パワー・デリバリ (PD) コントローラ
  - 広い  $V_{IN}$ : 5.5V ~ 18V (最大 40V)
  - 最大 65W の USB PD 出力電力をサポートする 4 つの統合型昇降圧パワー・スイッチ
  - $V_{BUS}$  出力: 3 ~ 21V,  $\pm 20mV$  のステップ・サイズ
  - $I_{BUS}$  出力: 0 ~ 3A,  $\pm 50mA$  の電流制限ステップ・サイズ
  - $V_{BUS}$  から  $V_{BAT}$  および GND への短絡保護
  - $V_{BUS}$  ケーブル・ドループ補償
  - MFi 過電流保護
  - スイッチング周波数: 300、400、450kHz
  - ディザリングによる DC/DC 同期入出力
- USB ポート構成オプション
  - 1 つの USB-PD ポート (TPS25762-Q1)
  - 2 つの USB-PD ポート (TPS25772-Q1)
- USB 準拠
  - USB Type-C® パワー・デリバリ・リビジョン 3.1
    - TPS25762-Q1: PPS、TID による USB-IF 認定: 9509
    - TPS25772-Q1: PPS、TID による USB-IF 認定: 9161
    - CC ロジック、 $V_{CONN}$  ソースおよび放電
    - USB ケーブルの極性検出
  - バッテリー充電仕様リビジョン 1.2
    - DCP: 専用充電ポート
- 従来型高速充電
  - 2.7V デバイダ -3 モード
  - 1.2V デバイダ・モード
  - 高電圧 DCP プロトコル
- マイコン・コア対応
  - ファームウェア更新
  - 複数の充電ポート間でのインテリジェントな電力共有
  - 電源電圧と温度によって動作が異なるパワー・マネージメント
- $V_{BUS}$  および  $V_{BAT}$  への短絡保護
  - $V_{BUS}$

–  $Px\_DP$  および  $Px\_DM$

–  $Px\_CC1$  および  $Px\_CC2$

- ウェットプル・フランク付きの HotRod™ QFN パッケージ

## 2 アプリケーション

- 車載用 USB 充電
- 車載用メディア・ハブ
- 車載用ヘッド・ユニット
- 車載用リアシート・エンターテインメント

## 3 概要

TPS25772-Q1 は、車載用デュアル USB ポート・アプリケーション向けの昇降圧コンバータを内蔵した完全統合型デュアル・ポート USB Type-C® パワー・デリバリ (PD) ソリューションです。4 つのパワー・スイッチを備えた統合型昇降圧コンバータ、ARM® Cortex®-M0、Type-C ケーブル・プラグおよび方向検出機能を備えた USB ポート・コントローラ、USB バッテリー充電仕様バージョン 1.2 (BC1.2) 検出、USB エンドポイント PHY、デバイスの電源管理および監視回路、コネクタ・ピンの過電圧および短絡保護などの機能が搭載されています。

インテリジェントなシステム・ポリシー・マネージャは、供給される USB 電力を最大化すると同時に、車載用バッテリーの過渡状態や過熱状態からシステムを保護します。

デバイス構成設定は、直感的なグラフィカル・ユーザー・インターフェイス (GUI) を使用して選択されます。

### 製品情報

| 部品番号        | パッケージ        | 本体サイズ     |
|-------------|--------------|-----------|
| TPS25772-Q1 | RQL (QFN-29) | 6mm × 5mm |





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## 4 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

| <b>Changes from Revision * (December 2022) to Revision A (September 2023)</b>                                                                    | <b>Page</b> |
|--------------------------------------------------------------------------------------------------------------------------------------------------|-------------|
| • TPS25762-Q1 および TPS25772-Q1 USB – IF 認定 TID を追加.....                                                                                           | <b>1</b>    |
| • ウェットابل・フランク・パッケージ情報を追加.....                                                                                                                   | <b>1</b>    |
| • Added TPS25762CAQRQLRQ1, TPS25772CAQRQLRQ1, TPS25762CQRQLRQ1, TPS25772CQRQLRQ1 comparison in Device Comparison Table.....                      | <b>4</b>    |
| • Added TPS25762CAQRQLRQ1 and TPS25762CAQRQLRQ1 R <sub>TVSP</sub> configuration settings.....                                                    | <b>37</b>   |
| • Added R <sub>TVSP</sub> Circuit Configuration for applications requiring a configuration other than TVSP Index 0 (R <sub>TVSP</sub> open)..... | <b>37</b>   |

## 5 Device Comparison Table

| PART NUMBER | Orderable Device  | Port A | Port B | Port A Output Power | Port B Output Power | Astable VIN Boot Support     | Configurable Boot Mode <sup>(2)</sup> |
|-------------|-------------------|--------|--------|---------------------|---------------------|------------------------------|---------------------------------------|
| TPS25762-Q1 | TPS25762CQRQLRQ1  | USB-PD | n/a    | 65 W                | n/a                 | VIN-dependent <sup>(1)</sup> | Yes                                   |
|             | TPS25762CAQRQLRQ1 |        |        |                     |                     | Yes                          | No                                    |
| TPS25772-Q1 | TPS25772CQRQLRQ1  |        | USB-PD | 65 W                | 65 W                | VIN-dependent <sup>(1)</sup> | Yes                                   |
|             | TPS25772CAQRQLRQ1 |        |        |                     |                     | Yes                          | No                                    |

1. Assured device boot up during astable VIN (e.g. cold crank) conditions when VIN oscillation minimum voltage is  $\geq 7.6\text{V}$  until boot is completed. Refer to application brief [TPS257x2-Q1 Startup with an Astable Supply Voltage](#).
2. Refer to [セクション 9.3.2](#).

## 6 Pin Configuration and Functions

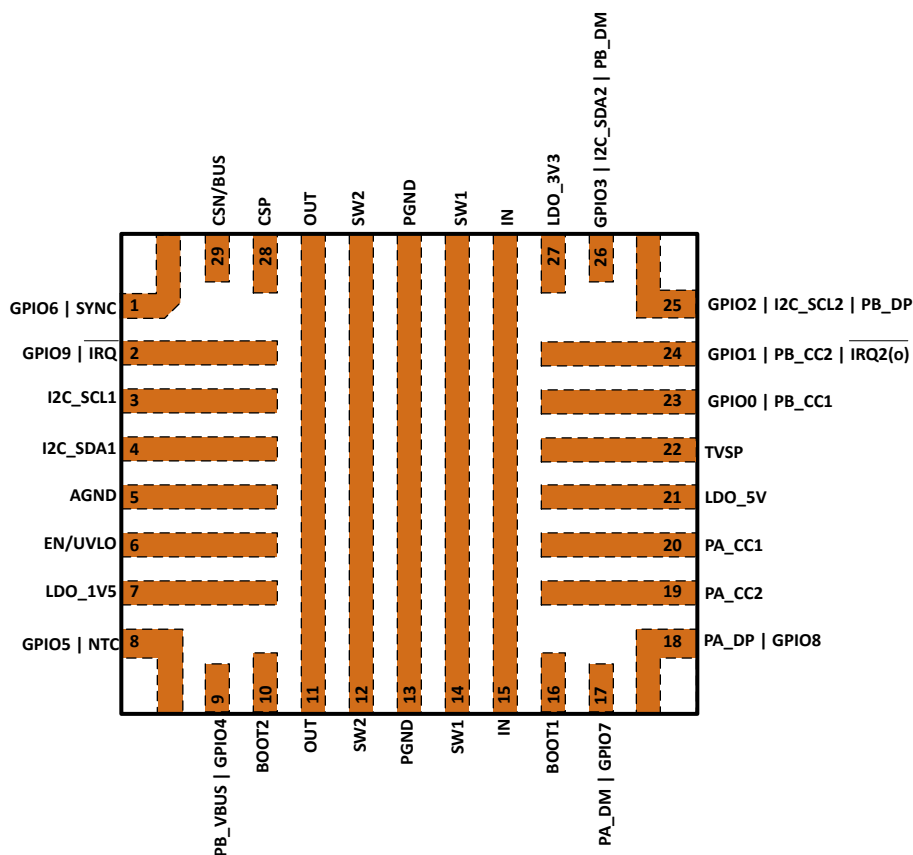


図 6-1. RQL Package 29-Pin (VQFN) Top View

表 6-1. Pin Descriptions

| PIN                         |     | DESCRIPTION                                                                                                                                                                                                               |
|-----------------------------|-----|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME                        | NO. |                                                                                                                                                                                                                           |
| EN/UVLO                     | 6   | Enable pin. For EN/UVLO < 0.3 V, the TPS25772-Q1 is in a low current shutdown mode. For EN/UVLO > 1.3 V, the full functionality is enabled, provided LDO_5V exceeds the LDO_5V UVLO threshold.                            |
| IN                          | 15  | The input supply pin to the IC. Connect $V_{IN}$ to a supply voltage between 5.5 V and 18 V (40-V ABS MAX transient).                                                                                                     |
| PGND                        | 13  | Power ground of the IC. The high current ground connection to the low-side gate drivers.                                                                                                                                  |
| SW1                         | 14  | The buck side switching node.                                                                                                                                                                                             |
| SW2                         | 12  | The boost side switching node.                                                                                                                                                                                            |
| BOOT1                       | 16  | An external capacitor is required between the BOOT1 and the SW1 pins to provide bias to the high-side MOSFET gate drivers.                                                                                                |
| BOOT2                       | 10  | An external capacitor is required between the BOOT2 and the SW2 pins to provide bias to the high-side MOSFET gate drivers.                                                                                                |
| AGND                        | 5   | Analog ground of the IC.                                                                                                                                                                                                  |
| OUT                         | 11  | Output of the buck-boost regulator. Connect to bulk capacitance.                                                                                                                                                          |
| CSP                         | 28  | Positive input of the current sense amplifier.                                                                                                                                                                            |
| CSN/BUS                     | 29  | Negative input of the current sense amplifier. This is the PA_VBUS supply.                                                                                                                                                |
| LDO_5V                      | 21  | Output of internal 5 V LDO for buck-boost low-side FET drivers, and Px_VCONN supply. Connect bypass capacitor to PGND. May be overdriven from external 5-V supply.                                                        |
| LDO_3V3                     | 27  | Output of internal 3.3-V LDO for analog circuitry and GPIO drivers. Connect bypass capacitor to AGND.                                                                                                                     |
| LDO_1V5                     | 7   | Output of internal 1.5-V LDO for digital circuitry. Connect bypass capacitor to AGND.                                                                                                                                     |
| I2C_SCL1                    | 3   | Controller I2C Clock Input/Output.                                                                                                                                                                                        |
| I2C_SDA1                    | 4   | Controller I2C Data Input/Output.                                                                                                                                                                                         |
| GPIO2 (I2C_SCL2 or PB_DP)   | 25  | Multifunction pin. GPIO; target I2C Clock Input; or Port B USB data line DP input depending upon firmware configuration.                                                                                                  |
| GPIO3 (I2C_SDA2 or PB_DM)   | 26  | Multifunction pin. GPIO; target I2C Data Input; or Port B USB data line DM input depending upon firmware configuration.                                                                                                   |
| IRQ (GPIO9)                 | 2   | Multifunction pin. Interrupt I/O and fault flag for I2C1 or I2C2; or GPIO depending upon firmware configuration. Reports fault conditions set by application configuration firmware.                                      |
| PA_CC1                      | 20  | Analog input/output. Port A Type-C current advertisement, VCONN, and USB PD modem. Connect to Port A Type-C connector CC1 pin.                                                                                            |
| PA_CC2                      | 19  | Analog input/output. Port A Type-C current advertisement, VCONN, and USB PD modem. Connect to Port A Type-C connector CC2 pin.                                                                                            |
| PA_DP (GPIO8)               | 18  | Multifunction pin. BC1.2 USB 2.0 D+ data line input/output. Connect to Port A Type-C USB data line DP connector pins. May also be used as GPIO depending upon firmware configuration.                                     |
| PA_DM (GPIO7)               | 17  | Multifunction pin. BC1.2 USB 2.0 D- data line input/output. Connect to Port A Type-C USB data line DM connector pins. May also be used as GPIO depending upon firmware configuration.                                     |
| PB_CC1 ( GPIO0 )            | 23  | Multifunction pin. Port B Type-C current advertisement, VCONN, and USB PD modem. Connect to Port B Type-C connector CC1 pin; May also be used as GPIO when port B is disabled in firmware configuration.                  |
| PB_CC2 ( GPIO1 or IRQ2(o) ) | 24  | Multifunction pin. Port B Type-C current advertisement, VCONN, and USB PD modem. Connect to Port B Type-C connector CC2 pin; May also be used as GPIO or Interrupt I/O when port B is disabled in firmware configuration. |
| GPIO5 (NTC)                 | 8   | Multifunction pin. GPIO; thermistor input (can use either negative temperature coefficient resistor or positive temperature coefficient resistor).                                                                        |
| GPIO6 (SYNC)                | 1   | Multifunction pin. GPIO; SYNC(o) - clock out to synchronize slave DC/DC regulators to internal DC/DC switching frequency; SYNC(i) - clock input to synchronize internal DC/DC to an external clock.                       |
| PB_VBUS (GPIO4)             | 9   | Multifunction pin. PB_VBUS voltage monitor; or GPIO when port B is disabled in firmware configuration                                                                                                                     |

**表 6-1. Pin Descriptions (続き)**

| PIN  |     | DESCRIPTION                                                                                                                                                          |
|------|-----|----------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| NAME | NO. |                                                                                                                                                                      |
| TVSP | 22  | Transient voltage protection and firmware setting pin. See <a href="#">表 9-4</a> for boot configuration. See <a href="#">表 9-3</a> for R-C network component values. |

## 7 Specifications

### 7.1 Absolute Maximum Ratings

Over the recommended operating junction temperature range of -40°C to 150°C and AGND = PGND (unless otherwise noted)<sup>(1) (2)</sup>

|                      |                                          | MIN  | MAX                | UNIT |
|----------------------|------------------------------------------|------|--------------------|------|
| Input voltage range  | IN <sup>(3) (4)</sup> to PGND            | -0.3 | 40                 | V    |
| Input voltage range  | IN with respect to SW1                   | -0.3 | 25                 | V    |
| Input voltage range  | EN/UVLO <sup>(5)</sup> to AGND           | -0.3 | internally limited | V    |
| Input voltage range  | BOOT1 with respect to SW1                | -0.3 | 6                  | V    |
| Input voltage range  | BOOT2 with respect to SW2 <sup>(6)</sup> | -0.3 | 6                  | V    |
| Input voltage range  | SW1 <sup>(7)</sup> to PGND               | -0.3 | 24                 | V    |
| Input voltage range  | SW2 <sup>(8)</sup> to PGND               | -0.3 | 24                 | V    |
| Input voltage range  | SW2 to OUT                               |      | 17.5               | V    |
| Input voltage range  | CSP to PGND                              | -0.3 | 24                 | V    |
| Input voltage range  | CSN/BUS to PGND                          | -0.3 | 24                 | V    |
| Input voltage range  | CSP to CSN                               | -0.3 | 0.3                | V    |
| Input voltage range  | AGND to PGND                             | -0.3 | 0.3                | V    |
| Output voltage range | OUT to PGND                              | -0.3 | 24                 | V    |
| Output voltage range | LDO_5V to PGND                           | -0.3 | 6                  | V    |
| Output voltage range | LDO_3V3 to AGND                          | -0.3 | 6                  | V    |
| Output voltage range | LDO_1V5 to AGND                          | -0.3 | 2                  | V    |
| I/O voltage range    | TVSP to PGND                             | -0.3 | 30                 | V    |
| I/O voltage range    | I2C_SCL1 to AGND                         | -0.3 | 6                  | V    |
| I/O voltage range    | I2C_SDA1 to AGND                         | -0.3 | 6                  | V    |
| I/O voltage range    | GPIO9, IRQ1 to AGND                      | -0.3 | 6                  | V    |
| I/O voltage range    | PA_CC1 to AGND                           | -0.3 | 30                 | V    |
| I/O voltage range    | PA_CC2 to AGND                           | -0.3 | 30                 | V    |
| I/O voltage range    | PA_DM to AGND                            | -0.3 | 30                 | V    |
| I/O voltage range    | GPIO7 to AGND                            | -0.3 | 6                  | V    |
| I/O voltage range    | PA_DP to AGND                            | -0.3 | 30                 | V    |
| I/O voltage range    | GPIO8 to AGND                            | -0.3 | 6                  | V    |
| I/O voltage range    | PB_CC1 to AGND                           | -0.3 | 30                 | V    |
| I/O voltage range    | GPIO0 to AGND                            | -0.3 | 6                  | V    |
| I/O voltage range    | PB_CC2 to AGND                           | -0.3 | 30                 | V    |
| I/O voltage range    | GPIO1, IRQ2 to AGND                      | -0.3 | 6                  | V    |
| I/O voltage range    | PB_DP to AGND                            | -0.3 | 30                 | V    |
| I/O voltage range    | GPIO2, I2C_SCL2 to AGND                  | -0.3 | 6                  | V    |
| I/O voltage range    | PB_DM to AGND                            | -0.3 | 30                 | V    |
| I/O voltage range    | GPIO3, I2C_SDA2 to AGND                  | -0.3 | 6                  | V    |
| I/O voltage range    | PB_BUS to AGND                           | -0.3 | 30                 | V    |
| I/O voltage range    | GPIO4                                    | -0.3 | 6                  | V    |
| I/O voltage range    | GPIO5, NTC to AGND                       | -0.3 | 6                  | V    |
| I/O voltage range    | GPIO6, SYNC to AGND                      | -0.3 | 6                  | V    |

## 7.1 Absolute Maximum Ratings (続き)

Over the recommended operating junction temperature range of -40°C to 150°C and AGND = PGND (unless otherwise noted)<sup>(1) (2)</sup>

|                                               |                                                                  | MIN                | MAX    | UNIT |
|-----------------------------------------------|------------------------------------------------------------------|--------------------|--------|------|
| Input current                                 | EN/UVLO                                                          | 0                  | 2      | mA   |
| Output current                                | Positive source current on PA_CC1, PA_CC2, PB_CC1, PB_CC2        | internally limited |        | A    |
| Output current                                | GPIO 2, 3, 5, 6, 7, 8                                            |                    | 0.0010 | A    |
| Output current                                | GPIO 0, 1, 4, 9                                                  |                    | 0.005  | A    |
| Output current                                | positive sink current for I2C_SDA1, I2C_SCL1, I2C_SDA2, I2C_SCL2 | internally limited |        | A    |
| Output current                                | positive source current for LDO_5V, LDO_3V3, LDO_1V5             | internally limited |        | A    |
| T <sub>A</sub> Operating ambient temperature  |                                                                  | -40                | 125    | °C   |
| T <sub>J</sub> Operating junction temperature |                                                                  | -40                | 150    | °C   |
| T <sub>STG</sub> Storage temperature          |                                                                  | -55                | 150    | °C   |

- (1) Stresses beyond those listed under *Absolute Maximum Rating* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Condition*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to PGND or AGND. Connect the PGND pin directly to the Ground plane of the board. The PGND and AGND traces can be connected near the AGND pin.
- (3) When the buck-boost is operating and V<sub>IN</sub> exceeds 18 V, the positive slew rate dV<sub>IN</sub>/dt must not exceed 200V/ms.
- (4) When applying V<sub>IN</sub>, the time from V<sub>IN</sub> exceeding 5 V to V<sub>IN</sub> exceeding 25 V must not be less than 2 μs. This is normally achieved by properly sizing the input EMI filter.
- (5) EN/UVLO pin is internally clamped to 10V. Ensure input current rating is not exceeded by connecting current limit resistor.
- (6) BOOT2 with respect to SW2 during OUT overvoltage conditions can be -15 V due to internal clamp.
- (7) SW1 can undershoot PGND by -1 V during negative switching transients as up to 10A (peak) may flow through the body diode. Typical duration ~20 ns. SW1 can overshoot OUT by 1 V during positive transients. Typical duration ~20 ns.
- (8) SW2 can undershoot PGND by -2 V during switching transients as up to 10A (peak) may flow through the body diode. Typical duration ~20 ns. SW2 can overshoot OUT by 1 V during positive transients. Typical duration ~20 ns.

## 7.2 ESD Ratings

|                    |                         |                                               | VALUE                | UNIT |
|--------------------|-------------------------|-----------------------------------------------|----------------------|------|
| V <sub>(ESD)</sub> | Electrostatic discharge | Human-body model (HBM), per AEC Q100-002      | ±2000 <sup>(1)</sup> | V    |
| V <sub>(ESD)</sub> | Electrostatic discharge | Charged-device model (CDM), per AEC Q100-011  | ±750 <sup>(2)</sup>  | V    |
| V <sub>(ESD)</sub> | Electrostatic discharge | IEC61000-4-2 Air-gap discharge 150 pF, 330 Ω. | ±2000 <sup>(4)</sup> | V    |
| V <sub>(ESD)</sub> | Electrostatic discharge | IEC61000-4-2 Contact discharge 150 pF, 330 Ω. | ±2000 <sup>(4)</sup> | V    |
| V <sub>(ESD)</sub> | Electrostatic discharge | ISO 10605 Contact discharge 330 pF, 330 Ω.    | ±2000 <sup>(3)</sup> | V    |
| V <sub>(ESD)</sub> | Electrostatic discharge | ISO 10605 Air-gap discharge 330 pF, 330 Ω.    | ±2000 <sup>(3)</sup> | V    |

- (1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.
- (2) The passing level per AEC-Q100 Classification C2b.
- (3) Test conducted on Texas Instruments evaluation board.

## 7.3 Recommended Operating Conditions

Over the recommended operating junction temperature range of -40°C to 150°C (unless otherwise noted)

|          |                                                               |                                                                                        | MIN  | MAX              | UNIT |
|----------|---------------------------------------------------------------|----------------------------------------------------------------------------------------|------|------------------|------|
| $V_I$    | Input voltage range (up to 65W output)                        | IN                                                                                     | 6.8  | 18               | V    |
| $V_I$    | Input voltage range (up to 30W output)                        | IN                                                                                     | 5.5  | 18               | V    |
| $V_I$    | Input voltage range                                           | EN/UVLO                                                                                | 0    | 7 <sup>(2)</sup> | V    |
| $I_I$    | Input current                                                 | EN/UVLO                                                                                | 0    | 1                | mA   |
| $V_I$    | Input voltage range                                           | LDO_5V when overdriven by external supply                                              | 4.75 | 5.5              | V    |
| $V_I$    | Input voltage range                                           | CSP, CSN/BUS                                                                           | 0    | 22               | V    |
| $V_I$    | Input voltage range                                           | PB_VBUS (GPIO4 when configured as PB_VBUS)                                             | 3    | 22               | V    |
| $V_O$    | Output voltage range                                          | OUT                                                                                    | 0    | 21               | V    |
| $V_{IO}$ | I/O voltage range                                             | PA_CC1, PA_CC2, PB_CC1, PB_CC2                                                         | 0    | 5.5              | V    |
| $V_{IO}$ | I/O voltage range                                             | PA_DP, PA_DM, PB_DP, PB_DM                                                             | 0    | 3.6              | V    |
| $V_{IO}$ | I/O voltage range                                             | I2C_SDA <sub>n</sub> , I2C_SCL <sub>n</sub> , I <sup>2</sup> Q <sub>n</sub> (n=1 or 2) | 0    | 5.5              | V    |
| $V_{IO}$ | I/O voltage range                                             | GPIO <sub>n</sub> (n = 0 - 9)                                                          | 0    | 3.6              | V    |
| $V_{IO}$ | I/O voltage range                                             | NTC monitor (GPIO5), SYNC (GPIO6)                                                      | 0    | 3.6              | V    |
| $I_O$    | Output current <sup>(1)</sup>                                 | IOUT                                                                                   |      | 5                | A    |
| $I_O$    | Output current                                                | PA_CC1, PA_CC2, PB_CC1, PB_CC2                                                         |      | 225              | mA   |
| $I_O$    | Output current (from LDO_3V3)                                 | GPIO <sub>n</sub> (n = 0 - 9)                                                          |      | 10               | mA   |
| fsw      | Buck-boost converter switching frequency driven from SYNC pin |                                                                                        | 250  | 500              | kHz  |
| $T_A$    | Ambient operating temperature                                 |                                                                                        | -40  | 125              | °C   |
| $T_J$    | Operating junction temperature                                |                                                                                        | -40  | 150              | °C   |

(1) Average LC filtered output current from buck-boost power stage. Operation with  $I_{OUT} > 3A$  with  $V_{OUT} > 10V$  may result in thermal shutdown.

(2) EN/UVLO MAX specification applies when current into pin is not externally limited.

## 7.4 Recommended Components

over operating free-air temperature range (unless otherwise noted)

| PARAMETER <sup>(1)</sup> |                                             | VOLTAGE RATING | MIN  | TYP | MAX | UNIT |
|--------------------------|---------------------------------------------|----------------|------|-----|-----|------|
| $C_{IN}$                 | Capacitance on VIN                          | 40 V           | 22   | 47  |     | μF   |
| $C_{LDO\_5V}$            | Capacitance on LDO_5V (supplied internally) | 10 V           | 4.7  |     | 10  | μF   |
| $C_{LDO\_5V}$            | Capacitance on LDO_5V (supplied externally) | 10 V           | 10   | 47  | 100 | μF   |
| $C_{LDO\_3V3}$           | Capacitance on LDO_3V3                      | 6.3 V          | 4.7  |     | 10  | μF   |
| $C_{LDO\_1V5}$           | Capacitance on LDO_1V5                      | 6.3 V          | 4.7  |     | 10  | μF   |
| $C_{Px\_CCy}$            | Capacitance on Px_CCy pins <sup>(2)</sup>   | 6.3 V          | 200  | 330 | 480 | pF   |
| $C_{BOOT1}, C_{BOOT2}$   | Boot charge capacitance                     | 10 V           | 0.08 | 0.1 | 0.3 | μF   |
| $R_{Snubber\_SW1}$       | RC snubber resistor on SW1                  | 35 V, 0.25 W   |      | 1.1 |     | Ω    |
| $C_{Snubber\_SW1}$       | RC snubber capacitor on SW1                 | 35 V           |      | 1   |     | nF   |
| $R_{Snubber\_SW2}$       | RC snubber resistor on SW2                  | 35 V, 0.25 W   |      | 1.1 |     | Ω    |

over operating free-air temperature range (unless otherwise noted)

| PARAMETER <sup>(1)</sup>                                             |                                                                        | VOLTAGE RATING | MIN   | TYP  | MAX   | UNIT |
|----------------------------------------------------------------------|------------------------------------------------------------------------|----------------|-------|------|-------|------|
| C <sub>Snubber_SW2</sub>                                             | RC snubber capacitor on SW2                                            | 35 V           |       | 3.3  |       | nF   |
| C <sub>OUT</sub>                                                     | Capacitance on OUT <sup>(4)</sup>                                      | 35 V           | 30    | 33   | 40    | μF   |
| C <sub>BUS</sub>                                                     | Capacitance on PA_VBUS                                                 | 35 V           | 100   | 120  | 150   | μF   |
| L                                                                    | Inductor <sup>(4)</sup>                                                |                | 3.3   | 4.7  | 5.6   | μH   |
| NTC                                                                  | Thermistor                                                             |                | 47    |      | 100   | kΩ   |
| R <sub>EN/UVLO</sub>                                                 | Enable/UVLO pull up resistance                                         |                | 47    |      |       | kΩ   |
| TVPS pin components (C <sub>TVSP</sub>    (Damper <sub>R</sub> + C)) | C <sub>TVSP</sub> Capacitance on TVSP pin <sup>href</sup>              | 40 V           | 0.08  | 0.1  | 0.12  | μF   |
| TVPS pin components (C <sub>TVSP</sub>    (Damper <sub>R</sub> + C)) | Damper resistor R of R + C network in Parallel with C <sub>TVSP</sub>  | 0.25W          | 8     | 10   | 12    | Ω    |
| TVPS pin components (C <sub>TVSP</sub>    (Damper <sub>R</sub> + C)) | Damper capacitor C of R + C network in Parallel with C <sub>TVSP</sub> | 40 V           | 0.376 | 0.47 | 0.564 | μF   |
| ESR <sub>C<sub>TVSP</sub></sub>                                      | TVSP Capacitor ESR (eq series resistance)                              |                |       | 10   |       | mΩ   |
| ESL <sub>C<sub>TVSP</sub></sub>                                      | TVSP Capacitor ESL (eq series inductance)                              |                |       | 1    |       | nH   |

- (1) Capacitance values do not include any derating factors. For example, if 5.0 μF is required and the external capacitor value reduces by 50% at the required operating voltage, then the required external capacitor value would be 10 μF.
- (2) This includes all capacitance to the Type-C receptacle.
- (3) Maximum capacitance allowed on TVSP pin to ensure proper decode of device configuration during boot.
- (4) See applications section for recommended L and C<sub>OUT</sub> combinations.

## 7.5 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | TPS25772-Q1 | UNIT |
|-------------------------------|----------------------------------------------|-------------|------|
|                               |                                              | Hot Rod     |      |
|                               |                                              | 29 PINS     |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 33.3        | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case (top) thermal resistance    | 13.1        |      |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 7.3         |      |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 0.3         |      |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 7.2         |      |

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 7.6 Buck-Boost Regulator

Typical values correspond to T<sub>J</sub> = 25°C. Minimum and maximum limits apply over the –40°C to 150°C junction temperature range unless otherwise stated. V<sub>IN</sub> = 13.5 V, V<sub>EN/UVLO</sub> = 2V unless otherwise stated. <sup>(1)</sup>

| PARAMETER               |                                               | TEST CONDITION                                                            | MIN  | TYP  | MAX  | UNIT |
|-------------------------|-----------------------------------------------|---------------------------------------------------------------------------|------|------|------|------|
| SUPPLY VOLTAGE (VIN)    |                                               |                                                                           |      |      |      |      |
| I <sub>Q</sub>          | V <sub>IN</sub> shutdown current              | V <sub>EN/UVLO</sub> = 0 V                                                |      |      | 130  | μA   |
| I <sub>Q</sub>          | V <sub>IN</sub> operating current             | V <sub>EN/UVLO</sub> = 2V, V <sub>OUT</sub> = 5 V, I <sub>OUT</sub> = 0 A |      | 8    |      | mA   |
| I <sub>Q</sub>          | V <sub>IN</sub> operating current             | V <sub>EN/UVLO</sub> = 1V, V <sub>OUT</sub> = 0 V, I <sub>OUT</sub> = 0 A |      |      | 4.5  | mA   |
| I <sub>Q</sub>          | V <sub>IN</sub> operating current             | V <sub>EN/UVLO</sub> = 2V, V <sub>OUT</sub> = 0 V, I <sub>OUT</sub> = 0 A |      |      | 8    | mA   |
| V <sub>IN(OVP_R)</sub>  | V <sub>IN</sub> rising overvoltage threshold  | V <sub>IN</sub> rising.                                                   | 18.4 | 19.2 | 20   | V    |
| V <sub>IN(OVP_F)</sub>  | V <sub>IN</sub> falling overvoltage threshold | V <sub>IN</sub> falling.                                                  | 18.0 | 18.8 | 19.6 | V    |
|                         | hysteresis                                    |                                                                           |      | 0.4  |      | V    |
| V <sub>IN(UVLO_R)</sub> | V <sub>IN</sub> undervoltage lockout rising   | V <sub>IN</sub> rising.                                                   | 5.14 | 5.30 | 5.46 | V    |

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Typical values correspond to  $T_J = 25^\circ\text{C}$ . Minimum and maximum limits apply over the  $-40^\circ\text{C}$  to  $150^\circ\text{C}$  junction temperature range unless otherwise stated.  $V_{IN} = 13.5\text{ V}$ ,  $V_{EN/UVLO} = 2\text{ V}$  unless otherwise stated. <sup>(1)</sup>

| PARAMETER               |                                                   | TEST CONDITION                                                                                                                                           | MIN   | TYP  | MAX   | UNIT          |
|-------------------------|---------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------|-------|------|-------|---------------|
| $V_{IN(UVLO\_F)}$       | $V_{IN}$ undervoltage lockout falling             | $V_{IN}$ falling.                                                                                                                                        | 5.04  | 5.20 | 5.36  | V             |
|                         | hysteresis                                        |                                                                                                                                                          |       | 0.1  |       | V             |
| <b>LDO_5V OUTPUT</b>    |                                                   |                                                                                                                                                          |       |      |       |               |
| $V_{LDO\_5V}$           | LDO_5V Output Regulation voltage                  | $7\text{ V} \leq V_{IN} \leq 18\text{ V}$ , $0 < I_{LDO\_5V} < 125\text{ mA}$ , $V_{EN} = 2\text{ V}$ .                                                  | 4.5   | 4.63 | 4.75  | V             |
| $V_{LDO\_5V(UVLO\_R)}$  | LDO_5V Undervoltage lockout rising                |                                                                                                                                                          | 4.29  | 4.4  | 4.51  | V             |
| $V_{LDO\_5V(UVLO\_F)}$  | LDO_5V Undervoltage lockout falling               |                                                                                                                                                          | 4.09  | 4.2  | 4.31  | V             |
|                         | Undervoltage hysteresis                           |                                                                                                                                                          |       | 200  |       | mV            |
| $V_{LDO\_5V\_DO}$       | drop out voltage                                  | $V_{IN} = 5.5\text{ V}$ ; $I_{LDO\_5V} = 125\text{ mA}$                                                                                                  | 4.3   |      |       | V             |
| $I_{LDO\_5V(ILIMIT)}$   | LDO_5V current limit                              | $V_{LDO\_5V} = 0$ to $3.5\text{ V}$ , $R_{LDO\_5V\_LOAD} = 1\ \Omega$                                                                                    | 125   | 200  | 400   | mA            |
| <b>LDO_3V3 OUTPUT</b>   |                                                   |                                                                                                                                                          |       |      |       |               |
| $V_{LDO\_3V3}$          | LDO_3V3 Output regulation voltage                 | $7\text{ V} \leq V_{IN} \leq 18\text{ V}$ , $V_{EN} = 2\text{ V}$ , $V_{LDO\_5V(UVLO)} < V_{LDO\_5V} < 5.5\text{ V}$ , $0 < I_{LDO\_3V3} < 25\text{ mA}$ | 3.4   | 3.5  | 3.6   | V             |
| $V_{LDO\_3V3(UVLO\_R)}$ | LDO_3V3 Undervoltage lockout rising               |                                                                                                                                                          | 3.2   | 3.3  | 3.4   | V             |
| $V_{LDO\_3V3(UVLO\_F)}$ | LDO_3V3 Undervoltage lockout falling              |                                                                                                                                                          | 3.05  | 3.15 | 3.25  | V             |
|                         | Undervoltage hysteresis                           |                                                                                                                                                          |       | 150  |       | mV            |
| $V_{LDO\_3V3\_DO}$      | drop out voltage                                  | $V_{IN} = 4.5\text{ V}$ , $I_{LDO\_3V3} = 30\text{ mA}$                                                                                                  | 3.3   |      |       | V             |
| $I_{LDO\_3V3(ILIMIT)}$  | LDO_3V3 current limit                             | $V_{LDO\_3V3} = 0$ to $2.5\text{ V}$ , $R_{LDO\_3V3\_LOAD} = 1\ \Omega$                                                                                  | 35    | 50   | 80    | mA            |
| <b>LDO_1V5 OUTPUT</b>   |                                                   |                                                                                                                                                          |       |      |       |               |
| $V_{LDO\_1V5}$          | LDO_1V5 Output Regulation voltage                 | $4.5 < V_{LDO\_5V} < 5.5\text{ V}$ , $0 < I_{LDO\_1V5} < 10\text{ mA}$                                                                                   | 1.49  | 1.55 | 1.65  | V             |
| $V_{LDO\_1V5(UVLO\_R)}$ | LDO_1V5 Undervoltage lockout rising               |                                                                                                                                                          | 1.44  | 1.49 | 1.54  | V             |
| $V_{LDO\_1V5(UVLO\_F)}$ | LDO_1V5 Undervoltage lockout falling              |                                                                                                                                                          | 1.37  | 1.42 | 1.47  | V             |
|                         | Undervoltage hysteresis                           |                                                                                                                                                          |       | 70   |       | mV            |
| $I_{LDO\_1V5(ILIMIT)}$  | LDO_1V5 current limit                             | $V_{LDO\_1V5} = 0$ to $1.2\text{ V}$ , $R_{LDO\_1V5\_LOAD} = 1\ \Omega$                                                                                  | 15    | 20   | 28    | mA            |
| <b>EN/UVLO</b>          |                                                   |                                                                                                                                                          |       |      |       |               |
| $V_{EN(LDO\_V5V\_R)}$   | EN input level required to turn on internal LDOs  | EN/UVLO rising                                                                                                                                           |       |      | 1.05  | V             |
| $V_{EN(LDO\_V5V\_F)}$   | EN input level required to turn off internal LDOs | EN/UVLO falling                                                                                                                                          | 0.3   |      |       | V             |
| $V_{EN(OPER)}$          | EN input level required to start operation        | EN/UVLO rising Precision EN                                                                                                                              | 1.2   | 1.25 | 1.3   | V             |
| $V_{EN(STBY)}$          | EN input level required to stop operation         | EN/UVLO falling                                                                                                                                          | 1.1   | 1.15 | 1.2   | V             |
| $V_{EN(HYS)}$           | Hysteresis                                        |                                                                                                                                                          |       | 100  |       | mV            |
| $V_{EN(CLAMP)}$         | EN input clamp voltage                            | $V_{EN/UVLO} > V_{EN(CLAMP)}$ , $10\ \mu\text{A} < I_{EN/UVLO} < 1\text{ mA}$                                                                            | 6     | 9    | 12    | V             |
| $I_{EN(LEAK)}$          | Leakage current into EN pin                       | $0\text{ V} < V_{EN} < 6\text{ V}$                                                                                                                       |       |      | 1     | $\mu\text{A}$ |
| <b>OUTPUT VOLTAGE</b>   |                                                   |                                                                                                                                                          |       |      |       |               |
| $V_{CNS/BUS(3V)}$       | $V_{CNS/BUS}$ regulation accuracy at 3V           | $0 \leq I_{OUT} \leq 3\text{ A}$                                                                                                                         | 2.9   | 3    | 3.1   | V             |
| $V_{CNS/BUS(5V)}$       | $V_{CNS/BUS}$ regulation accuracy at 5V           | $0 \leq I_{OUT} \leq 3\text{ A}$                                                                                                                         | 4.85  | 5    | 5.15  | V             |
| $V_{CNS/BUS(21V)}$      | $V_{CNS/BUS}$ regulation accuracy at 21V          | $0 \leq I_{OUT} \leq 3\text{ A}$                                                                                                                         | 20.48 | 21   | 21.53 | V             |
| $V_{CNS/BUS\_STP}$      | Output voltage step size (12-bit DAC)             |                                                                                                                                                          |       | 10   |       | mV            |
| VDAC Resolution         | Resolution of $V_{BUS}$ DAC                       |                                                                                                                                                          |       | 12   |       | Bits          |

Typical values correspond to  $T_J = 25^\circ\text{C}$ . Minimum and maximum limits apply over the  $-40^\circ\text{C}$  to  $150^\circ\text{C}$  junction temperature range unless otherwise stated.  $V_{IN} = 13.5\text{ V}$ ,  $V_{EN/UVLO} = 2\text{ V}$  unless otherwise stated. <sup>(1)</sup>

| PARAMETER                       |                                                                       | TEST CONDITION                                                                                             | MIN  | TYP  | MAX  | UNIT |
|---------------------------------|-----------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------|------|------|------|------|
| I <sub>DISCHG</sub>             | CSN/BUS discharge current when transitioning to VSafe0V               | V <sub>CSP</sub> = V <sub>CSN/BUS</sub> ; V <sub>CSN/BUS</sub> = 3V. Measure current into BUS.             | 40   |      |      | mA   |
| t <sub>DISCHG</sub>             | CSN/BUS discharge time when transitioning to VSafe5V                  | V <sub>BUS</sub> = 21 V (max), CBULK = 220 μF, time to discharge BUS to < 5.5 V (per USB PD specification) |      |      | 275  | ms   |
| t <sub>DISCHG</sub>             | CSN/BUS discharge time when transitioning to VSafe0V                  | V <sub>BUS</sub> = 21 V (max), CBULK = 220 μF, time to discharge BUS to < 0.8 V (per USB PD specification) |      |      | 650  | ms   |
| R <sub>DISCHG</sub>             | Weak discharge resistance on BUS pin when not sourcing VBUS           | EN = 2V; measure BUS to PGND resistance.                                                                   | 60   |      | 135  | kΩ   |
| R <sub>BUS-GND(PWR)</sub>       | BUS to GND resistance, R <sub>DISCH</sub> disabled, not sourcing VBUS | EN = 2V measure BUS to PGND resistance.                                                                    | 120  |      | 500  | kΩ   |
| R <sub>BUS-GND(UNPWR)</sub>     | BUS to GND resistance, unpowered                                      | VIN = EN = 0V measure BUS to PGND resistance.                                                              |      | 2    |      | kΩ   |
| CABLE VOLTAGE DROP COMPENSATION |                                                                       |                                                                                                            |      |      |      |      |
| V <sub>OUT_CDC</sub>            | ΔV <sub>OUT</sub> increase vs I <sub>OUT</sub>                        | Gain setting = 0.1V/A: V <sub>CSP</sub> - V <sub>CSN/BUS</sub> = 50 mV                                     | 465  | 500  | 535  | mV   |
| V <sub>OUT_CDC</sub>            | ΔV <sub>OUT</sub> increase vs I <sub>OUT</sub>                        | Gain setting = 0.1V/A: V <sub>CSP</sub> - V <sub>CSN/BUS</sub> = 10 mV                                     | 85   | 100  | 115  | mV   |
| V <sub>OUT_CDC</sub>            | ΔV <sub>OUT</sub> increase vs I <sub>OUT</sub>                        | Gain stetting = 0.075V/A: V <sub>CSP</sub> - V <sub>CSN/BUS</sub> = 50 mV                                  | 346  | 375  | 404  | mV   |
| V <sub>OUT_CDC</sub>            | ΔV <sub>OUT</sub> increase vs I <sub>OUT</sub>                        | Gain setting = 0.075V/A: V <sub>CSP</sub> - V <sub>CSN/BUS</sub> = 10 mV                                   | 61   | 75   | 89   | mV   |
| V <sub>OUT_CDC</sub>            | ΔV <sub>OUT</sub> increase vs I <sub>OUT</sub>                        | Gain setting = 0.05V/A: V <sub>CSP</sub> - V <sub>CSN/BUS</sub> = 50 mV                                    | 227  | 250  | 273  | mV   |
| V <sub>OUT_CDC</sub>            | ΔV <sub>OUT</sub> increase vs I <sub>OUT</sub>                        | Gain setting = 0.05V/A: V <sub>CSP</sub> - V <sub>CSN/BUS</sub> = 10 mV                                    | 37   | 50   | 63   | mV   |
| V <sub>OUT_CDC</sub>            | ΔV <sub>OUT</sub> increase vs I <sub>OUT</sub>                        | Gain setting = 0.025V/A: V <sub>CSP</sub> - V <sub>CSN/BUS</sub> = 50 mV                                   | 109  | 125  | 141  | mV   |
| V <sub>OUT_CDC</sub>            | ΔV <sub>OUT</sub> increase vs I <sub>OUT</sub>                        | Gain setting = 0.025V/A: V <sub>CSP</sub> - V <sub>CSN/BUS</sub> = 10 mV                                   | 14   | 25   | 36   | mV   |
| V <sub>OUT_CDC</sub>            | ΔV <sub>OUT</sub> increase vs I <sub>OUT</sub>                        | Gain setting = 0V/A: 0 mV ≤ V <sub>CSP</sub> - V <sub>CSN/BUS</sub> ≤ 50 mV                                | -5   |      | 20   | mV   |
| BUCK-BOOST PEAK CURRENT LIMITS  |                                                                       |                                                                                                            |      |      |      |      |
| I <sub>PEAK(BOOST)</sub>        | Boost peak current limit (in boost mode)                              |                                                                                                            | 12.3 | 14.5 | 16.7 | A    |
| I <sub>PEAK(BOOST)</sub>        | Boost peak current limit (in boost mode)                              |                                                                                                            | 10.8 | 12.8 | 14.7 | A    |
| I <sub>PEAK(BOOST)</sub>        | Boost peak current limit (in boost mode)                              |                                                                                                            | 9.3  | 11.0 | 12.6 | A    |
| I <sub>PEAK(BOOST)</sub>        | Boost peak current limit (in boost mode)                              |                                                                                                            | 7.9  | 9.3  | 10.6 | A    |
| I <sub>PEAK(BOOST)</sub>        | Boost peak current limit (in boost mode)                              |                                                                                                            | 6.3  | 7.5  | 8.6  | A    |
| I <sub>PEAK(BOOST)</sub>        | Boost peak current limit (in boost mode)                              |                                                                                                            | 4.8  | 5.7  | 6.5  | A    |
| I <sub>PEAK(BUCK)</sub>         | Buck peak current limit (in buck mode)                                |                                                                                                            | 8.2  | 9.7  | 11.2 | A    |
| I <sub>PEAK(BUCK)</sub>         | Buck peak current limit (in buck mode)                                |                                                                                                            | 9.0  | 10.6 | 12.1 | A    |
| I <sub>PEAK(BUCK)</sub>         | Buck peak current limit (in buck mode)                                |                                                                                                            | 9.7  | 11.4 | 13.1 | A    |
| I <sub>PEAK(BUCK)</sub>         | Buck peak current limit (in buck mode)                                |                                                                                                            | 10.4 | 12.3 | 14.1 | A    |
| I <sub>PEAK(BUCK)</sub>         | Buck peak current limit (in buck mode)                                |                                                                                                            | 5.3  | 6.2  | 7.2  | A    |
| I <sub>PEAK(BUCK)</sub>         | Buck peak current limit (in buck mode)                                |                                                                                                            | 6    | 7.1  | 8.2  | A    |

Typical values correspond to  $T_J = 25^\circ\text{C}$ . Minimum and maximum limits apply over the  $-40^\circ\text{C}$  to  $150^\circ\text{C}$  junction temperature range unless otherwise stated.  $V_{IN} = 13.5\text{ V}$ ,  $V_{EN/UVLO} = 2\text{ V}$  unless otherwise stated. <sup>(1)</sup>

| PARAMETER                     |                                                   | TEST CONDITION                                                                                          | MIN  | TYP  | MAX  | UNIT       |
|-------------------------------|---------------------------------------------------|---------------------------------------------------------------------------------------------------------|------|------|------|------------|
| $I_{PEAK(BUCK)}$              | Buck peak current limit (in buck mode)            |                                                                                                         | 6.8  | 8.0  | 9.1  | A          |
| $I_{PEAK(BUCK)}$              | Buck peak current limit (in buck mode)            |                                                                                                         | 7.5  | 8.8  | 10.1 | A          |
| $I_{NEG(BUCK)}$               | Buck negative current limit (in buck mode)        |                                                                                                         | -4.6 | -3.8 | -3   | A          |
| <b>OUT CURRENT DAC</b>        |                                                   |                                                                                                         |      |      |      |            |
| IDAC_Resolution               |                                                   |                                                                                                         |      | 8    |      | Bits       |
| <b>CURRENT LIMIT</b>          |                                                   |                                                                                                         |      |      |      |            |
| $I_{LIMIT\_LO}$               | Current limit accuracy                            | $1\text{ A} \leq I_{OUT} \leq 3\text{ A}$ , $V_{CSN/BUS} < 2.5\text{ V}$ ; $R_S = 10\text{ m}\Omega$    | -250 |      | 250  | mA         |
| $I_{LIMIT\_LO}$               | Current limit accuracy $< 1\text{ A}$             | $1\text{ A} \leq I_{OUT} \leq 3\text{ A}$ , $V_{CSN/BUS} \geq 2.5\text{ V}$ ; $R_S = 10\text{ m}\Omega$ | -150 |      | 150  | mA         |
| $I_{LIMIT\_HI}$               | Current limit accuracy $> 3\text{ A}$             | $I_{OUT} > 3\text{ A}$ , $V_{CSN/BUS} < 2.5\text{ V}$ ; $R_S = 10\text{ m}\Omega$                       | -20  |      | 20   | %          |
| $I_{LIMIT\_HI}$               | Current limit accuracy $> 3\text{ A}$             | $I_{OUT} > 3\text{ A}$ , $V_{CSN/BUS} \geq 2.5\text{ V}$ ; $R_S = 10\text{ m}\Omega$                    | -5   |      | 5    | %          |
| $I_{LIMIT\_MIN}$              | Minimum programmable current limit                |                                                                                                         | 1    |      |      | A          |
| $I_{CL\_STEP}$                | Current limit step size                           | $1\text{ A} \leq I_{OUT} \leq 5\text{ A}$ ; $R_S = 10\text{ m}\Omega$                                   |      | 50   |      | mA         |
| <b>FREQUENCY</b>              |                                                   |                                                                                                         |      |      |      |            |
| $f_{SW(1)}$                   | Switching Frequency 1                             |                                                                                                         | 285  | 300  | 315  | kHz        |
| $f_{SW(2)}$                   | Switching Frequency 2                             |                                                                                                         | 380  | 400  | 420  | kHz        |
| $f_{SW(3)}$                   | Switching Frequency 3                             |                                                                                                         | 428  | 450  | 473  | kHz        |
| <b>FREQUENCY DITHER</b>       |                                                   |                                                                                                         |      |      |      |            |
| $FS_{SS}$                     | Positive frequency deviation during dither        |                                                                                                         | 8    | 10   | 12   | %          |
|                               | Negative frequency deviation during dither        |                                                                                                         | -12  | -10  | -8   | %          |
| $FS_{SS\_MOD}$                | Modulation frequency of dither                    | DITHER_FREQ = 0                                                                                         | 9    | 10   | 11   | kHz        |
| $FS_{SS\_MOD}$                | Modulation frequency of dither                    | DITHER_FREQ = 1                                                                                         | 22.5 | 25   | 27.5 | kHz        |
| <b>OVERVOLTAGE PROTECTION</b> |                                                   |                                                                                                         |      |      |      |            |
| $V_{CSN/BUS\_OVP\_R}$         | Fixed output overvoltage threshold at CSN/BUS pin |                                                                                                         | 22.0 | 23   | 24   | V          |
| $V_{CSN/BUS\_OVP\_F}$         | Falling                                           |                                                                                                         | 20.5 | 21.5 | 22.5 | V          |
|                               | Hysteresis                                        |                                                                                                         |      | 1.5  |      | V          |
| <b>POWER SWITCHES</b>         |                                                   |                                                                                                         |      |      |      |            |
| $R_{DS(ON)}$                  | M1                                                | $V_{IN} = 12\text{ V}$ ; $(V_{BOOT1} - V_{SW1}) = 4.5\text{ V}$ ; $I_{SW1} = -1\text{ A}$               |      | 4.5  |      | m $\Omega$ |
| $R_{DS(ON)}$                  | M2                                                | $V_{IN} = 12\text{ V}$ ; $I_{SW1} = 1\text{ A}$                                                         |      | 20   |      | m $\Omega$ |
| $R_{DS(ON)}$                  | M4                                                | $V_{IN} = 12\text{ V}$ ; $I_{SW2} = 1\text{ A}$                                                         |      | 6    |      | m $\Omega$ |
| $R_{DS(ON)}$                  | M3 + M5                                           | $V_{IN} = V_{OUT} = 12\text{ V}$ ; $(V_{BOOT2} - V_{SW2}) = 4.5\text{ V}$ ; $I_{SW2} = -1\text{ A}$     |      | 18   |      | m $\Omega$ |
| $V_{UV\_BOOT1\_R}$            | BOOT1 to SW1 rising UVLO threshold                |                                                                                                         | 3.5  | 4    | 4.4  | V          |
| $V_{UV\_BOOT1\_F}$            | BOOT1 to SW1 falling UVLO threshold               |                                                                                                         | 2.9  | 3.4  | 3.7  | V          |
|                               | BOOT1 to SW1 UVLO hysteresis                      |                                                                                                         |      | 680  |      | mV         |
| $V_{OV\_BOOT1\_R}$            | BOOT1 to SW1 rising OVP threshold                 |                                                                                                         | 4.6  | 5.3  | 5.9  | V          |
| $V_{OV\_BOOT1\_F}$            | BOOT1 to SW1 falling OVP threshold                |                                                                                                         | 4.3  | 5    | 5.6  | V          |
|                               | BOOT 1 OVP hysteresis                             |                                                                                                         | 250  | 300  | 350  | mV         |
| $V_{UV\_BOOT2\_R}$            | BOOT2 to SW2 rising UVLO threshold                |                                                                                                         | 3.5  | 4    | 4.4  | V          |

Typical values correspond to  $T_J = 25^\circ\text{C}$ . Minimum and maximum limits apply over the  $-40^\circ\text{C}$  to  $150^\circ\text{C}$  junction temperature range unless otherwise stated.  $V_{IN} = 13.5\text{ V}$ ,  $V_{EN/UVLO} = 2\text{ V}$  unless otherwise stated. <sup>(1)</sup>

| PARAMETER                         |                                     | TEST CONDITION | MIN | TYP | MAX | UNIT |
|-----------------------------------|-------------------------------------|----------------|-----|-----|-----|------|
| $V_{UV\_BOOT2\_F}$                | BOOT2 to SW2 falling UVLO threshold |                | 2.9 | 3.4 | 3.7 | V    |
|                                   | BOOT2 to SW2 UVLO hysteresis        |                |     | 680 |     | mV   |
| $V_{OV\_BOOT2\_R}$                | BOOT2 to SW2 rising OVP threshold   |                | 4.6 | 5.3 | 5.9 | V    |
| $V_{OV\_BOOT2\_F}$                | BOOT2 to SW2 falling OVP threshold  |                | 4.3 | 5   | 5.6 | V    |
|                                   | BOOT2 OVP hysteresis                |                | 250 | 300 | 350 | mV   |
| <b>BUCK-BOOST CHARACTERISTICS</b> |                                     |                |     |     |     |      |
| $t_{SS}$                          | Soft-start time                     |                |     | 6   |     | ms   |

(1) All minimum and maximum limits are specified by correlating the electrical characteristics to process and temperature variations and applying statistical process control.

## 7.7 CC Cable Detection Parameters

Typical values correspond to  $T_J = 25^\circ\text{C}$ . Minimum and maximum limits apply over the  $-40^\circ\text{C}$  to  $150^\circ\text{C}$  junction temperature range unless otherwise stated.  $V_{IN} = 13.5\text{ V}$ ,  $EN = 2\text{ V}$ , unless otherwise stated.

| PARAMETER                         |                                                                                                                                                          | TEST CONDITIONS                                                                | MIN  | TYP  | MAX | UNIT             |
|-----------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------|------|------|-----|------------------|
| <b>Type-C Source (Rp pull-up)</b> |                                                                                                                                                          |                                                                                |      |      |     |                  |
| $V_{OC\_3.3}$                     | Unattached Px_CCy open circuit voltage while Rp enabled, no load                                                                                         | $R_{CC} = 47\text{ k}\Omega$                                                   | 1.85 |      |     | V                |
| $V_{OC\_5}$                       | Attached Px_CCy open circuit voltage while Rp enabled, no load                                                                                           | $R_{CC} = 47\text{ k}\Omega$                                                   | 2.95 |      |     | V                |
| $I_{Rev}$                         | Unattached reverse current on Px_CCy                                                                                                                     | $V_{CCy} = 5.5\text{ V}$ , $V_{CCx} = 0\text{ V}$ , measure current into CCy   |      |      | 10  | $\mu\text{A}$    |
| $I_{RpStd}$                       | current source - Standard                                                                                                                                | $0 < V_{CCy} < 1.0\text{ V}$ , measure $I_{CCy}$                               | 64   | 80   | 96  | $\mu\text{A}$    |
| $I_{Rp1.5}$                       | current source - 1.5A                                                                                                                                    | $0 < V_{CCy} < 1.5\text{ V}$ , measure $I_{CCy}$                               | 166  | 180  | 194 | $\mu\text{A}$    |
| $I_{Rp3.0}$                       | current source - 3.0A                                                                                                                                    | $0 < V_{CCy} < 2.45\text{ V}$ , measure $I_{CCy}$                              | 304  | 330  | 356 | $\mu\text{A}$    |
| <b>Type-C Sink (Rd pull-down)</b> |                                                                                                                                                          |                                                                                |      |      |     |                  |
| $R_{SNK}$                         | Rd pulldown resistance                                                                                                                                   | $0\text{ V} \leq V_{Px\_CCy} \leq 2.1\text{ V}$ , measure resistance on Px_CCy | 4.6  |      | 5.6 | $\text{k}\Omega$ |
| $R_{VCONN\_DIS}$                  | VCONN discharge resistance                                                                                                                               | $0\text{ V} \leq V_{Px\_CCy} \leq 5.5\text{ V}$ , measure resistance on Px_CCy | 4.0  |      | 6.6 | $\text{k}\Omega$ |
| <b>Common (Source and Sink)</b>   |                                                                                                                                                          |                                                                                |      |      |     |                  |
| $t_{CC}$                          | deglitch time for comparators on Px_CCy, this applies for $V_{SRC1}$ , $V_{SRC2}$ , $V_{SRC3}$ , $V_{SNK1}$ , $V_{SNK2}$ , $V_{SNK3}$ , and $V_{SNK4}$ . |                                                                                |      | 2.56 |     | ms               |

## 7.8 CC VCONN Parameters

Typical values correspond to  $T_J = 25^\circ\text{C}$ . Minimum and maximum limits apply over the  $-40^\circ\text{C}$  to  $150^\circ\text{C}$  junction temperature range unless otherwise stated.  $V_{IN} = 13.5\text{ V}$ ,  $EN = 2\text{ V}$  unless otherwise stated.

| PARAMETER       |                             | TEST CONDITIONS                                                                               | MIN | TYP | MAX | UNIT     |
|-----------------|-----------------------------|-----------------------------------------------------------------------------------------------|-----|-----|-----|----------|
| $R_{PP\_CABLE}$ | Rdson of the VCONN path     | $V_{LDO\_5V} = 5\text{ V}$ , $I_L = 200\text{ mA}$ , measure resistance from LDO_5V to Px_CCy |     |     | 1.2 | $\Omega$ |
| $I_{LIMVC}$     | short circuit current limit | setting 0, $V_{LDO\_5V} = 5\text{ V}$ , $R_L = 10\text{ m}\Omega$ , measure $I_{Px\_CCy}$     | 30  | 50  | 70  | mA       |
|                 |                             | setting 1, $V_{LDO\_5V} = 5\text{ V}$ , $R_L = 10\text{ m}\Omega$ , measure $I_{Px\_CCy}$     | 235 | 275 | 315 |          |

Typical values correspond to  $T_J = 25^\circ\text{C}$ . Minimum and maximum limits apply over the  $-40^\circ\text{C}$  to  $150^\circ\text{C}$  junction temperature range unless otherwise stated.  $V_{IN} = 13.5\text{ V}$ ,  $EN = 2\text{ V}$  unless otherwise stated.

| PARAMETER            | TEST CONDITIONS                                                                                                                        | MIN | TYP | MAX | UNIT          |
|----------------------|----------------------------------------------------------------------------------------------------------------------------------------|-----|-----|-----|---------------|
| $I_{CCYLKG}$         | Leakage current into Px_Cy pins<br>VCONN disabled, $T_J \leq 125^\circ\text{C}$ , $V_{Px\_CCy} = 5.5\text{ V}$ , measure $I_{Px\_CCy}$ | -1  | 0   | 10  | $\mu\text{A}$ |
| $V_{VC\_OVP}$        | Over-voltage protection threshold for Px_CCy                                                                                           | 5.6 | 5.9 | 6.2 | V             |
| $V_{VC\_RCP}$        | Reverse current protection threshold for Px_CCy, sourcing VCONN through CCx                                                            | 230 | 310 | 390 | mV            |
| $V_{VC\_RCP}$        | Reverse current protection threshold for Px_CCy, sourcing VCONN through CCx                                                            | 60  | 155 | 250 | mV            |
| $t_{PP\_CABLE\_FSD}$ | Time to disable Px_Cy VCONN after $V_{LDO\_5V} > V_{VC\_OVP}$ or $V_{CCx} - V_{LDO\_5V} > V_{VC\_RCP}$                                 |     | 1.5 |     | $\mu\text{s}$ |
| $t_{PP\_CABLE\_off}$ | from disable signal to Px_CCy at 10% of final value                                                                                    | 100 | 225 | 300 | $\mu\text{s}$ |
| $t_{IOS\_PP\_CABLE}$ | response time to short circuit                                                                                                         |     |     | 2   | $\mu\text{s}$ |
| $t_{IOS\_PP\_CABLE}$ | response time to short circuit                                                                                                         |     |     | 0.3 | $\mu\text{s}$ |

## 7.9 CC PHY Parameters

Typical values correspond to  $T_J = 25^\circ\text{C}$ . Minimum and maximum limits apply over the  $-40^\circ\text{C}$  to  $150^\circ\text{C}$  junction temperature range unless otherwise stated.  $V_{IN} = 13.5\text{ V}$ ,  $EN = 2\text{ V}$  unless otherwise stated.

| PARAMETER          | TEST CONDITIONS                                                                                                    | MIN  | TYP   | MAX | UNIT     |
|--------------------|--------------------------------------------------------------------------------------------------------------------|------|-------|-----|----------|
| <b>Transmitter</b> |                                                                                                                    |      |       |     |          |
| $V_{TXHI}$         | Transmit high voltage on Px_CCy                                                                                    | 1.05 | 1.125 | 1.2 | V        |
| $V_{TXLO}$         | Transmit low voltage on Px_CCy                                                                                     | -75  |       | 75  | mV       |
| $Z_{DRIVER}$       | Transmit output impedance while driving the CC line using Px_CCy                                                   | 33   |       | 75  | $\Omega$ |
| $t_{Rise}$         | Rise time. 10 % to 90 % amplitude points on Px_CCy, minimum is under an unloaded condition. Maximum set by TX mask | 300  |       |     | ns       |
| $t_{Fall}$         | Fall time. 90 % to 10 % amplitude points on Px_CCy, minimum is under an unloaded condition. Maximum set by TX mask | 300  |       |     | ns       |
| $V_{PHY\_OVP}$     | OVP detection threshold for USB PD PHY.                                                                            | 5.5  |       | 8.5 | V        |
| <b>Receiver</b>    |                                                                                                                    |      |       |     |          |

Typical values correspond to  $T_J = 25^\circ\text{C}$ . Minimum and maximum limits apply over the  $-40^\circ\text{C}$  to  $150^\circ\text{C}$  junction temperature range unless otherwise stated.  $V_{IN} = 13.5\text{ V}$ ,  $EN = 2\text{ V}$  unless otherwise stated.

| PARAMETER          | TEST CONDITIONS                                                                                                               | MIN | TYP | MAX | UNIT      |
|--------------------|-------------------------------------------------------------------------------------------------------------------------------|-----|-----|-----|-----------|
| $Z_{BMC RX}^{(2)}$ | Receiver input impedance on Px_CCy<br>Does not include pull-up or pulldown resistance from cable detect. Transmitter is Hi-Z. | 1   |     |     | $M\Omega$ |
| $C_{CC}$           | Receiver capacitance on Px_CCy <sup>(1)</sup><br>Capacitance looking into the CC pin when in receiver mode                    |     |     | 120 | pF        |
| $V_{RX\_SNK\_R}$   | Rising threshold on Px_CCy for receiver comparator<br>sink mode (rising)                                                      | 499 | 525 | 551 | mV        |
| $V_{RX\_SRC\_R}$   | Rising threshold on Px_CCy for receiver comparator<br>source mode (rising)                                                    | 784 | 825 | 866 | mV        |
| $V_{RX\_SNK\_F}$   | Falling threshold on Px_CCy for receiver comparator<br>sink mode (falling)                                                    | 230 | 250 | 270 | mV        |
| $V_{RX\_SRC\_F}$   | Falling threshold on Px_CCy for receiver comparator<br>source mode (falling)                                                  | 523 | 550 | 578 | mV        |

- (1)  $C_{CC}$  includes only the internal capacitance on a Px\_CCy pin when the pin is configured to be receiving BMC data. External capacitance is needed to meet the required minimum capacitance per the USB-PD Specifications (cReceiver). Therefore, TI recommends adding  $C_{Px\_CCy}$  externally.
- (2) Guaranteed, but not production tested.

## 7.10 Thermal Shutdown Characteristics

over operating free-air temperature range (unless otherwise noted)

| PARAMETER                 | TEST CONDITIONS                                      | MIN | TYP | MAX | UNIT             |
|---------------------------|------------------------------------------------------|-----|-----|-----|------------------|
| $T_{SD\_BB}$              | Temperature shutdown threshold<br>Temperature rising | 160 | 167 | 175 | $^\circ\text{C}$ |
| $T_{SD\_HYS}$             | Temperature shutdown hysteresis<br>hysteresis        |     | 18  |     | $^\circ\text{C}$ |
| $T_{SD\_PA\_VCONN}$       | Temperature shutdown threshold<br>Temperature rising | 152 | 166 | 179 | $^\circ\text{C}$ |
| $T_{SD\_HYS}$             | Temperature shutdown hysteresis<br>hysteresis        |     | 20  |     | $^\circ\text{C}$ |
| $T_{SD\_PB\_VCONN}$       | Temperature shutdown threshold<br>Temperature rising | 152 | 166 | 179 | $^\circ\text{C}$ |
| $T_{SD\_HYS}$             | Temperature shutdown hysteresis<br>hysteresis        |     | 20  |     | $^\circ\text{C}$ |
| $T_{SD\_PA\_VBUS\_DISCH}$ | Temperature shutdown threshold<br>Temperature rising | 155 | 166 | 177 | $^\circ\text{C}$ |
| $T_{SD\_HYS}$             | Temperature shutdown hysteresis<br>hysteresis        |     | 20  |     | $^\circ\text{C}$ |
| $T_{SD\_LDO5V}$           | Temperature shutdown threshold<br>Temperature rising | 165 | 177 | 188 | $^\circ\text{C}$ |
| $T_{SD\_HYS}$             | Temperature shutdown hysteresis<br>hysteresis        |     | 15  |     | $^\circ\text{C}$ |

## 7.11 Oscillator Characteristics

Typical values correspond to  $T_J = 25^\circ\text{C}$ . Minimum and maximum limits apply over the  $-40^\circ\text{C}$  to  $150^\circ\text{C}$  junction temperature range unless otherwise stated.  $V_{IN} = 13.5\text{ V}$ ,  $EN = 2\text{ V}$ , unless otherwise stated.

| PARAMETER       | TEST CONDITIONS                                                               | MIN   | TYP  | MAX   | UNIT |
|-----------------|-------------------------------------------------------------------------------|-------|------|-------|------|
| $F_{OSC(100K)}$ | 100KHz oscillator<br>Trimmed.                                                 | 89    | 103  | 111   | kHz  |
| $F_{OSC(24M)}$  | 24MHz oscillator<br>Trimmed. $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$ | 23.64 | 24.2 | 24.36 | MHz  |

Typical values correspond to  $T_J = 25^\circ\text{C}$ . Minimum and maximum limits apply over the  $-40^\circ\text{C}$  to  $150^\circ\text{C}$  junction temperature range unless otherwise stated.  $V_{IN} = 13.5\text{ V}$ ,  $EN = 2\text{ V}$ , unless otherwise stated.

| PARAMETER      |                  | TEST CONDITIONS                                              | MIN  | TYP  | MAX  | UNIT |
|----------------|------------------|--------------------------------------------------------------|------|------|------|------|
| $F_{OSC(24M)}$ | 24MHz oscillator | Trimmed. $-40^\circ\text{C} \leq T_A \leq 150^\circ\text{C}$ | 23.3 | 24.2 | 24.5 | MHz  |

## 7.12 ADC Characteristics

Typical values correspond to  $T_J = 25^\circ\text{C}$ . Minimum and maximum limits apply over the  $-40^\circ\text{C}$  to  $150^\circ\text{C}$  junction temperature range unless otherwise stated.  $V_{IN} = 13.5\text{ V}$ ,  $EN = 2\text{ V}$ , unless otherwise stated.

| PARAMETER   |                             | TEST CONDITIONS                                                                  | MIN  | TYP | MAX | UNIT |
|-------------|-----------------------------|----------------------------------------------------------------------------------|------|-----|-----|------|
| LSB         | least significant bit       | 3.6V max scaling, voltage divider of 3                                           |      | 14  |     | mV   |
| LSB         | least significant bit       | 25.2V max scaling, voltage divider of 21                                         |      | 98  |     | mV   |
| LSB         | least significant bit       | $(V_{CSP} - V_{CSN/BUS}) = 10\text{ mV}$ ,<br>30 mV                              |      | 27  |     | mA   |
| $E_G$       | Gain error                  | $0\text{ A} \leq I_{TVSP} \leq 0.9\text{ mA}$                                    | -2.7 |     | 2.7 | %    |
| $E_G$       | Gain error                  | $0.05\text{ V} \leq V_{GPIOX} \leq 3.6\text{ V}$ , $V_{GPIOX} \leq V_{LDO\_3V3}$ | -2.7 |     | 2.7 | %    |
| $E_G$       | Gain error                  | $2.7\text{ V} \leq V_{LDO\_3V3} \leq 3.6\text{ V}$                               | -2.4 |     | 2.4 | %    |
| $E_G$       | Gain error                  | $0.6\text{ V} \leq V_{PX\_VBUS} \leq 22\text{ V}$                                | -2.4 |     | 2.4 | %    |
| $E_G$       | Gain error, current sense   | $(V_{CSP} - V_{CSN/BUS}) = 10\text{ mV}$ ,<br>30 mV                              | -2.4 |     | 2.4 | %    |
| $E_G$       | Gain error                  | $V_{IN}$                                                                         | -2.4 |     | 2.4 | %    |
| $E_G$       | Gain error                  | $4.3\text{ V} \leq V_{LDO\_5V} \leq 5.5\text{ V}$                                | -2.4 |     | 2.4 | %    |
| $V_{OS(E)}$ | Offset error <sup>(1)</sup> | $0\text{ A} \leq I_{TVSP} \leq 0.9\text{ mA}$                                    | -4.1 |     | 15  | mV   |
| $V_{OS(E)}$ | Offset error <sup>(1)</sup> | $0.05\text{ V} \leq V_{GPIOX} \leq 3.6\text{ V}$ , $V_{GPIOX} \leq V_{LDO\_3V3}$ | -4.1 |     | 4.1 | mV   |
| $V_{OS(E)}$ | Offset error <sup>(1)</sup> | $2.7\text{ V} \leq V_{LDO\_3V3} \leq 3.6\text{ V}$                               | -4.1 |     | 4.1 | mV   |
| $V_{OS(E)}$ | Offset error <sup>(1)</sup> | $0.6\text{ V} \leq V_{PX\_VBUS} \leq 22\text{ V}$                                | -4.1 |     | 4.1 | mV   |
| $V_{OS(E)}$ | Offset error <sup>(1)</sup> | $(V_{CSP} - V_{CSN/BUS}) = 10\text{ mV}$ ,<br>30 mV                              | -4.5 |     | 4.5 | mA   |
| $V_{OS(E)}$ | Offset error <sup>(1)</sup> | $V_{IN}$                                                                         | -4.1 |     | 4.1 | mV   |
| $V_{OS(E)}$ | Offset error <sup>(1)</sup> | $4.3\text{ V} \leq V_{LDO\_5V} \leq 5.5\text{ V}$                                | -4.1 |     | 4.1 | mV   |

(1) The offset error is specified after the voltage divider.

## 7.13 TVS Parameters

$V_{IN} = 13.5\text{ V}$ ,  $EN = 2\text{ V}$ , over operating free-air temperature range (unless otherwise noted)

| PARAMETER      |                                                  | TEST CONDITIONS                 | MIN   | TYP | MAX   | UNIT          |
|----------------|--------------------------------------------------|---------------------------------|-------|-----|-------|---------------|
| <b>TVSP</b>    |                                                  |                                 |       |     |       |               |
| $V_{TVSP\_PU}$ | Pull up voltage for configuration <sup>(1)</sup> | $0 < I_{TVSP} < 1\text{ mA}$    | 5.3   | 5.5 | 5.7   | V             |
| Decode 0       | Device configuration decode                      | $R_{TVS} = \text{Open}$         |       |     | 1     | $\mu\text{A}$ |
| Decode 1       | Device configuration decode                      | $R_{TVS} = 93.1\text{ k}\Omega$ | 56.9  |     | 61.2  | $\mu\text{A}$ |
| Decode 2       | Device configuration decode                      | $R_{TVS} = 47.5\text{ k}\Omega$ | 111.6 |     | 120   | $\mu\text{A}$ |
| Decode 3       | Device configuration decode                      | $R_{TVS} = 29.4\text{ k}\Omega$ | 180.3 |     | 193.9 | $\mu\text{A}$ |
| Decode 4       | Device configuration decode                      | $R_{TVS} = 20.0\text{ k}\Omega$ | 265   |     | 285   | $\mu\text{A}$ |
| Decode 5       | Device configuration decode                      | $R_{TVS} = 14.7\text{ k}\Omega$ | 360.5 |     | 387.8 | $\mu\text{A}$ |
| Decode 6       | Device configuration decode                      | $R_{TVS} = 11.0\text{ k}\Omega$ | 481.8 |     | 518.2 | $\mu\text{A}$ |
| Decode 7       | Device configuration decode                      | $R_{TVS} = 8.45\text{ k}\Omega$ | 627.2 |     | 674.6 | $\mu\text{A}$ |

V<sub>IN</sub> = 13.5V, EN = 2V. over operating free-air temperature range (unless otherwise noted)

| PARAMETER                 |                                      | TEST CONDITIONS                                                                                                                                        | MIN | TYP  | MAX   | UNIT |
|---------------------------|--------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------|-----|------|-------|------|
| Decode 8                  | Device configuration decode          | R <sub>TVS</sub> = 6.65 kΩ                                                                                                                             | 797 |      | 857.1 | μA   |
| I <sub>TVSP(ILIMIT)</sub> | Current limit when TVSP is sourcing. | C <sub>TVSP</sub> = open; R <sub>TVSP</sub> = open.<br>All Px_Dy = 0 V and Px_CCy = 0 V. V <sub>TVSP</sub> = 0 V. Measure current flowing out of TVSP. | 1.1 | 1.44 | 1.83  | mA   |

(1) For proper device configuration, V<sub>IN</sub> must be ≥ 7.6 V at time of configuration read.

## 7.14 Input/Output (I/O) Characteristics

Typical values correspond to T<sub>J</sub> = 25°C. Minimum and maximum limits apply over the –40°C to 150°C junction temperature range unless otherwise stated. V<sub>IN</sub> = 13.5 V, EN = 2 V, unless otherwise stated.

| PARAMETER                                      |                                                                    | TEST CONDITIONS                                                    | MIN  | TYP | MAX | UNIT    |
|------------------------------------------------|--------------------------------------------------------------------|--------------------------------------------------------------------|------|-----|-----|---------|
| GPIO0-9 (Inputs) <sup>(1)</sup>                |                                                                    |                                                                    |      |     |     |         |
| V <sub>IH</sub>                                | GPIOx high-Level input voltage                                     |                                                                    | 1.3  |     |     | V       |
| V <sub>IL</sub>                                | GPIOx low-level input voltage                                      |                                                                    | 0.54 |     |     | V       |
|                                                | GPIOx input hysteresis voltage                                     |                                                                    | 0.09 |     |     | V       |
| I <sub>I(LEAKAGE)</sub>                        | GPIOx leakage current                                              | V <sub>GPIOx</sub> = 5.5 V                                         | −8   |     | 8   | μA      |
| R <sub>PU</sub>                                | GPIOx internal pull-up                                             | pull-up enabled                                                    | 50   | 100 | 150 | kΩ      |
| R <sub>PD</sub>                                | GPIOx internal pull-down                                           | pull-down enabled                                                  | 50   | 100 | 150 | kΩ      |
| t <sub>DG</sub>                                | GPIOx input deglitch                                               |                                                                    | 20   |     |     | ns      |
| GPIO 2, 3, 5, 6 (Outputs)                      |                                                                    |                                                                    |      |     |     |         |
| V <sub>OH</sub>                                | GPIOx output high voltage                                          | I <sub>GPIOx</sub> = -5mA                                          | 2.9  |     |     | V       |
| V <sub>OL</sub>                                | GPIOx output low voltage                                           | I <sub>GPIOx</sub> =5mA                                            | 0.4  |     |     | V       |
| GPIO 0, 1, 4, 7, 8, 9 (Outputs) <sup>(2)</sup> |                                                                    |                                                                    |      |     |     |         |
| V <sub>OH</sub>                                | GPIOx output high voltage                                          | I <sub>GPIOx</sub> = -2mA                                          | 2.9  |     |     | V       |
| V <sub>OL</sub>                                | GPIOx output low voltage                                           | I <sub>GPIOx</sub> =2mA                                            | 0.4  |     |     | V       |
| SYNC OUT                                       |                                                                    |                                                                    |      |     |     |         |
| φ shift_00                                     | GPIOx when configured as phase shifted DC/DC fsw clock output      | Phase difference between fsw and GPIO6 when configured as SYNC(O). | 0    |     |     | degrees |
| φ shift_90                                     | GPIOx when configured as phase shifted DC/DC fsw clock output      | Phase difference between fsw and GPIO6 when configured as SYNC(O). | 90   |     |     | degrees |
| φ shift_120                                    | GPIOx when configured as phase shifted DC/DC fsw clock output      | Phase difference between fsw and GPIO6 when configured as SYNC(O). | 120  |     |     | degrees |
| φ shift_180                                    | GPIOx when configured as phase shifted DC/DC fsw clock output      | Phase difference between fsw and GPIO6 when configured as SYNC(O). | 180  |     |     | degrees |
| SYNC IN                                        |                                                                    |                                                                    |      |     |     |         |
| f <sub>SYNC(300kHz)</sub>                      | Valid external clock frequency (f <sub>SW_internal</sub> = 300kHz) |                                                                    | 250  |     | 353 | kHz     |
| f <sub>SYNC(400kHz)</sub>                      | Valid external clock frequency (f <sub>SW_internal</sub> = 400kHz) |                                                                    | 334  |     | 470 | kHz     |
| f <sub>SYNC(450kHz)</sub>                      | Valid external clock frequency (f <sub>SW_internal</sub> = 450kHz) |                                                                    | 376  |     | 530 | kHz     |

(1) GPIO9 is normally configured as I2C\_IRQ1m (master): input pin. I2C specification requires use of external pullup resistor. Input thresholds (V<sub>IH</sub>; V<sub>IL</sub>) leakage current (I<sub>I(LEAKAGE)</sub>) and deglitch timing (t<sub>DG</sub>) specifications are apply when used as I2C\_IRQ1m. Internal pullup and pulldown resistors are not used during this mode of operation.

- (2) GPIO9 or GPIO1 may be configured as I2C\_IRQ2s (slave): open-drain output pin. I2C specification requires use of external pullup resistor. Output threshold ( $V_{OL}$ ) applies. Internal pullup and pulldown resistors are not used during this mode of operation.

## 7.15 BC1.2 Characteristics

Typical values correspond to  $T_J = 25^\circ\text{C}$ . Minimum and maximum limits apply over the  $-40^\circ\text{C}$  to  $150^\circ\text{C}$  junction temperature range unless otherwise stated.  $V_{IN} = 13.5\text{ V}$ ,  $EN = 2\text{ V}$ , unless otherwise stated.

| PARAMETER                        |                                                            | TEST CONDITIONS                                                                          | MIN   | TYP   | MAX  | UNIT |
|----------------------------------|------------------------------------------------------------|------------------------------------------------------------------------------------------|-------|-------|------|------|
| BC1.2 RESISTANCES                |                                                            |                                                                                          |       |       |      |      |
| R <sub>DCP_DAT</sub>             | Dedicated Charging Port Resistance between Px_DP and Px_DM | V <sub>Px_DP</sub> = 0.6 V, V <sub>Px_DM</sub> = 0V, measure DP to DM shorted resistance |       |       | 200  | Ω    |
| R <sub>DM_DWN_15k</sub>          | Px_DM line pulldown resistance                             | V <sub>Px_DM</sub> = 3.6V                                                                | 12    | 15    | 18   | kΩ   |
| R <sub>DM_DWN_20k</sub>          | Px_DM line pulldown resistance                             | V <sub>Px_DM</sub> = 3.6V                                                                | 14.25 | 19.53 | 24.8 | kΩ   |
| DIVIDER MODES                    |                                                            |                                                                                          |       |       |      |      |
| V <sub>2.7V</sub>                | Output Voltage on DPy pin                                  | No load on DPy pin                                                                       | 2.57  | 2.7   | 2.83 | V    |
| V <sub>2.7V</sub>                | Output Voltage on DMy pin                                  | No load on DMy pin                                                                       | 2.57  | 2.7   | 2.83 | V    |
| R <sub>2.7V</sub>                | Output Impedance on DPy                                    | 5μA pulled from DPy pin                                                                  | 24    | 30    | 36   | kΩ   |
| R <sub>2.7V</sub>                | Output Impedance on DMy                                    | 5μA pulled from DMy pin                                                                  | 24    | 30    | 36   | kΩ   |
| V <sub>1.2V</sub>                | Output Voltage on DMy                                      | No load on DMy                                                                           | 1.12  | 1.2   | 1.28 | V    |
| R <sub>1.2V</sub>                | Output Impedance on DMy                                    | 5μA pulled from DMy                                                                      | 80    | 102   | 130  | kΩ   |
| HVDCP THRESHOLD VOLTAGES         |                                                            |                                                                                          |       |       |      |      |
| V <sub>DAT_REF</sub>             | Data detection voltage on DP or DM pin                     |                                                                                          | 0.25  | 0.325 | 0.4  | V    |
| V <sub>SEL_REF</sub>             | Output selection voltage DP or DM pin                      |                                                                                          | 1.8   | 2     | 2.2  | V    |
| DP AND DM OVERVOLTAGE PROTECTION |                                                            |                                                                                          |       |       |      |      |
| V <sub>Dy_OVP</sub>              | OVP detection threshold for USB Px_DP and Px_DM pins       | Initially V <sub>PxDy</sub> ≤ 3.6 V, then V <sub>PxDy</sub> rises.                       | 5.5   |       | 8.5  | V    |

## 7.16 I2C Requirements and Characteristics

Typical values correspond to  $T_J = 25^\circ\text{C}$ . Minimum and maximum limits apply over the  $-40^\circ\text{C}$  to  $150^\circ\text{C}$  junction temperature range unless otherwise stated.  $V_{IN} = 13.5\text{ V}$ ,  $EN = 2\text{ V}$ , unless otherwise stated.  $V_{DD} = \text{I2C pullup voltage (3.3 V or 1.8 V)}$

| PARAMETER                                                    |                                                                                       | TEST CONDITIONS                               | MIN | TYP   | MAX  | UNIT |
|--------------------------------------------------------------|---------------------------------------------------------------------------------------|-----------------------------------------------|-----|-------|------|------|
| I2C_IRQ1s, I2C_IRQ2                                          |                                                                                       |                                               |     |       |      |      |
| I2C_IRQ1m                                                    |                                                                                       |                                               |     |       |      |      |
| SDA and SCL Characteristics (Standard, Fast, Fast-mode Plus) |                                                                                       |                                               |     |       |      |      |
| V <sub>IL</sub>                                              | Input low signal                                                                      |                                               |     |       | 0.54 | V    |
| V <sub>IH</sub>                                              | Input high signal                                                                     |                                               |     | 1.3   |      | V    |
| V <sub>DD</sub> = 3.3 V INPUT LOGIC THRESHOLDS               |                                                                                       |                                               |     |       |      |      |
| V <sub>IL</sub>                                              | Input low signal                                                                      |                                               |     |       | 0.9  | V    |
| V <sub>IH</sub>                                              | Input high signal                                                                     |                                               |     | 2.31  |      | V    |
| V <sub>HYS</sub>                                             | Input hysteresis                                                                      |                                               |     | 0.165 |      | V    |
| V <sub>OL</sub>                                              | Output low voltage                                                                    | V <sub>DD</sub> = 1.8V, I <sub>OL</sub> =2 mA |     |       | 0.36 |      |
| V <sub>OL</sub>                                              | Output low voltage                                                                    | V <sub>DD</sub> = 3.3V, I <sub>OL</sub> =3 mA |     |       | 0.4  | V    |
| I <sub>OL</sub>                                              | Max output low current                                                                | V <sub>OL</sub> =0.4 V                        |     | 12    |      | mA   |
| I <sub>LEAK</sub>                                            | Input leakage current                                                                 | Voltage on pin = 3.3V                         |     | −5    | 5    | μA   |
| C <sub>I</sub>                                               | pin capacitance (internal)                                                            |                                               |     |       | 10   | pF   |
| C <sub>b</sub>                                               | Capacitive load for each bus line (external). Applies in Standard-mode and Fast-mode. |                                               |     |       | 400  | pF   |

Typical values correspond to  $T_J = 25^\circ\text{C}$ . Minimum and maximum limits apply over the  $-40^\circ\text{C}$  to  $150^\circ\text{C}$  junction temperature range unless otherwise stated.  $V_{IN} = 13.5\text{ V}$ ,  $EN = 2\text{ V}$ , unless otherwise stated.  $V_{DD} = \text{I}^2\text{C}$  pullup voltage (3.3 V or 1.8 V)

| PARAMETER                                          |                                                                               | TEST CONDITIONS                                                                                                                                        | MIN                | TYP | MAX                 | UNIT |
|----------------------------------------------------|-------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|-----|---------------------|------|
| $C_b$                                              | Capacitive load for each bus line (external). Applies in Fast-mode Plus.      |                                                                                                                                                        |                    |     | 550                 | pF   |
| <b>COMMON TIMING</b>                               |                                                                               |                                                                                                                                                        |                    |     |                     |      |
| $t_{SP}$                                           | I <sup>2</sup> C pulse width suppressed                                       |                                                                                                                                                        |                    |     | 50                  | ns   |
| <b>SDA and SCL Characteristics (Standard Mode)</b> |                                                                               |                                                                                                                                                        |                    |     |                     |      |
| $f_{SCLS}$                                         | Clock frequency (slave)                                                       | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$                                                                                                              |                    |     | 100                 | kHz  |
| $t_{HD,STA}$                                       | Start or repeated start condition hold time                                   | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$                                                                                                              | 4                  |     |                     | μs   |
| $t_{LOW}$                                          | SCL Clock low time                                                            | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$                                                                                                              | 4.7                |     |                     | μs   |
| $t_{HIGH}$                                         | SCL Clock high time                                                           | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$                                                                                                              | 4                  |     |                     | μs   |
| $t_{SU,STA}$                                       | Start or repeated start condition setup time                                  | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$                                                                                                              | 4.7                |     |                     | μs   |
| $t_{HD,DAT}$                                       | Serial data hold time <sup>(1)</sup>                                          | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$                                                                                                              | 0 <sup>(2)</sup>   |     | - <sup>(3)</sup>    | ns   |
| $t_{SU,DAT}$                                       | Serial data setup time                                                        | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$                                                                                                              | 250                |     |                     | ns   |
| $t_r$                                              | Rise time of SCL and SDA signals                                              | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$ ; $R_{PU} = 2.8\text{ k}\Omega$ ; $C_b = 400\text{ pF}$ ; measure $0.3 \times V_{DD}$ to $0.7 \times V_{DD}$ |                    |     | 1000                | ns   |
| $t_{of}$                                           | Output fall time from $V_{IH(MIN)}$ to $V_{IL(MAX)}$                          | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$ ; measure $0.3 \times V_{DD}$ to $0.7 \times V_{DD}$                                                         |                    |     | 250 <sup>(4)</sup>  | ns   |
| $t_f$                                              | Fall time of SCL and SDA signals <sup>(2)</sup> <sup>(4)</sup> <sup>(5)</sup> | $V_{DD} = 1.8\text{ V}$ , $R_{PU} = 2.8\text{ k}\Omega$ ; $10\text{ pF} \leq C_b \leq 400\text{ pF}$                                                   |                    |     | 300                 | ns   |
| $t_f$                                              | Fall time of SCL and SDA signals <sup>(2)</sup> <sup>(4)</sup> <sup>(5)</sup> | $V_{DD} = 3.3\text{ V}$ , $R_{PU} = 2.8\text{ k}\Omega$ ; $10\text{ pF} \leq C_b \leq 400\text{ pF}$                                                   |                    |     | 300                 | ns   |
| $t_{SU,STO}$                                       | Stop condition setup time                                                     | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$                                                                                                              | 4                  |     |                     | μs   |
| $t_{BUF}$                                          | Bus free time between stop and start                                          | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$                                                                                                              | 4.7                |     |                     | μs   |
| $t_{VD,DAT}$                                       | Valid data time <sup>(6)</sup>                                                | Transmitting Data; $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$ , SCL low to SDA output valid                                                             |                    |     | 3.45 <sup>(3)</sup> | μs   |
| $t_{VD,ACK}$                                       | Valid data time of ACK condition                                              | Transmitting Data; $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$ , ACK signal from SCL low to SDA valid                                                    |                    |     | 3.45 <sup>(3)</sup> | μs   |
| <b>SDA and SCL Characteristics (Fast Mode)</b>     |                                                                               |                                                                                                                                                        |                    |     |                     |      |
| $f_{SCLS}$                                         | Clock frequency (slave)                                                       | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$                                                                                                              |                    |     | 400                 | kHz  |
| $t_{HD,STA}$                                       | Start or repeated start condition hold time                                   | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$                                                                                                              | 0.6                |     |                     | μs   |
| $t_{LOW}$                                          | SCL Clock low time                                                            | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$                                                                                                              | 1.3                |     |                     | μs   |
| $t_{HIGH}$                                         | SCL Clock high time                                                           | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$                                                                                                              | 0.6                |     |                     | μs   |
| $t_{SU,STA}$                                       | Start or repeated start condition setup time                                  | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$                                                                                                              | 0.6                |     |                     | μs   |
| $t_{HD,DAT}$                                       | Serial data hold time <sup>(1)</sup>                                          | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$                                                                                                              | 0 <sup>(2)</sup>   |     | - <sup>(3)</sup>    | ns   |
| $t_{SU,DAT}$                                       | Serial data setup time                                                        | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$                                                                                                              | 100 <sup>(7)</sup> |     |                     | ns   |
| $t_r$                                              | Rise time of SCL and SDA signals                                              | $V_{DD} = 1.8\text{ V}$ or $3.3\text{ V}$ ; $R_{PU} = 850\text{ }\Omega$ ; $C_b = 400\text{ pF}$ ; measure $0.3 \times V_{DD}$ to $0.7 \times V_{DD}$  | 20                 |     | 300                 | ns   |
| $t_{of}$                                           | Output fall time from $V_{IH(MIN)}$ to $V_{IL(MAX)}$                          | $V_{DD} = 1.8\text{ V}$ ; measure $0.3 \times V_{DD}$ to $0.7 \times V_{DD}$                                                                           | 6.55               |     | 250 <sup>(4)</sup>  | ns   |
| $t_{of}$                                           | Output fall time from $V_{IH(MIN)}$ to $V_{IL(MAX)}$                          | $V_{DD} = 3.3\text{ V}$ ; measure $0.3 \times V_{DD}$ to $0.7 \times V_{DD}$                                                                           | 12                 |     | 250 <sup>(4)</sup>  | ns   |

Typical values correspond to  $T_J = 25^\circ\text{C}$ . Minimum and maximum limits apply over the  $-40^\circ\text{C}$  to  $150^\circ\text{C}$  junction temperature range unless otherwise stated.  $V_{IN} = 13.5\text{ V}$ ,  $EN = 2\text{ V}$ , unless otherwise stated.  $V_{DD} = \text{I}^2\text{C}$  pullup voltage (3.3 V or 1.8 V)

| PARAMETER    |                                                 | TEST CONDITIONS                                                                                       | MIN  | TYP | MAX     | UNIT          |
|--------------|-------------------------------------------------|-------------------------------------------------------------------------------------------------------|------|-----|---------|---------------|
| $t_f$        | Fall time of SCL and SDA signals<br>(2) (4) (5) | $V_{DD} = 1.8\text{V}$ ; $R_{PU} = 850\ \Omega$ ; $10\text{ pF} \leq C_b \leq 400\text{ pF}$          | 6.55 |     | 300     | ns            |
| $t_f$        | Fall time of SCL and SDA signals<br>(2) (4) (5) | $V_{DD} = 3.3\text{V}$ ; $R_{PU} = 850\ \Omega$ ; $10\text{ pF} \leq C_b \leq 400\text{ pF}$          | 12   |     | 300     | ns            |
| $t_{SU,STO}$ | Stop condition setup time                       | $V_{DD} = 1.8\text{V}$ or $3.3\text{V}$                                                               | 0.6  |     |         | $\mu\text{s}$ |
| $t_{BUF}$    | Bus free time between stop and start            | $V_{DD} = 1.8\text{V}$ or $3.3\text{V}$                                                               | 1.3  |     |         | $\mu\text{s}$ |
| $t_{VD,DAT}$ | Valid data time (6)                             | Transmitting Data; $V_{DD} = 1.8\text{V}$ or $3.3\text{V}$ , SCL low to SDA output valid              |      |     | 0.9 (3) | $\mu\text{s}$ |
| $t_{VD,ACK}$ | Valid data time of ACK condition                | Transmitting Data; $V_{DD} = 1.8\text{V}$ or $3.3\text{V}$ , ACK signal from SCL low to SDA (out) low |      |     | 0.9 (3) | $\mu\text{s}$ |

- (1)  $t_{HD,DAT}$  = the data hold time that is measured from the falling edge of SCL, applies to data in transmission and the acknowledge.
- (2) A device must internally provide a hold time of at least 300 ns for the SDA signal (with respect to the  $V_{IH(MIN)}$  of the SCL signal) to bridge the undefined region of the falling edge of SCL.
- (3) The maximum  $t_{HD,DAT}$  could be 3.45  $\mu\text{s}$  and 0.9  $\mu\text{s}$  for Standard-mode and Fast-mode, but must be less than the maximum  $t_{VD,DAT}$  or  $t_{VD,ACK}$  by a transition time. This maximum must only be met if the device does not stretch the LOW period ( $t_{LOW}$ ) of the SCL signal. If the clock stretches the SCL, the data must be valid by the setup time before it releases the clock.
- (4) The maximum  $t_f$  for the SDA and SCL bus lines is stated in these tables as 300 ns is longer than the specified maximum  $t_{of}$  for the output stages (250 ns). This allows series protection resistors ( $R_S$ ) to be connected between the SDA and SCL pins and the SDA and SCL bus lines without exceeding the maximum specified  $t_f$ .
- (5) In Fast-mode Plus, fall time is specified the same for both output stage and bus timing. If series resistors ( $R_S$ ) are used, designers should allow for this when considering bus timing.
- (6)  $t_{VD,DAT}$  = time for data signal from SCL LOW to SDA output (HIGH or LOW, depending on which one is worse).
- (7) A Fast-mode I<sup>2</sup>C-bus device can be used in a Standard-mode I<sup>2</sup>C-bus system, but the requirement  $t_{SU,DAT}$  250 ns must then be met. This will automatically be the case if the device does not stretch the LOW period of the SCL signal. If such a device does stretch the LOW period of the SCL signal, it must output the next data bit to the SDA line  $t_{r(max)} + t_{SU,DAT} = 1000 + 250 = 1250\text{ ns}$  (according to the Standard-mode I<sup>2</sup>C-bus specification) before the SCL line is released. Also the acknowledge timing must meet this set-up time.

## 7.17 Typical Characteristics

At  $V_{IN} = 12\text{ V}$ ,  $f_{sw} = 400\text{ kHz}$ , unless otherwise stated.

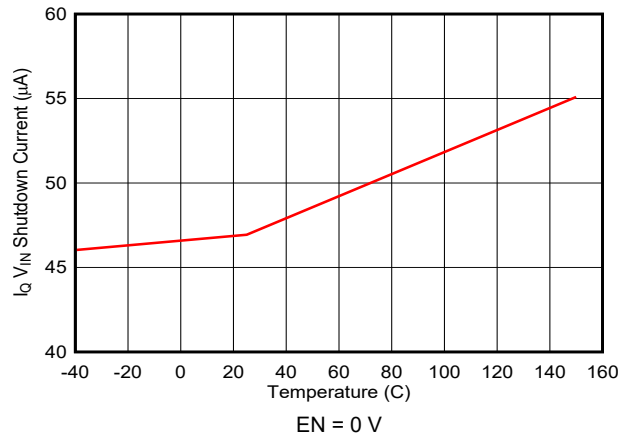


Figure 7-1.  $I_{Q V_{IN}}$  Shutdown Current vs Temperature

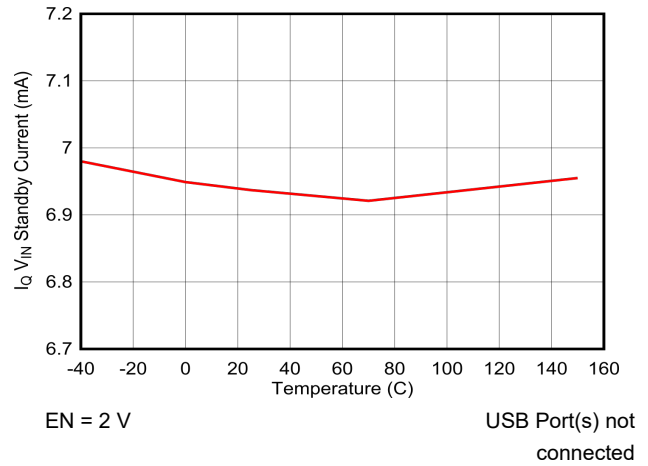


Figure 7-2.  $I_{Q V_{IN}}$  Standby Current vs Temperature

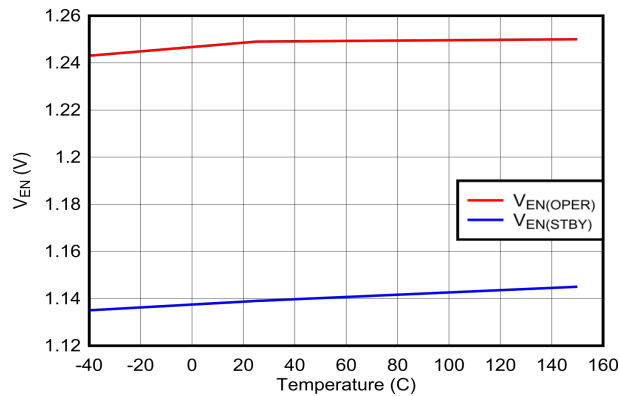


Figure 7-3. ENABLE/UVLO Thresholds vs Temperature

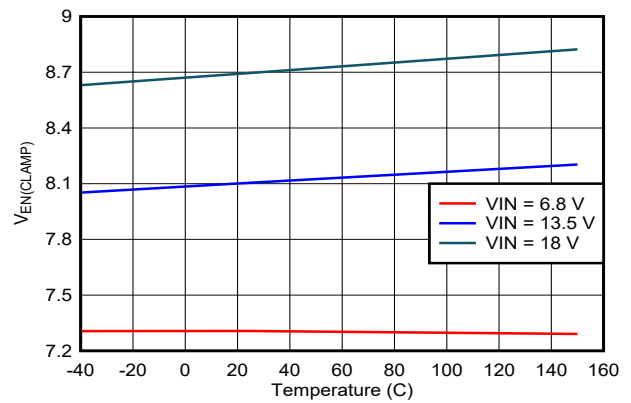


Figure 7-4. EN Clamp Voltage vs Temperature

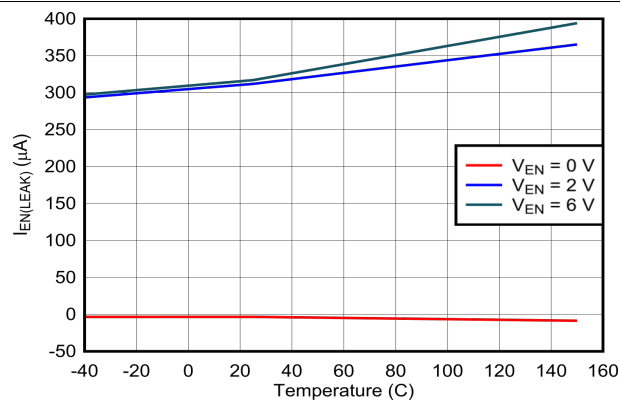


Figure 7-5. EN Leakage Current vs Temperature

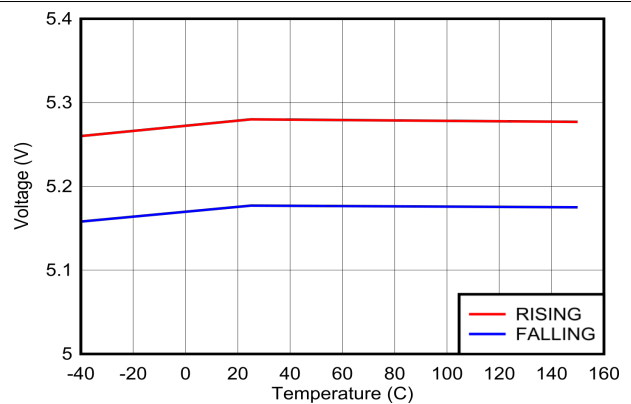


Figure 7-6.  $V_{\text{IN(UVLO)}}$  vs Temperature

## 7.17 Typical Characteristics (continued)

At  $V_{IN} = 12\text{ V}$ ,  $f_{sw} = 400\text{ kHz}$ , unless otherwise stated.

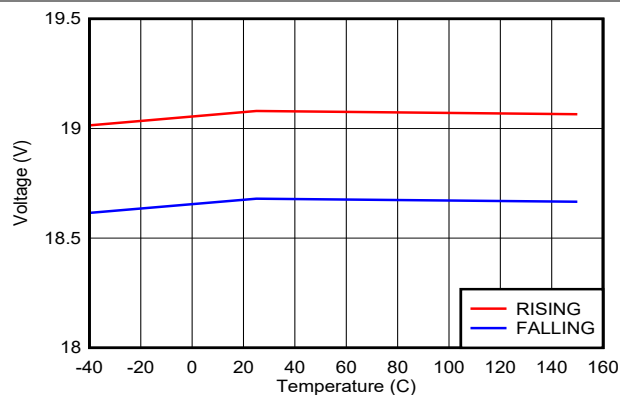


Figure 7-7.  $V_{IN(OVP)}$  vs Temperature

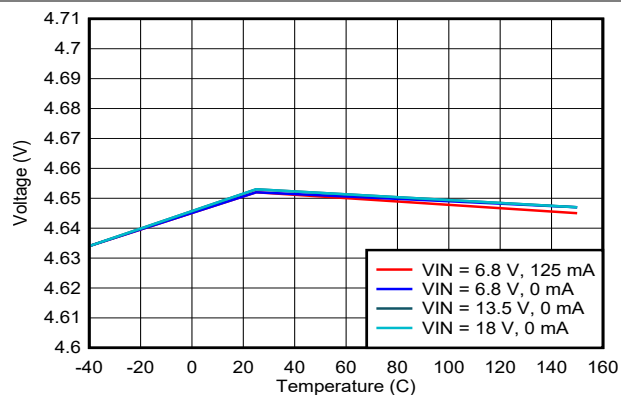


Figure 7-8. LDO\_5V vs  $V_{IN}$  and Temperature

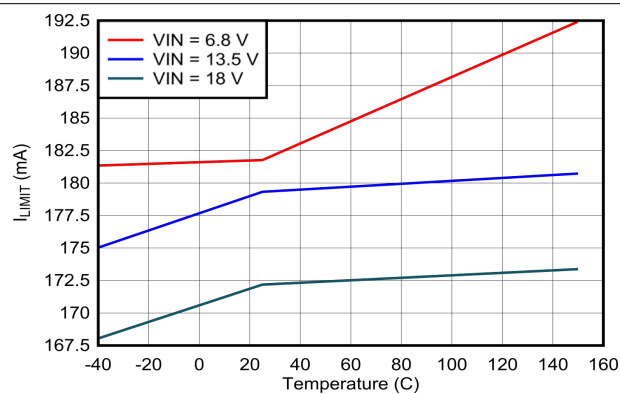


Figure 7-9. LDO\_5V Current Limit vs  $V_{IN}$  and Temperature

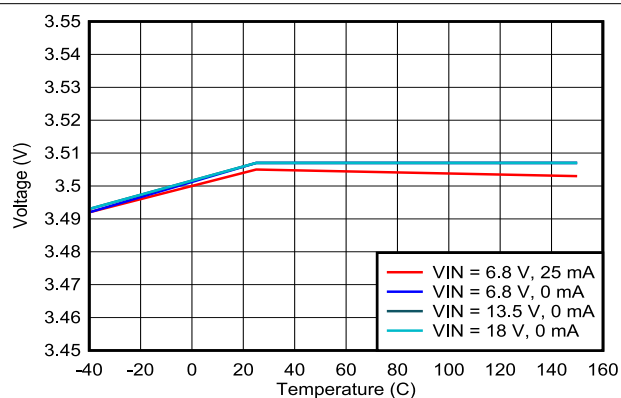


Figure 7-10. LDO\_3V3 vs  $V_{IN}$  and Temperature

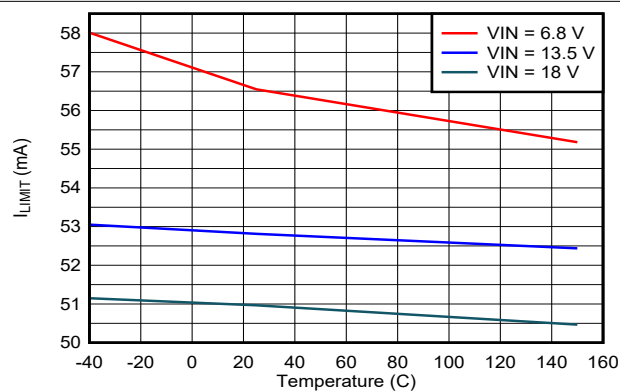


Figure 7-11. LDO\_3V3 Current Limit vs  $V_{IN}$  and Temperature

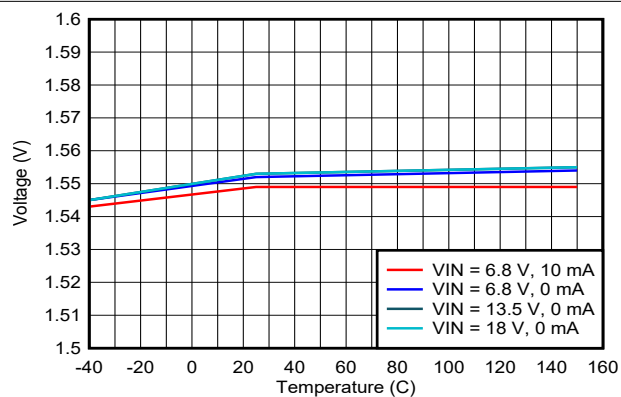


Figure 7-12. LDO\_1V5 vs  $V_{IN}$  and Temperature

## 7.17 Typical Characteristics (continued)

At  $V_{IN} = 12\text{ V}$ ,  $f_{sw} = 400\text{ kHz}$ , unless otherwise stated.

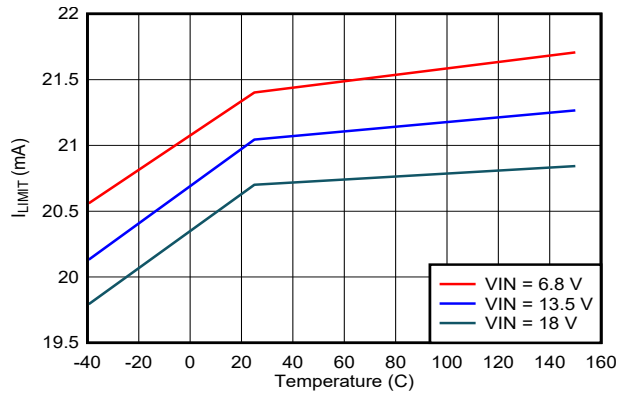


Figure 7-13. LDO\_1V5 Current Limit vs  $V_{IN}$  and Temperature

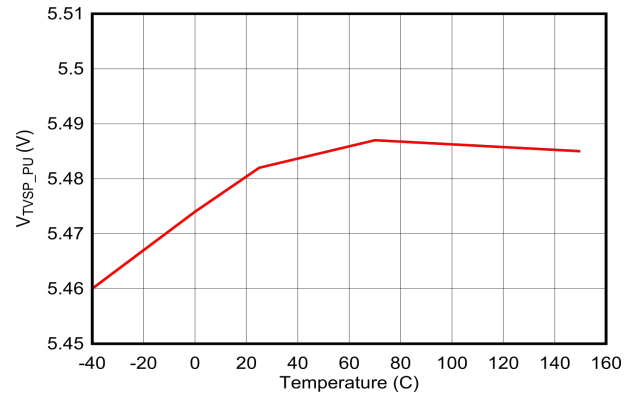


Figure 7-14.  $V_{TVSP\_PU}$  vs Temperature

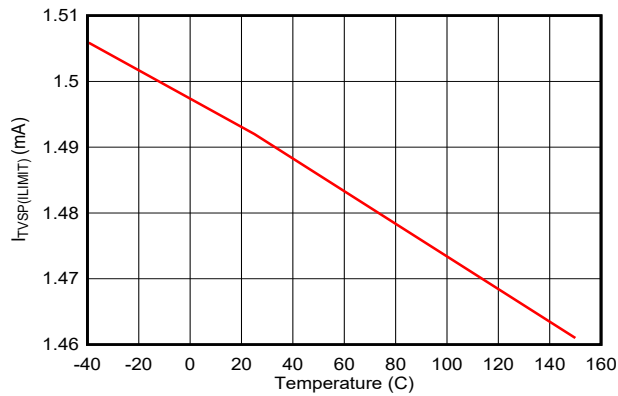


Figure 7-15.  $I_{TVSP(ILIMIT)}$  vs Temperature

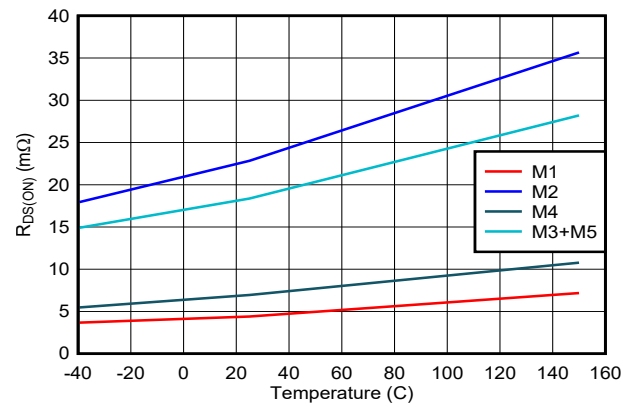


Figure 7-16. Buck-Boost Power FET  $R_{DS(ON)}$  vs Temperature

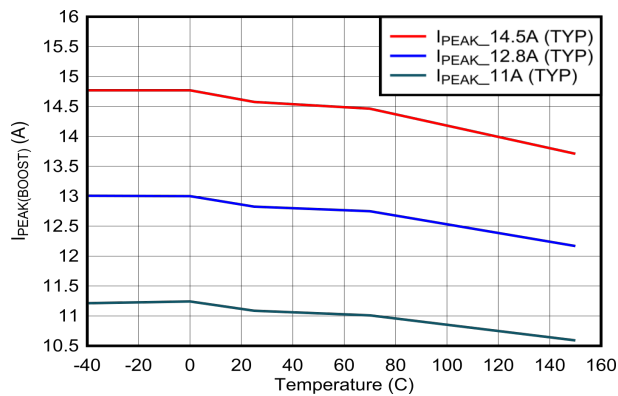


Figure 7-17. Boost Peak Current Limit vs Temperature (upper settings)

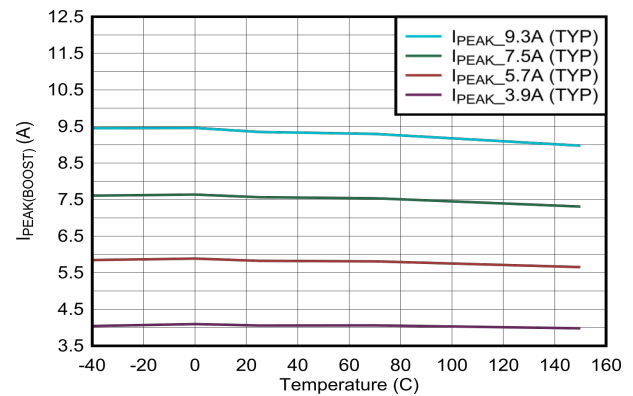


Figure 7-18. Boost Peak Current Limit vs Temperature (lower settings)

## 7.17 Typical Characteristics (continued)

At  $V_{IN} = 12\text{ V}$ ,  $f_{sw} = 400\text{ kHz}$ , unless otherwise stated.

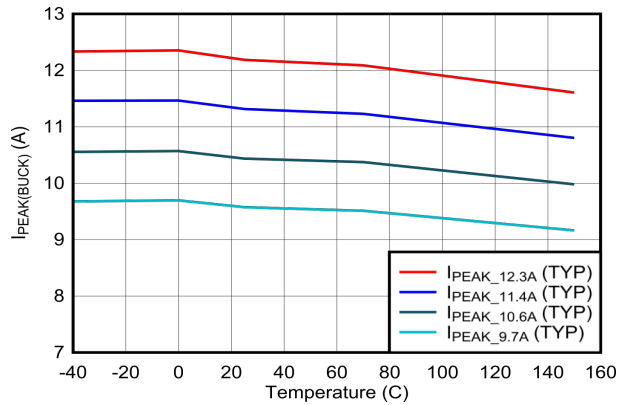


Figure 7-19. Buck Peak Current Limit vs Temperature (upper settings)

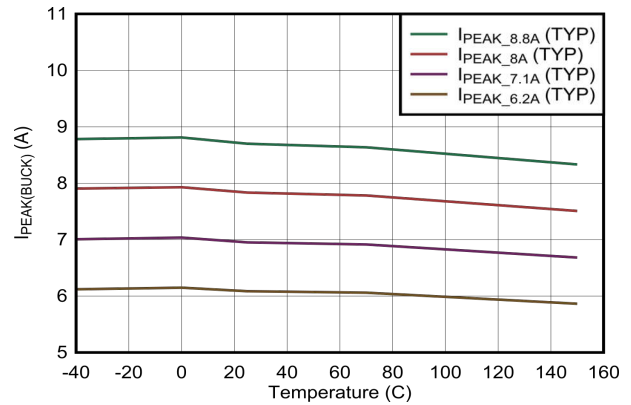


Figure 7-20. Buck Peak Current Limit vs Temperature (lower settings)

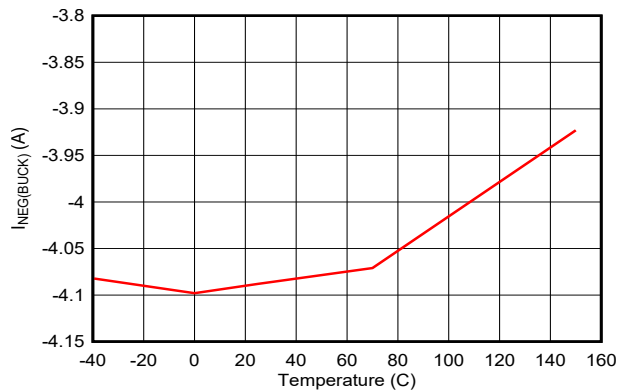


Figure 7-21. Buck Negative Current Limit vs Temperature

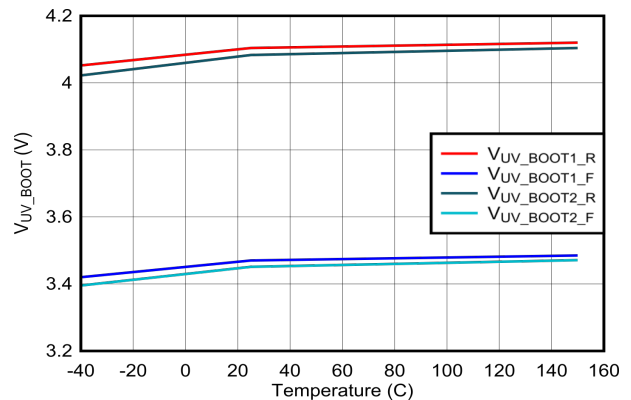


Figure 7-22. BOOTx UVLO vs Temperature

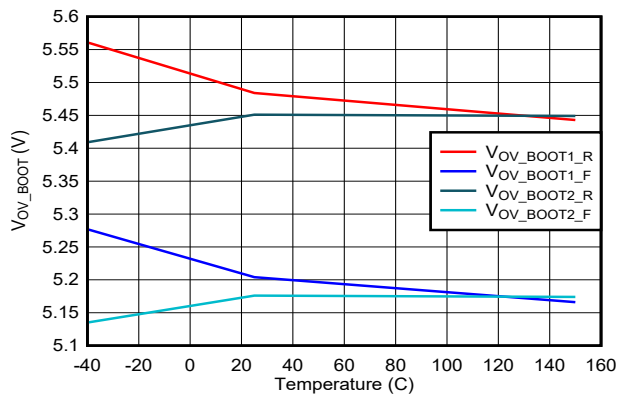


Figure 7-23. BOOTx OVP vs Temperature

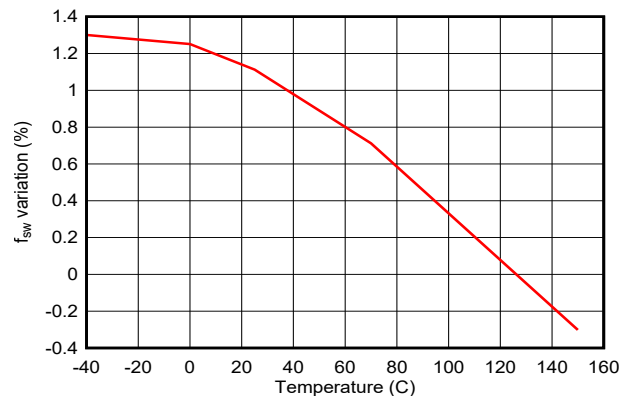


Figure 7-24. Buck-Boost Switching Frequency Variation vs Temperature

## 7.17 Typical Characteristics (continued)

At  $V_{IN} = 12\text{ V}$ ,  $f_{sw} = 400\text{ kHz}$ , unless otherwise stated.

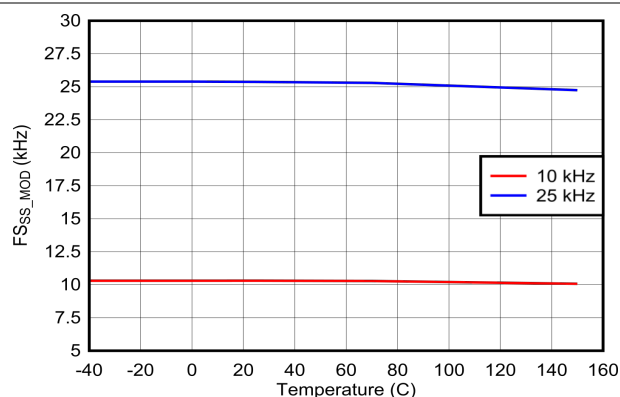
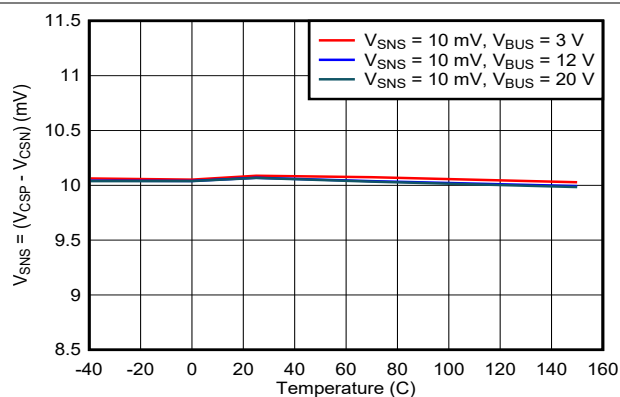
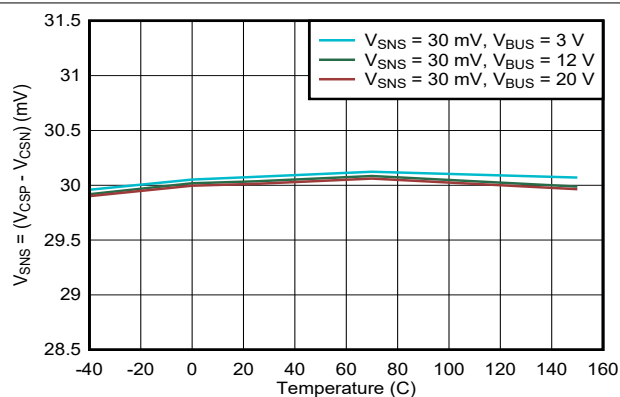


Figure 7-25.  $f_{sw}$  Dither Modulation Frequency vs Temperature



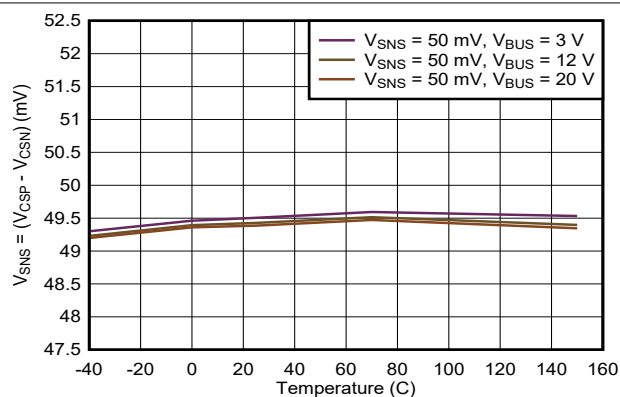
Target  $V_{SNS}$  for Current Limit = 10 mV  
Current Limiting Engaged

Figure 7-26. Current Loop Regulation Voltage vs  $V_{BUS}$  and Temperature



Target  $V_{SNS}$  for Current Limit = 30 mV  
Current Limiting Engaged

Figure 7-27. Current Loop Regulation Voltage vs  $V_{BUS}$  and Temperature



Target  $V_{SNS}$  for Current Limit = 50 mV  
Current Limiting Engaged

Figure 7-28. Current Loop Regulation Voltage vs  $V_{BUS}$  and Temperature

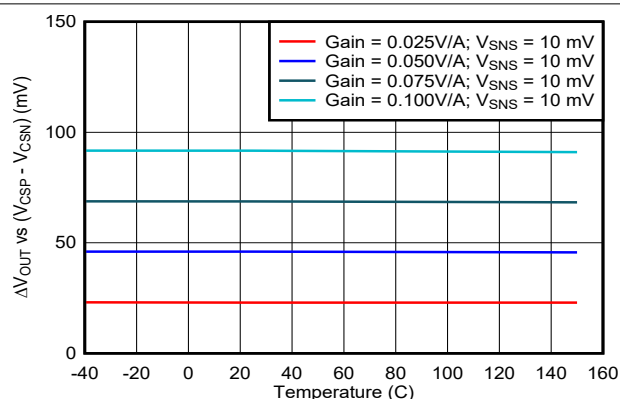


Figure 7-29. Cable Voltage Droop Compensation vs Temperature

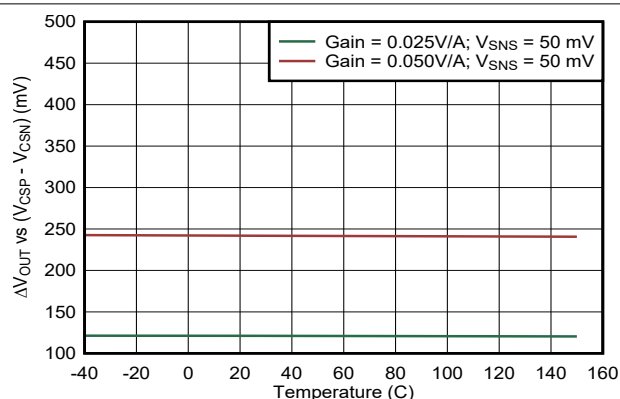
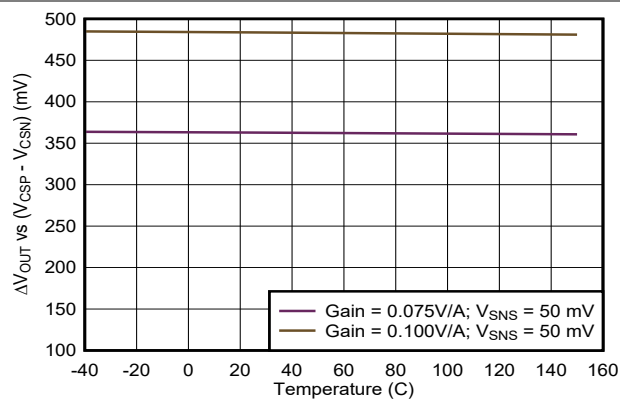


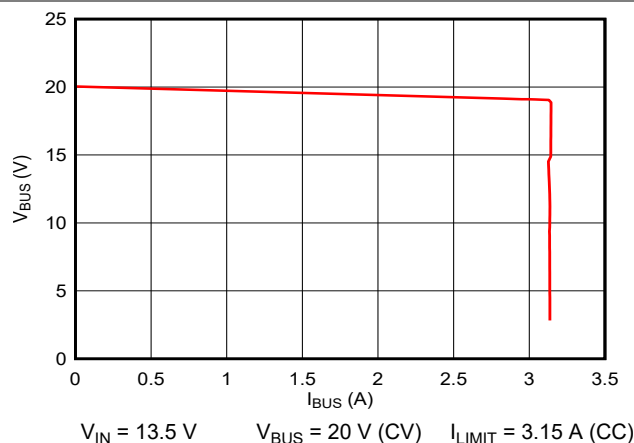
Figure 7-30. Cable Voltage Droop Compensation vs Temperature

## 7.17 Typical Characteristics (continued)

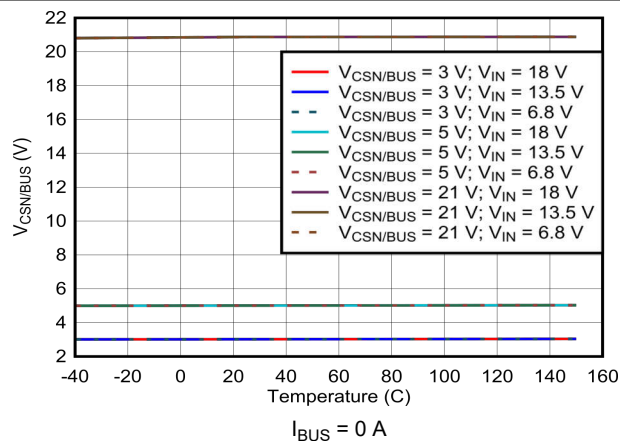
At  $V_{IN} = 12\text{ V}$ ,  $f_{sw} = 400\text{ kHz}$ , unless otherwise stated.



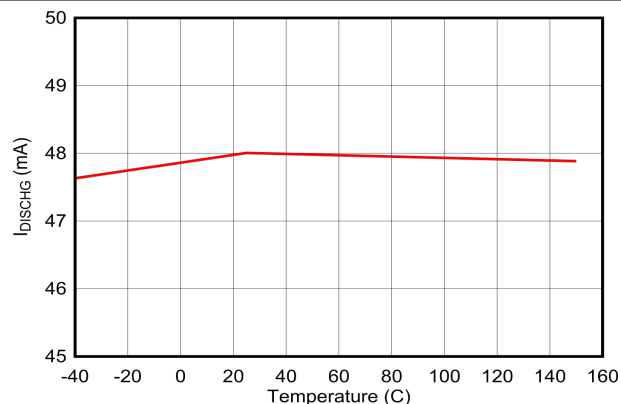
7-31. Cable Voltage Droop Compensation vs Temperature



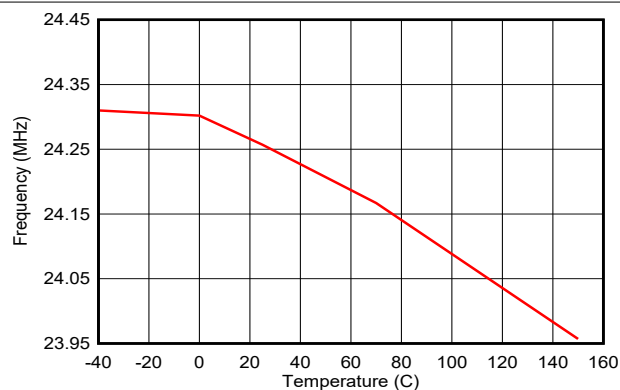
7-32. Constant Voltage to Constant Current Transition



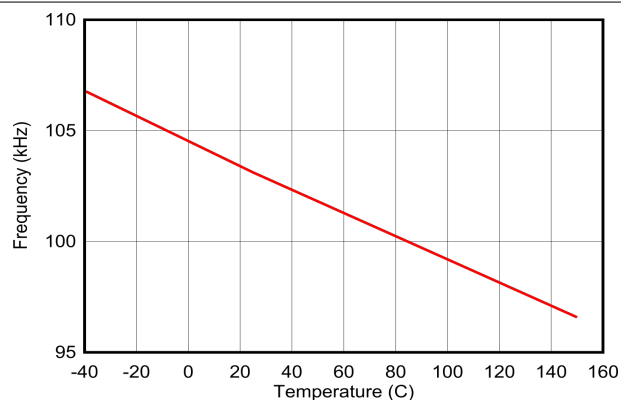
7-33. Buck-boost Output Voltage Regulation vs Temperature



7-34.  $V_{BUS}$  Discharge Current vs Temperature



7-35. (M0) 24 MHz Oscillator vs Temperature



7-36. (M0) 100 kHz Oscillator vs Temperature

## 7.17 Typical Characteristics (continued)

At  $V_{IN} = 12\text{ V}$ ,  $f_{SW} = 400\text{ kHz}$ , unless otherwise stated.

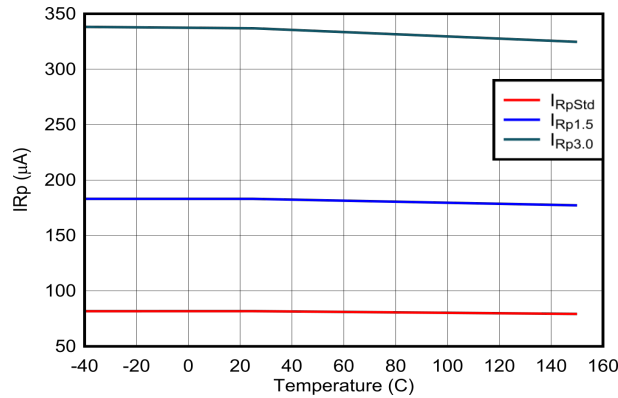


Figure 7-37. Type-C Cable Detect:  $I_{Rp}$  vs Temperature

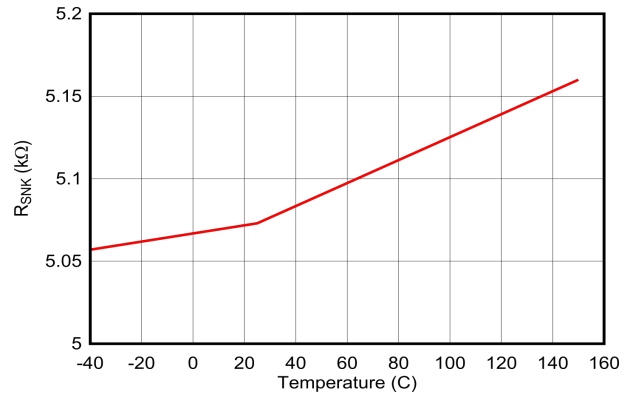


Figure 7-38. Type-C Cable Detect:  $R_{SNK}$  vs Temperature

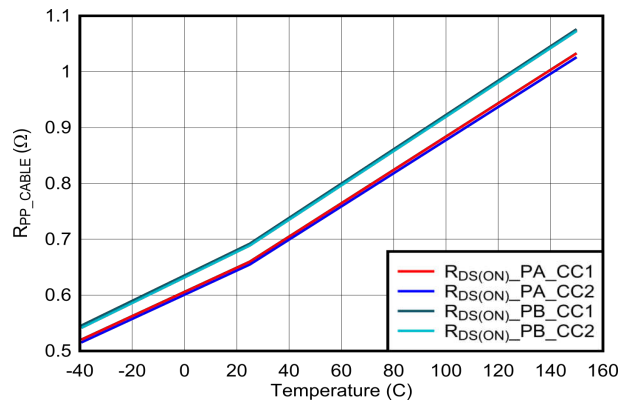


Figure 7-39.  $V_{CONN}$  Power Path:  $R_{DS(ON)}$  vs Temperature

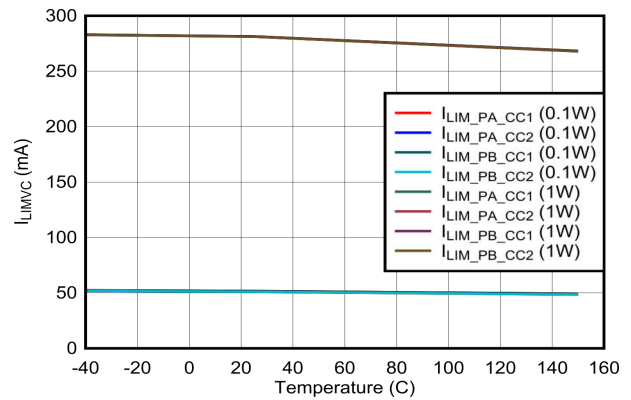


Figure 7-40.  $V_{CONN}$  Power Path: Current Limit vs Temperature

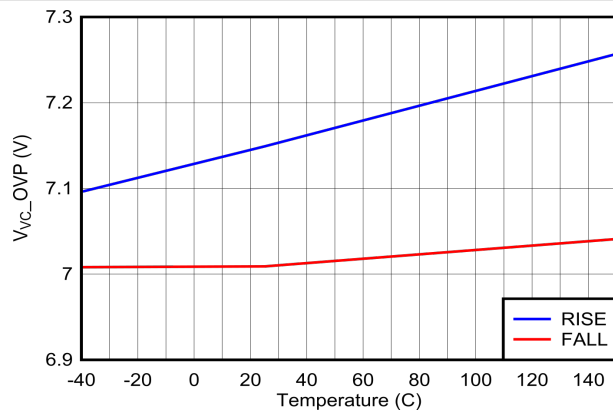


Figure 7-41. Type-C Cable Detect &  $V_{CONN}$ : Over-voltage Protection Thresholds vs Temperature

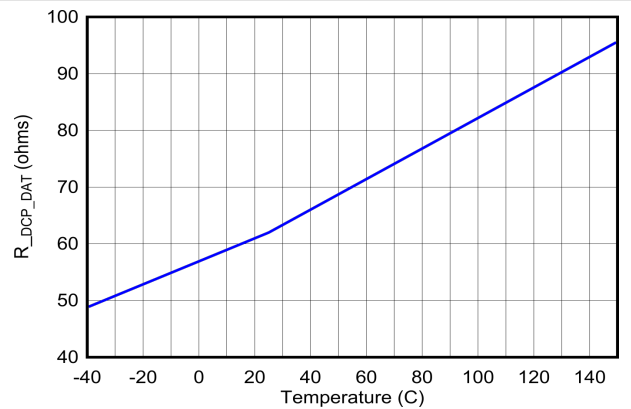


Figure 7-42. USB BC1.2: DP to DM Shorting Resistance,  $R_{DCP\_DAT}$

## 7.17 Typical Characteristics (continued)

At  $V_{IN} = 12\text{ V}$ ,  $f_{SW} = 400\text{ kHz}$ , unless otherwise stated.

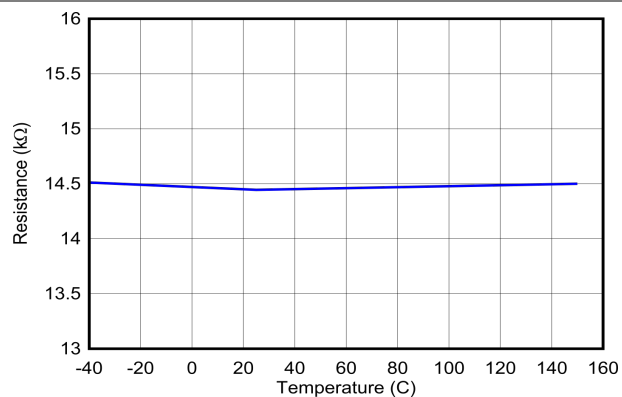


Figure 7-43. USB BC1.2: DM to AGND 15 kΩ Resistance,  $R_{DM\_DWN\_15k}$

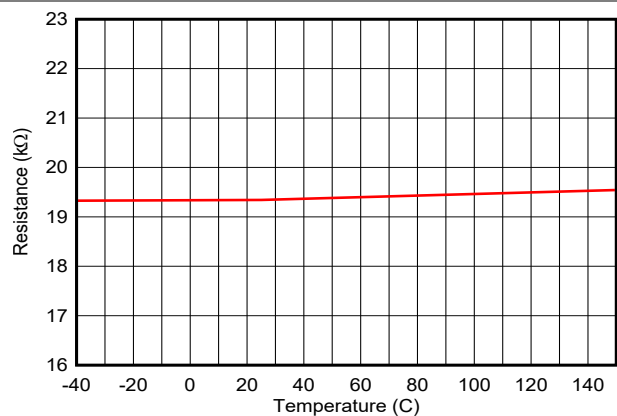


Figure 7-44. USB BC1.2: DM to AGND 20 kΩ Resistance,  $R_{DM\_DWN\_20k}$

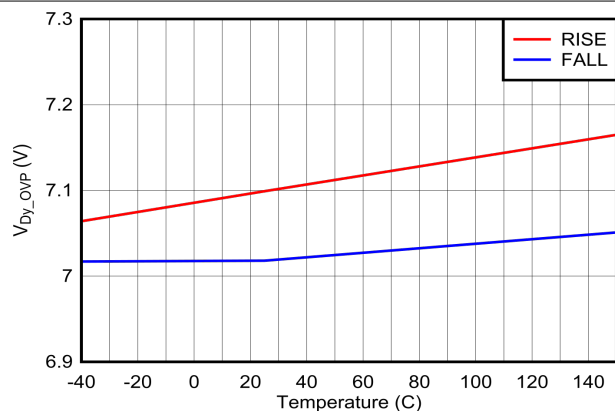


Figure 7-45. USB BC1.2: DP and DM Pin Over-voltage Protection Thresholds vs Temperature

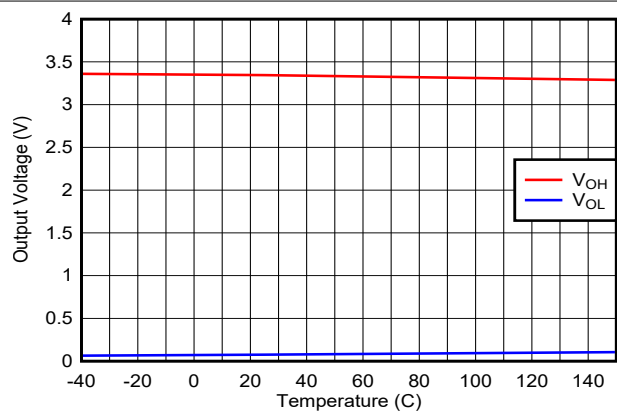


Figure 7-46. GPIO: Output Voltage vs Output Current and Temperature  
GPIO 0, 1, 4, 7, 8, 9  
 $I_O = \pm 2\text{ mA}$

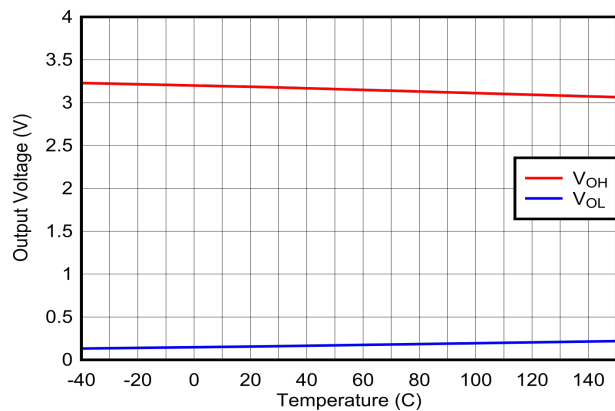


Figure 7-47. GPIO: Output Voltage vs Output Current and Temperature  
GPIO 2, 3, 5, 6  
 $I_O = \pm 5\text{ mA}$

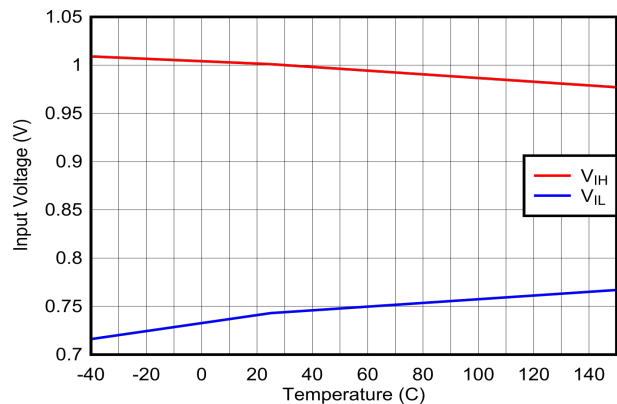
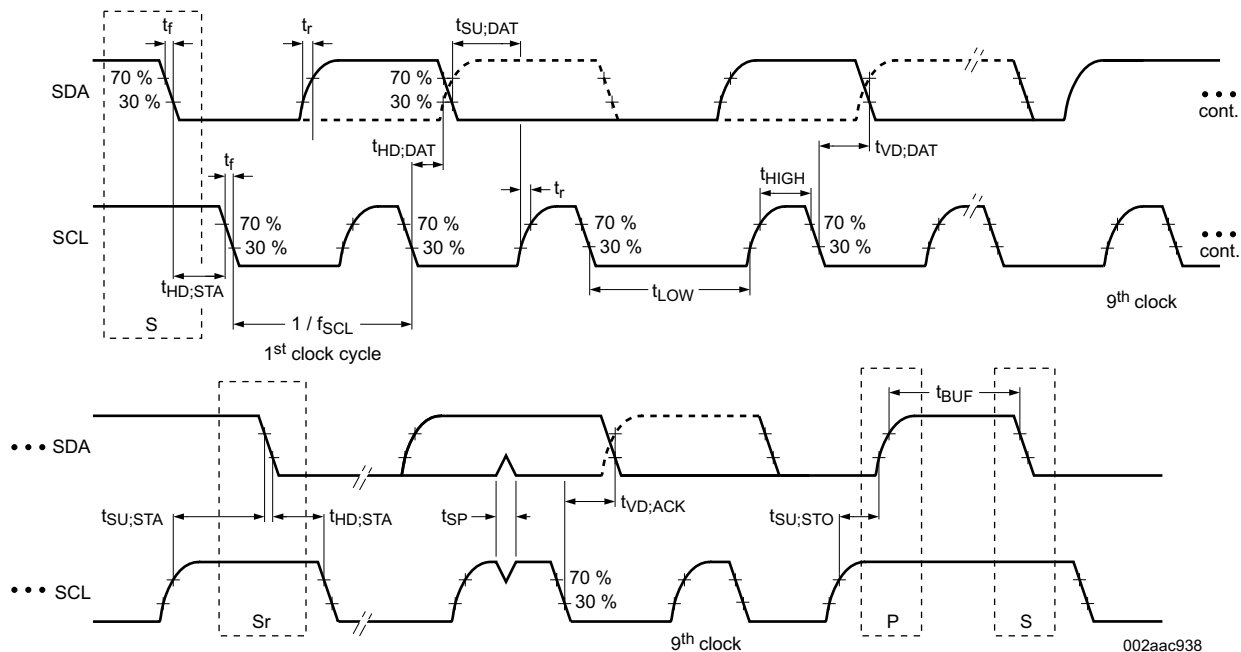
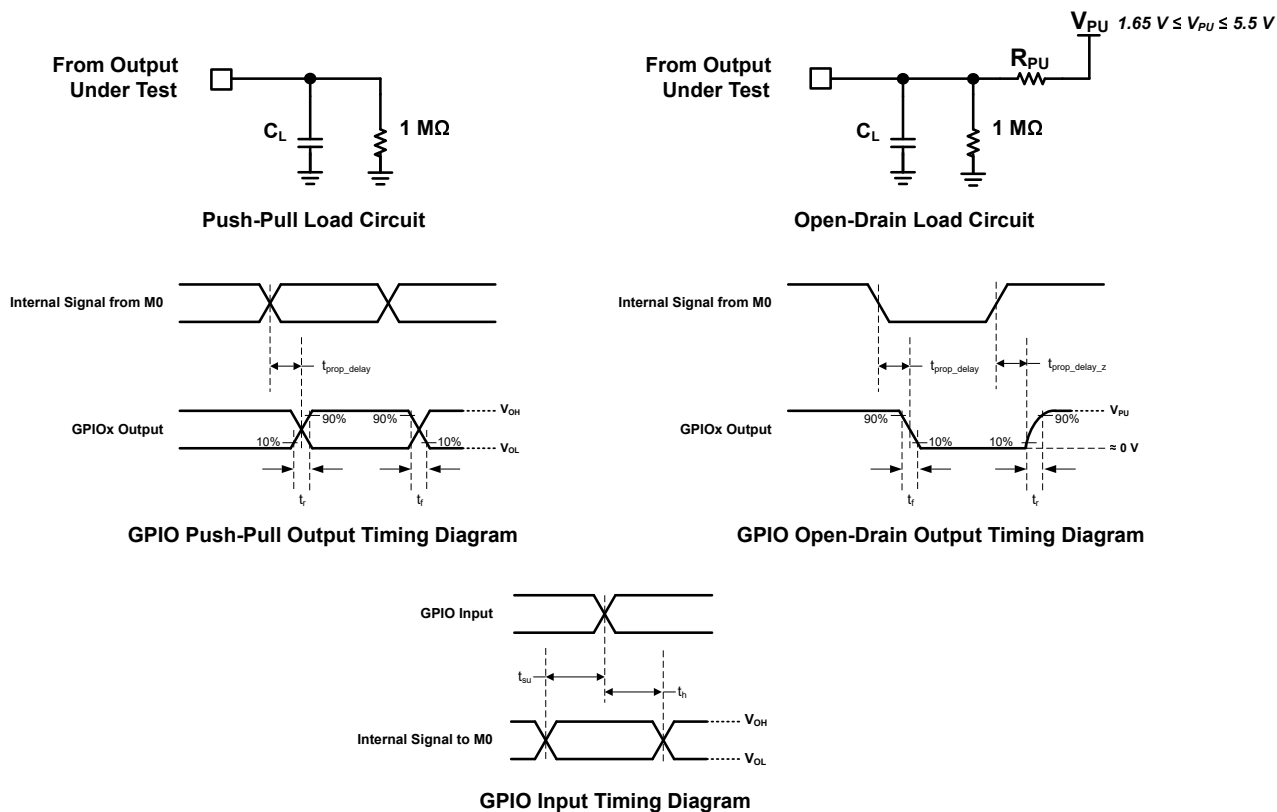


Figure 7-48. GPIO: Input Voltage Thresholds vs Temperature

## 8 Parameter Measurement Information



8-1. I²C Slave Interface Timing



8-2. GPIO Output Timing Diagram (rise/fall vs capacitive load)

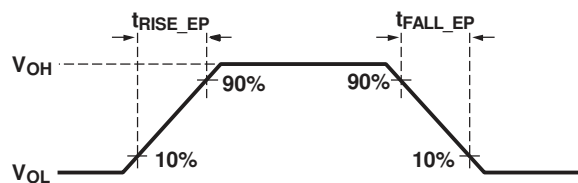


図 8-3. USB Endpoint Transmitter Rise and Fall Time

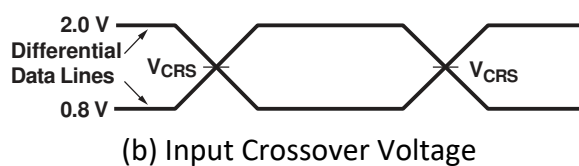
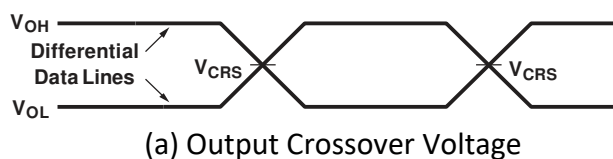


図 8-4. USB Endpoint Crossover Voltages

## 9 Detailed Description

### 9.1 Overview

The TPS25772-Q1 is a fully-integrated AEC-Q100 USB Power Delivery (USB-PD) source intended for use in 12-V automotive battery systems. Input supply pin,  $V_{IN}$ , must be connected to a load dump clamped battery supply,  $V_{BAT}$ , and never exceed 40 V (ABS MAX).

The device consists of seven sub-blocks: USB-PD controller; Type-C cable plug and orientation detection circuitry; USB Endpoint; USB Battery Charging Specification Version 1.2 (BC1.2) detection circuitry; digital core; device power management and supervisory circuitry; and a buck-boost converter integrated with 4 power switches.

The USB-PD controller provides the physical layer (PHY) functionality of the USB-PD protocol. The USB-PD data is output through either the Px\_CC1 pin or the Px\_CC2 pin, depending on the orientation of the reversible USB Type-C cable. For a high-level block diagram of the USB-PD physical layer, a description of its features and more detailed circuitry, see [USB-PD Physical Layer](#).

The cable plug and orientation detection analog circuitry automatically detects a USB Type-C cable plug insertion and also automatically detects the cable orientation. For a high-level block diagram of cable plug and orientation detection, a description of its features and more detailed circuitry, see [Cable Plug and Orientation Detection](#).

A USB Endpoint is included for downloading configuration information and firmware updates. When enabled by firmware, the USB Endpoint connects to the Port A DP and DM pins.

The USB BC1.2 sub-block contains circuitry to support legacy USB charging methods which signal on the USB DP and DM data lines including: DCP, Divider-3, 1.2 V mode, and HVDCP. See [BC 1.2, legacy and fast charging modes \(Px\\_DP, Px\\_DM\)](#).

The power management and supervisory circuitry generates the LDO\_5V, LDO\_3V3, and LDO\_1V5 voltage rails used by the device. LDO\_5V supplies the LDO\_3V3 and LDO\_1V5 rails. For a high-level block diagram of the power management circuitry, a description of its features and more detailed operation, see [Internal LDO Regulators](#) section.

The digital core contains an ARM Cortex-M0 with 160-kB ROM and 27-kB RAM memory. The ROM contains firmware code to execute device functionality. RAM stores application configuration code created using the Graphical User Interface (GUI) and post-manufacturing firmware updates. The digital core is the engine for autonomously managing the system including: USB port connection status and communication; system power budget and allocation; system thermal monitoring and load shedding; and fault detection and reporting. All devices contain one controller I<sup>2</sup>C port (I<sup>2</sup>C1) for controlling external peripherals such as external EEPROM memory; DC/DC converters; USB data multiplexers/redrivers; GPIO expanders; and additional temperature sensors. Some devices include an I<sup>2</sup>C target port (I<sup>2</sup>C2) for connection to an external processor, HUB or embedded controller. An integrated 8-bit analog-to-digital converter ADC (see the [ADC](#) section), monitors USB port telemetry information. USB port connection status, voltage, current and fault information can be read from I<sup>2</sup>C2 target port. For a high-level block diagram of the digital core and a description of its features, see the [Digital Core](#) section.

The integrated buck-boost converter is the PA\_VBUS power source. It operates in buck mode when  $V_{IN}$  is greater than  $V_{OUT}$  and boost mode when  $V_{IN}$  is less than  $V_{OUT}$ . When  $V_{IN}$  and  $V_{OUT}$  are nearly the same, it operates in transition mode.

### Dual Port Devices

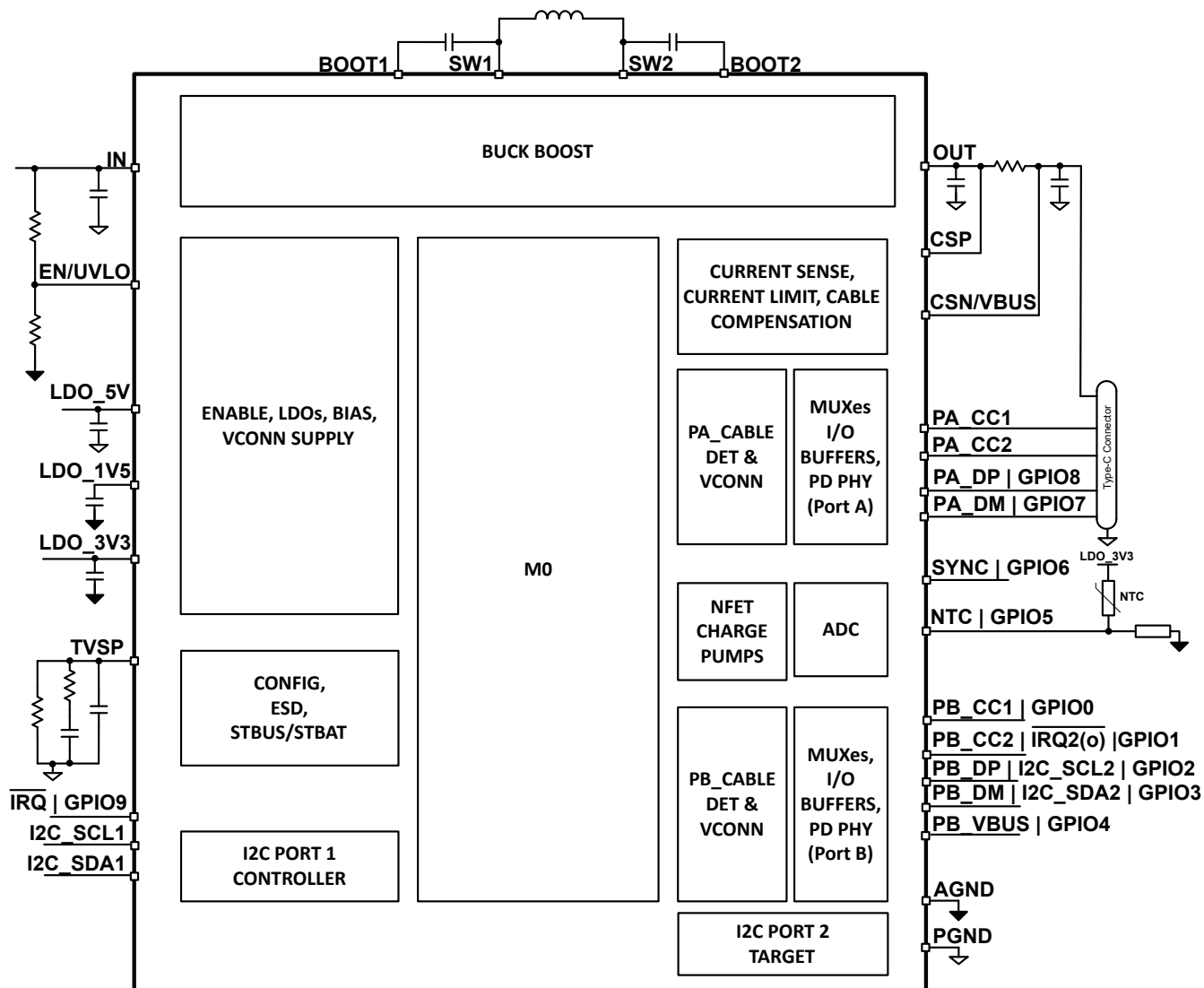
TPS25772-Q1 is a dual USB port device. Refer to [Device Comparison Table](#) for functional differences. The TPS25772-Q1 consists of a single 3 to 21 V output internal buck-boost converter, two USB-PD port controllers providing cable plug and orientation detection, two internal VCONN source paths, legacy USB Battery Charging Specification v1.2 Dedicated Charging Port (DCP) as well as legacy (non-USB compliant) charger detection including: Divider-3, 1.2 V, and HVDCP modes on each port.

PB\_VBUS for TPS25772-Q1 must be supplied from an external power source. The implementation of this power is shown in 表 9-1.

表 9-1. Supported Dual USB Port Implementations

| Port A (PA)                        | Port B (PB)                                    | Port B (PB) Suggested Power Devices |
|------------------------------------|------------------------------------------------|-------------------------------------|
| USB Power Delivery (including PPS) | Type-C with USB Power Delivery (including PPS) | TPS55288-Q1                         |

## 9.2 Functional Block Diagram



## 9.3 Feature Description

### 9.3.1 Device Power Management and Supervisory Circuitry

#### 9.3.1.1 VIN UVLO and Enable/UVLO

The TPS25772-Q1 has one internally fixed  $V_{IN}$  UVLO and one user programmable UVLO using the EN/UVLO pin. Both thresholds must be cleared for the device to start up.

- The fixed  $V_{IN(UVLO)}$  has a rising threshold between 5 and 5.5 V to ensure internal circuits have sufficient headroom for proper operation.

- The EN/UVLO pin provides the user with a resistor programmable UVLO threshold and master enable / disable for the device.

The EN/UVLO pin has three distinct voltage ranges: shutdown, standby, and operating. When the EN/UVLO pin is below the standby threshold  $V_{EN(STBY)}$ , the device is disabled in a low power shutdown. When EN/UVLO voltage is greater than the standby threshold  $V_{EN(STBY)}$  but less than the operating threshold  $V_{EN(OPER)}$ , the internal bias rails, LDO\_5V, LDO\_3V3, and LDO\_1V5 regulators are enabled but remaining device functions are disabled. When EN/UVLO is greater than the operating threshold  $V_{EN(OPER)}$  and LDO\_5V, LDO\_3V3 and LDO\_1V5 regulators are above their respective undervoltage threshold UVLO thresholds, the device is fully functional. The EN/UVLO pin includes fixed hysteresis between the shutdown mode and the standby mode.

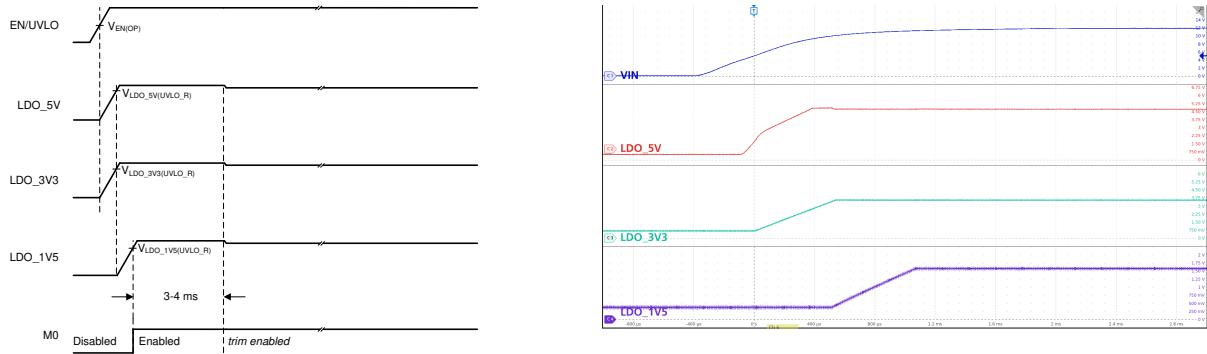


図 9-1. EN/UVLO and LDO Sequencing

表 9-2. EN/UVLO and LDO\_UVLO Operation

| EN/UVLO <sup>(1)</sup>                            | LDOs                                                                                                                  | DEVICE OPERATION                                            |
|---------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------|
| $V_{EN/UVLO} < V_{EN(LDO\_V5\_F)}$                | —                                                                                                                     | Shutdown: LDO_5V, LDO_3V3 and LDO_1V5 OFF. M0 (MCU) is OFF. |
| $V_{EN(LDO\_V5\_R)} < V_{EN/UVLO} < V_{EN(STBY)}$ | —                                                                                                                     | Standby: LDO_5V, LDO_3V3 and LDO_1V5 ON. M0 (MCU) is OFF.   |
| $V_{EN/UVLO} > V_{EN(OPER)}$                      | LDO_5V < $V_{LDO\_5V(UVLO\_R)}$ , or<br>LDO_3V3 < $V_{LDO\_3V3(UVLO\_R)}$ ; or<br>LDO_1V5 < $V_{LDO\_1V5(UVLO\_R)}$   | LDO_5V, LDO_3V3 and LDO_1V5 ON, M0 (MCU) is OFF.            |
| $V_{EN/UVLO} > V_{EN(OPER)}$                      | LDO_5V > $V_{LDO\_5V(UVLO\_R)}$ , and<br>LDO_3V3 > $V_{LDO\_3V3(UVLO\_R)}$ , and<br>LDO_1V5 > $V_{LDO\_1V5(UVLO\_R)}$ | Operating: M0 (MCU) is ON.                                  |

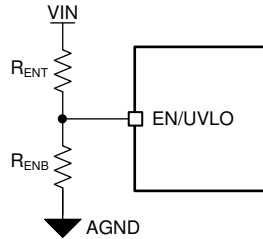
(1) Valid when  $V_{IN} > V_{IN(UVLO\_R)}$ .

In some cases an input UVLO level different than that provided by the internal  $V_{IN(UVLO)}$  is needed. This can be accomplished by using the circuit shown in [UVLO Threshold Programming](#). The input voltage at which the device turns on is designated  $V_{ON}$ ; while the turnoff voltage is  $V_{OFF}$ . First a value for  $R_{ENB}$  is chosen in the range of 13 kΩ to 22 kΩ. Use 式 1 and 式 2 to calculate  $R_{ENT}$  and  $V_{OFF}$ .

$$R_{ENT} = \left( \frac{V_{ON}}{V_{EN(OPER)}} - 1 \right) \times R_{ENB} \quad (1)$$

The hysteresis between the UVLO turn-on threshold and turn-off threshold is set by the upper resistor in the EN/UVLO resistor divider and is given by:

$$V_{OFF} = \left( 1 - \frac{V_{EN(HYS)}}{V_{EN(OPER)}} \right) \times V_{ON} \quad (2)$$



**9-2. UVLO Threshold Programming**

Where

- $V_{ON} = V_{IN}$  turn-on voltage
- $V_{OFF} = V_{IN}$  turn-off voltage

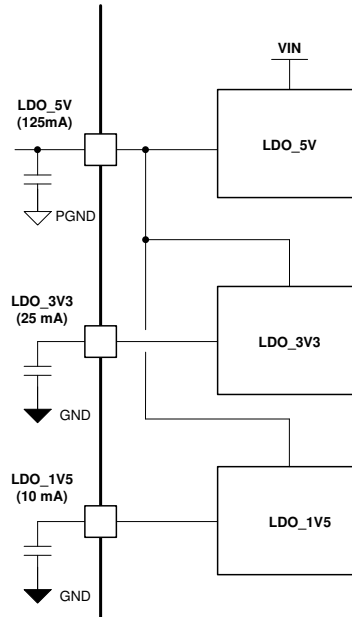
**Note:** Ensure  $R_{ENT} \geq 47 \text{ k}\Omega$

If the programmable UVLO is not required, the EN/UVLO pin can be connected to the IN pin with a 47 k $\Omega$ , or larger, resistor.

### 9.3.1.2 Internal LDO Regulators

Three internal LDOs provide regulated supplies for operation of internal circuitry.

- **LDO\_5V:** Supplies buck-boost gate drive circuitry, LDO\_3V3, LDO\_1V5, and PA and PB VCONN power paths. External bypass capacitance,  $C_{LDO\_5V}$  is required for proper operation. It is highly recommended to include an additional high frequency 0.1  $\mu\text{F}$  capacitor in parallel with  $C_{LDO\_5V}$ .  $C_{LDO\_5V}$  and the parallel high frequency should be placed as close to the LDO\_5V pin as possible. This capacitance: 1) provides energy storage for the buck-boost internal FET gate drivers, and 2) is required to stabilize the internal 5-V LDO in applications where an external 5-V supply is not connected. The TPS25772-Q1 will not operate (release reset) until  $V_{LDO\_5V(UVLO\_R)}$  threshold is met. Hard reset occurs when  $V_{LDO\_5V} < V_{LDO\_5V(UVLO\_F)}$  threshold. Current from LDO\_5V returns to PGND pin. The LDO\_5V output may be used to supply a small external loads such as indicator LEDs. When supplying external components, it is recommended that the total external load current not exceed 25 mA (MAX).
  - 0.1W VCONN: when enabled in the application configuration GUI, LDO\_5V is capable of sourcing 20 mA each to PA\_VCONN and PB\_VCONN.
  - 1W VCONN: when enabled in the application configuration GUI, this mode of operation *requires* an external 4.75 - 5.5 V, 500-mA capable supply connected to LDO\_5V. Back-feeding of LDO\_5V is allowed.
- **LDO\_3V3:** Supplies internal analog circuits, GPIO buffers, USB PD and the USB Endpoint PHYs. External bypass capacitance of  $C_{LDO\_3V3}$  is required for proper operation. An additional 0.1  $\mu\text{F}$  capacitor in parallel with  $C_{LDO\_3V3}$  is highly recommended to filter high frequency noise from the I/O buffers and PHYs. The LDO\_3V3 can supply external circuits at up to 25 mA. Expected loads include: EEPROM (5mA), NTC resistor divider network (< 1 mA). Current may be drawn up to  $I_{LDO\_3V3(ILIMIT)}$ . Note: the USB PD and Endpoint PHYs draw current from LDO\_3V3. If a CCx or Dx pin is shorted to GND during a transmission the current drawn may reach the current limit threshold. Similarly, if any GPIO pins are configured as push-pull outputs and a GPIO short to GND event occurs, the LDO\_3V3 current limit may be reached. Current returns to AGND pin.
- **LDO\_1V5:** Supplies digital core. External bypass capacitance of  $C_{LDO\_1V5}$  is required for proper operation. An additional 0.1  $\mu\text{F}$  capacitor in parallel with  $C_{LDO\_1V5}$  is highly recommended to filter noise generated by the digital core. The M0 is held in reset until all three UVLO\_R (rising) thresholds are met. Current returns to AGND pin.



Note: LDO\_5V max regulation current includes LDO\_3V3 (25 mA) and LDO\_1V5 (10 mA)

図 9-3. Internal LDO Connection Diagram

### 9.3.2 TVSP Device Configuration and ESD Protection

The Transient Voltage protection and firmware **Setting Pin (TVSP)** has three functions: 1) Boot configuration settings; 2) USB connector pin short to  $V_{BUS}$  or  $V_{BAT}$  protection; and 3) USB connector pin enhanced ESD protection.

- **$R_{TVSP}$ :** At power on, the resistance between the TVSP pin and PGND determines the boot method, USB PD port I<sup>2</sup>C addresses and I<sup>2</sup>C logic thresholds. Refer to 表 9-4 and 表 9-5. The most common configuration is shown in 図 9-4 with  $R_{TVSP}$  open, corresponding to TVSP Index 0. During device initialization and boot, typically within 4 seconds after power on,  $V_{IN}$  must be above 7.6 V to ensure proper bias of the TVSP pin to 5.5 V. Once boot is complete the device can operate over the full  $V_{IN}$  range.
- **$C_{TVSP}$ :** A 0.1- $\mu$ F capacitor ( $C_{TVSP}$ ) *must* be connected to PGND. Place  $C_{TVSP}$  as close to the TVSP pin as possible to minimize parasitic inductance.  $C_{TVSP}$  is part of the centralized protection circuitry fortifying connector pins Px\_CCy, Px\_DP and Px\_DM from damage during short to  $V_{BUS}$ ,  $V_{BAT}$  and ESD events. A 40-V 0.1- $\mu$ F capacitor is recommended for proper operation of the internal TVSP regulator circuit.
- **TVSP Damper Network:** Capacitance,  $C_{DAMP}$ , and resistance,  $R_{DAMP}$ , form an RC network preventing excessive current from flowing inside the device during connector pin over-voltage and ESD events.
  - **$C_{DAMP}$ :** A 0.47- $\mu$ F capacitor *must* be connected in series with  $R_{DAMP}$  to PGND. A 40-V 0.47- $\mu$ F capacitor is recommended.
  - **$R_{DAMP}$ :** A 10- $\Omega$  resistor *must* be connected in series with  $C_{DAMP}$  to PGND. A 0.25-W rating is recommended.

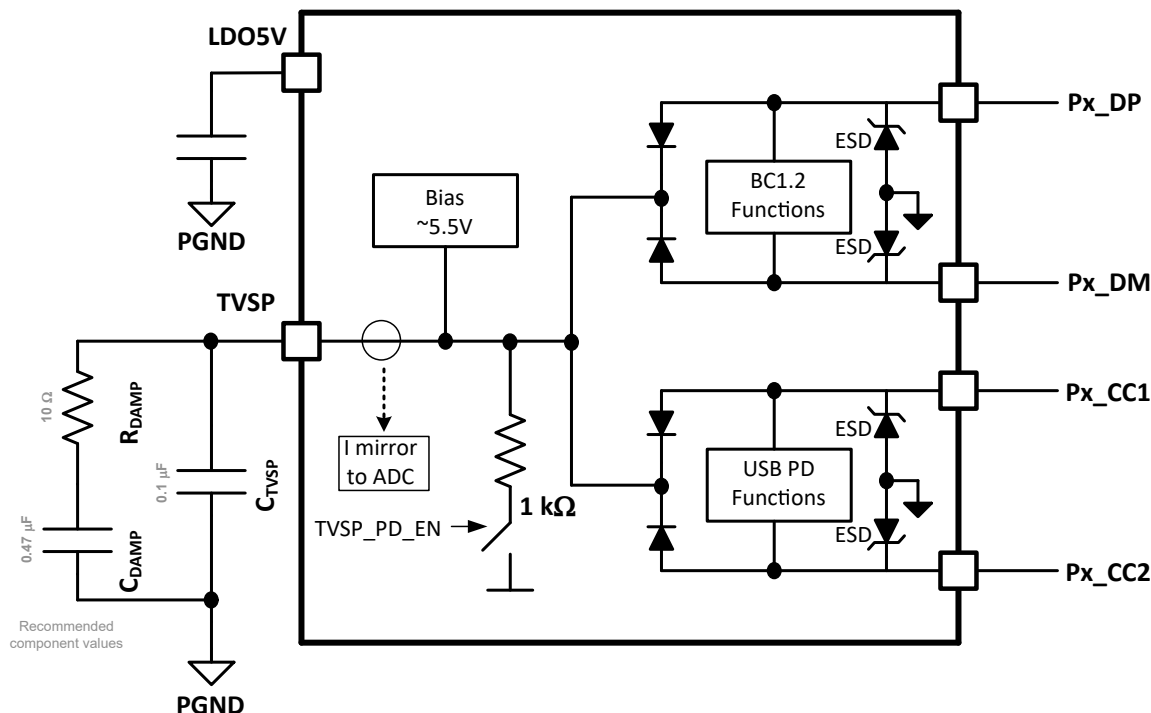


図 9-4. Basic TVSP Pin Connection

表 9-3. Recommended TVSP Components

| C <sub>TVSP</sub> | R <sub>DAMP</sub> | C <sub>DAMP</sub> |
|-------------------|-------------------|-------------------|
| 0.1 μF            | 10 Ω              | 0.47 μF           |

表 9-4. R<sub>TVSP</sub> Configuration Settings (TPS25762CQRQLRQ1 and TPS25772CQRQLRQ1)

| R <sub>TVSP</sub> (kΩ) <sup>(1)</sup> | TVSP Index | ADC Value    | I2C Target Port Addresses (A   B) <sup>(2)</sup> | I2C Logic (V <sub>DD</sub> ) | Boot Mode        |
|---------------------------------------|------------|--------------|--------------------------------------------------|------------------------------|------------------|
| Open                                  | 0          | ≤ 10 (0x0A)  | 0x22   0x26                                      | 3.3 V                        | EEPROM           |
| 93.1                                  | 1          | ≤ 24 (0x18)  | 0x23   0x27                                      | 3.3 V                        | External HUB/MCU |
| 47.5                                  | 2          | ≤ 42 (0x2A)  | 0x22   0x26                                      | 1.8 V                        | EEPROM           |
| 29.4                                  | 3          | ≤ 63 (0x3F)  | 0x23   0x27                                      | 1.8 V                        | External HUB/MCU |
| 20.0                                  | 4          | ≤ 89 (0x59)  | 0x23   0x27                                      | 3.3 V                        | EEPROM           |
| 14.7                                  | 5          | ≤ 119 (0x77) | 0x22   0x26                                      | 3.3 V                        | External HUB/MCU |
| 11.0                                  | 6          | ≤ 156 (0x9C) | 0x23   0x27                                      | 1.8 V                        | EEPROM           |
| 8.45                                  | 7          | ≤ 201 (0xC9) | 0x22   0x26                                      | 1.8 V                        | External HUB/MCU |
| 6.65                                  | 8          | ≤ 255 (0xFF) | 0x22   0x26                                      | 3.3 V                        | Firmware Update  |

表 9-5. RTVSP Configuration Settings (TPS25762CAQRQLRQ1 and TPS25772CAQRQLRQ1)

| R <sub>TVSP</sub> (kΩ) <sup>(1)</sup> | TVSP Index | ADC Value    | I2C Target Port Addresses (A   B) <sup>(2)</sup> | I2C Logic (V <sub>DD</sub> ) | Boot Mode       |
|---------------------------------------|------------|--------------|--------------------------------------------------|------------------------------|-----------------|
| Open                                  | 0          | ≤ 201 (0x0A) | 0x22   0x26                                      | 3.3 V                        | EEPROM          |
| 5.6                                   | 8          | ≤ 255 (0xFF) | 0x22   0x26                                      | 3.3 V                        | Firmware Update |

(1) 1% resistor required.

(2) 0x22h = 0100010; 0x26h = 0100110; 0x23h = 0100011; 0x27 = 0100111

Applications requiring a configuration other than standard, TVSP Index 0 (R<sub>TVSP</sub> open), as shown in 表 9-4 must implement a circuit similar to the one shown in 図 9-5. The base of the bipolar transistor is connected to LDO\_5V to provide proper power up sequencing of the TVSP resistor - OFF when TPS25772-Q1 is disabled and ON

when TPS25772-Q1 is enabled. A 2N2222 is recommended for its large collector-emitter breakdown voltage, low-cost and wide availability.

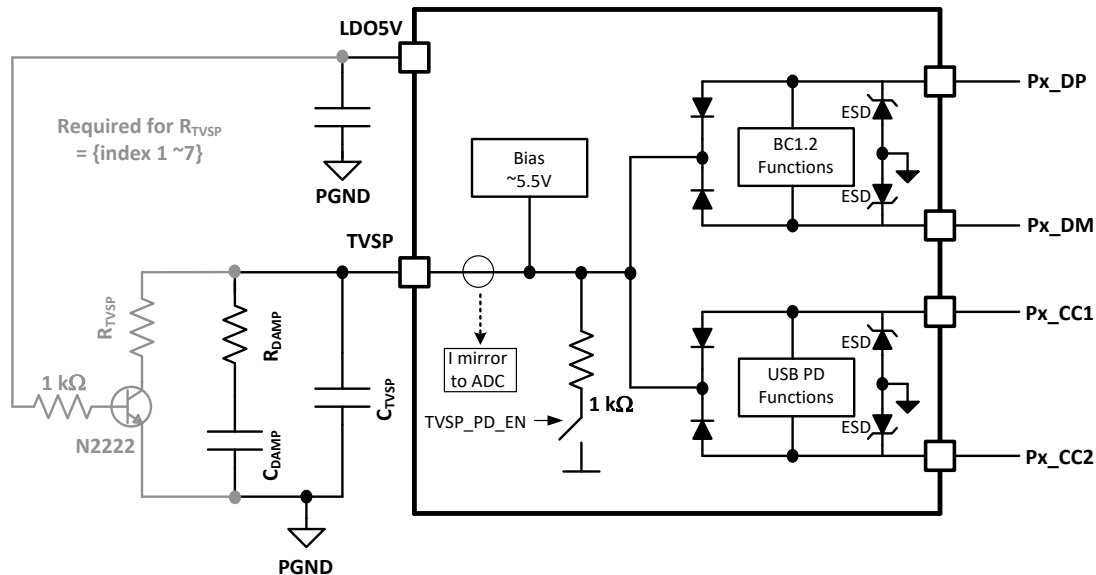


図 9-5.  $R_{TVSP}$  Circuit Configuration

Device firmware can be updated using the USB Endpoint on the PA\_DP and PA\_DM pins. To enable firmware update mode, boot the device with a resistance corresponding to Index 8 between TVSPS and PGND. A boot cycle can be performed by power cycling the device or by pulling the EN/UVLO pin momentarily below  $V_{EN(OPER)}$  threshold. An example circuit to enable USB Endpoint firmware update mode is shown in 図 9-6

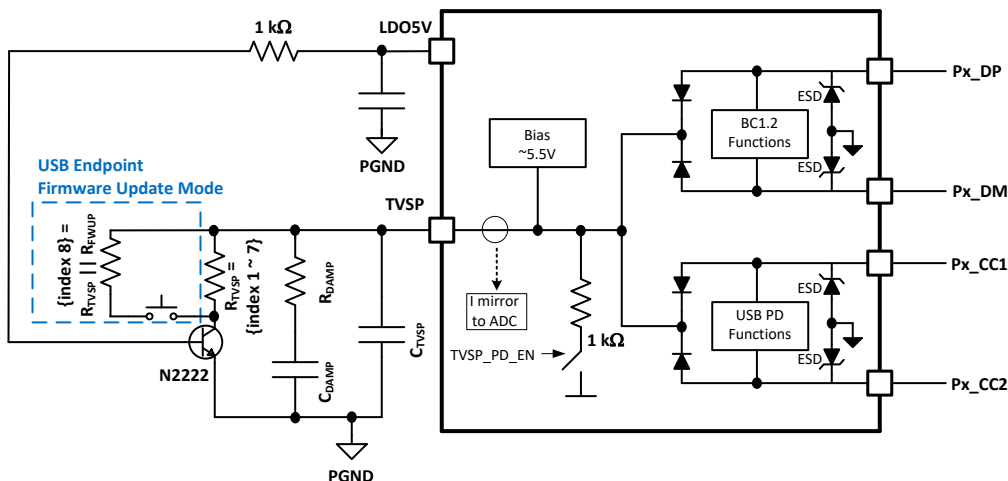


図 9-6. Example Circuit to Enable USB Endpoint Firmware Update Mode

### 9.3.3 Buck-Boost Regulator

#### 9.3.3.1 Buck-Boost Regulator Operation

The TPS25772-Q1 devices utilize a fixed frequency, current mode control buck-boost converter. This converter operates in forced continuous conduction mode (CCM) and therefore allows inductor current to flow in either direction at light loads. The power train consists of five N-Channel power MOSFETs. See 図 9-7. Transistors M1 and M2 are the high-side and low-side buck FETs. Transistors M3 and M4 are the high-side and low-side boost

FETs. Transistor M5 blocks reverse conduction from OUT to SW2 during input overvoltage transients as explained in [VIN Supply and VIN Over-Voltage Protection](#).

- **IN:** Receives power from the battery. The input bulk capacitor must be connected between IN and PGND.
- **OUT:** Delivers power from the switching converter. The output bulk capacitor connects between OUT to PGND.
- **PGND:** Ground return for the switching converter power train.
- **AGND:** Ground return for everything except the power train. The voltage feedback divider returns to AGND. PGND and AGND must connect together on the circuit board.
- **LDO\_5V:** Provides gate drive for M2 and M4 and current for the bootstrap circuits feeding BOOT1 and BOOT2. A bypass capacitor must connect from LDO\_5V to PGND. See [Internal LDO Regulators](#) for more information on LDO\_5V.
- **LDO\_3V3:** Analog circuitry power supply. A bypass capacitor must connect from LDO\_3V3 to AGND. See [Internal LDO Regulators](#) for more information on LDO\_3V3.
- **BOOT1:** Provides gate drive for M1. A bootstrap capacitor must connect from BOOT1 to SW1.
- **BOOT2:** Provides gate drive for M3. A bootstrap capacitor must connect from BOOT2 to SW2.
- **SW1:** Connects M1 and M2 to external inductor.
- **SW2:** Connects M3 and M4 to external inductor.
- **CSP:** Positive terminal of average current sense amplifier. Connects to positive terminal of output bulk capacitor.
- **CSN/BUS:** Negative terminal of average current sense amplifier. A 10-mΩ current sense resistor is externally connected from CSP to CSN/BUS.

Depending upon the input voltage  $V_{IN}$  and the output voltage  $V_{OUT}$ , the converter can operate in one of four different states, each of which is described in following sections.

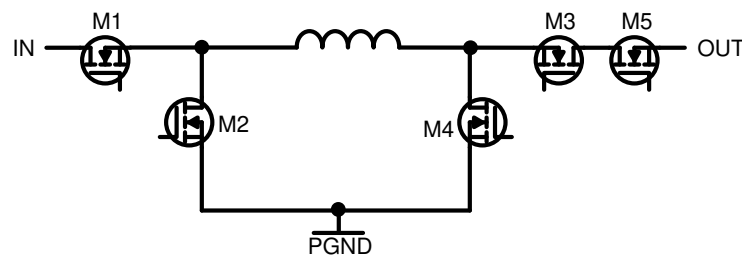


图 9-7. Buck-Boost Internal Power FETs

### Buck State

When the input voltage  $V_{IN}$  significantly exceeds the output voltage  $V_{OUT}$ , the converter enters the buck region of operation in which it performs an endless series of buck switching cycles [Buck State](#). M3 and M5 are constantly on and M4 is constantly off. When the clock signals that a switching cycle has begun, the controller turns on M2 and turns off M1. This switch configuration corresponds to the off-time interval of a traditional buck converter. The voltage difference  $V_{SW1} - V_{SW2}$  across the inductor equals  $-V_{OUT}$ . The inductor current  $I_L$  ramps down until it reaches a threshold  $I_{VALLEY}$  set by the error amplifiers. The controller then turns off M2 and turns on M1. This switch configuration corresponds to the on-time interval of a traditional buck converter. The voltage difference  $V_{SW1} - V_{SW2}$  now equals  $V_{IN} - V_{OUT}$ . The inductor current now ramps up until the converter clock signals that the end of the switching cycle has been reached.

The on-time  $t_{on}$  equals the time interval during which M1 conducts. The off-time  $t_{off}$  equals the time interval during which M2 conducts. Because the converter operates in FCCM, the period  $\tau$  equals the sum of  $t_{on}$  and  $t_{off}$ . During the buck state, the controller regulates power flow by adjusting the buck duty cycle  $D$ , which equals the ratio  $t_{on}/\tau$ .

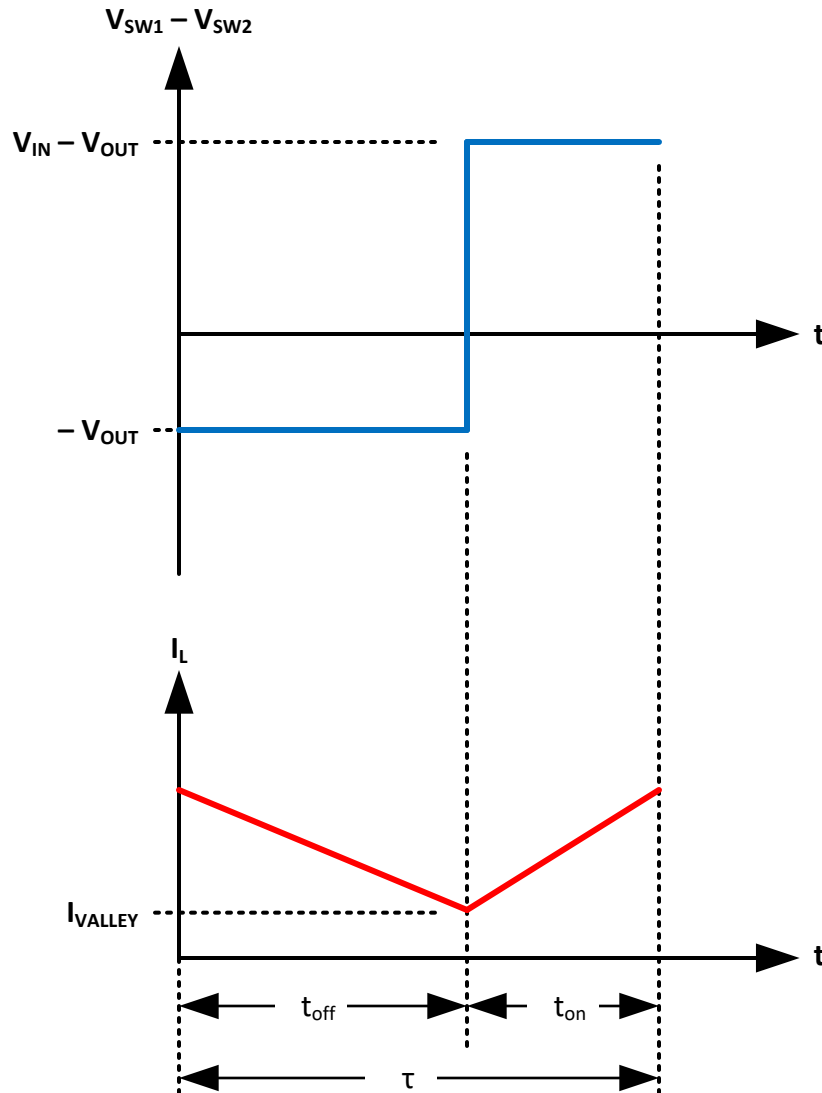


図 9-8. Buck State

### Buck Transition State

When the input voltage  $V_{IN}$  is only slightly larger than the output voltage  $V_{OUT}$ , the converter enters the buck transition region of operation in which it alternately performs buck and boost switching cycles [Buck Transition](#). M5 is always on. When the clock signals that a buck switching cycle has begun, the controller turns on M2 and M3, and it turns off M1 and M4. This switch configuration corresponds to the off-time of a traditional buck converter. The inductor current  $I_L$  ramps down until it reaches a threshold  $I_{VALLEY}$  set by the error amplifiers. The controller then turns off M2 and turns on M1. This switch configuration corresponds to the on-time of a traditional buck converter. The inductor current now ramps up slowly until the clock signals the end of the buck switching cycle. The next switching cycle is a boost switching cycle. When this cycle begins, the controller turns M3 off and turns M4 on. M2 remains off, and both M1 and M5 remain on. This switch configuration corresponds to the on-time of a traditional boost converter. The inductor current  $I_L$  now ramps up rapidly until the fixed on-time expires. The controller then turns off M4 and turns on M3. The inductor current now ramps down until the clock signals the end of the boost switching cycle. The next switching cycle will be another buck cycle.

During the buck transition state, the controller regulates power flow by adjusting the buck duty cycle. The boost duty cycle remains fixed. If the converter had remained in the buck state rather than move to the buck transition

state, the buck on-time would have become so short that it would have become impossible to regulate power flow without pulse skipping.

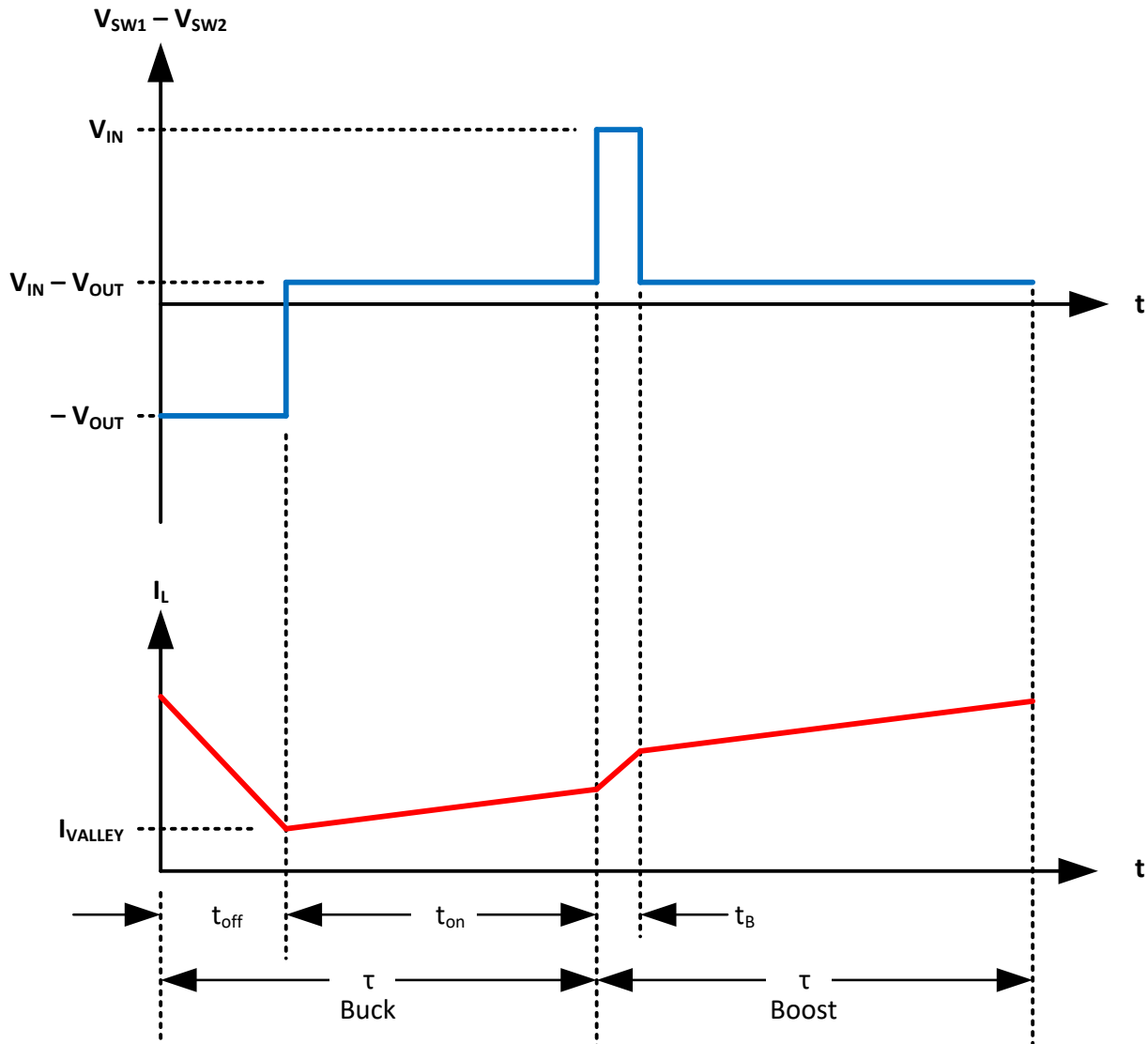


图 9-9. Buck Transition

### Boost Transition State

When the input voltage  $V_{IN}$  is only slightly smaller than the output voltage  $V_{OUT}$ , the converter enters the boost transition region of operation in which it alternately performs boost and buck switching cycles [Boost Transition](#). M5 is always on. When the clock signals that a boost switching cycle has begun, the controller turns on M1 and M4, and it turns off M2 and M3. This switch configuration corresponds to the on-time of a traditional boost converter. The inductor current  $I_L$  ramps up until it reaches a threshold  $I_{PEAK}$  set by the error amplifiers. The controller then turns off M4 and turns on M3. This switch configuration corresponds to the off-time of a traditional boost converter. The inductor current now ramps down slowly until the clock signals the end of the boost switching cycle. The next switching cycle is a buck switching cycle. When this cycle begins, the controller turns M1 off and turns M2 on. M4 remains off, and both M3 and M5 remain on. This switch configuration corresponds to the off-time of a traditional buck converter. The inductor current  $I_L$  now ramps down rapidly until the fixed off-

time expires. The controller then turns off M2 and turns on M1. The inductor current now ramps up until the clock signals the end of the buck switching cycle. The next switching cycle will be another boost cycle.

During the boost transition state, the controller regulates power flow by adjusting the boost duty cycle. The buck duty cycle remains fixed. If the converter had remained in the boost state rather than move to the boost transition state, the boost on-time would have become so short that it would have become impossible to regulate power flow without pulse skipping.

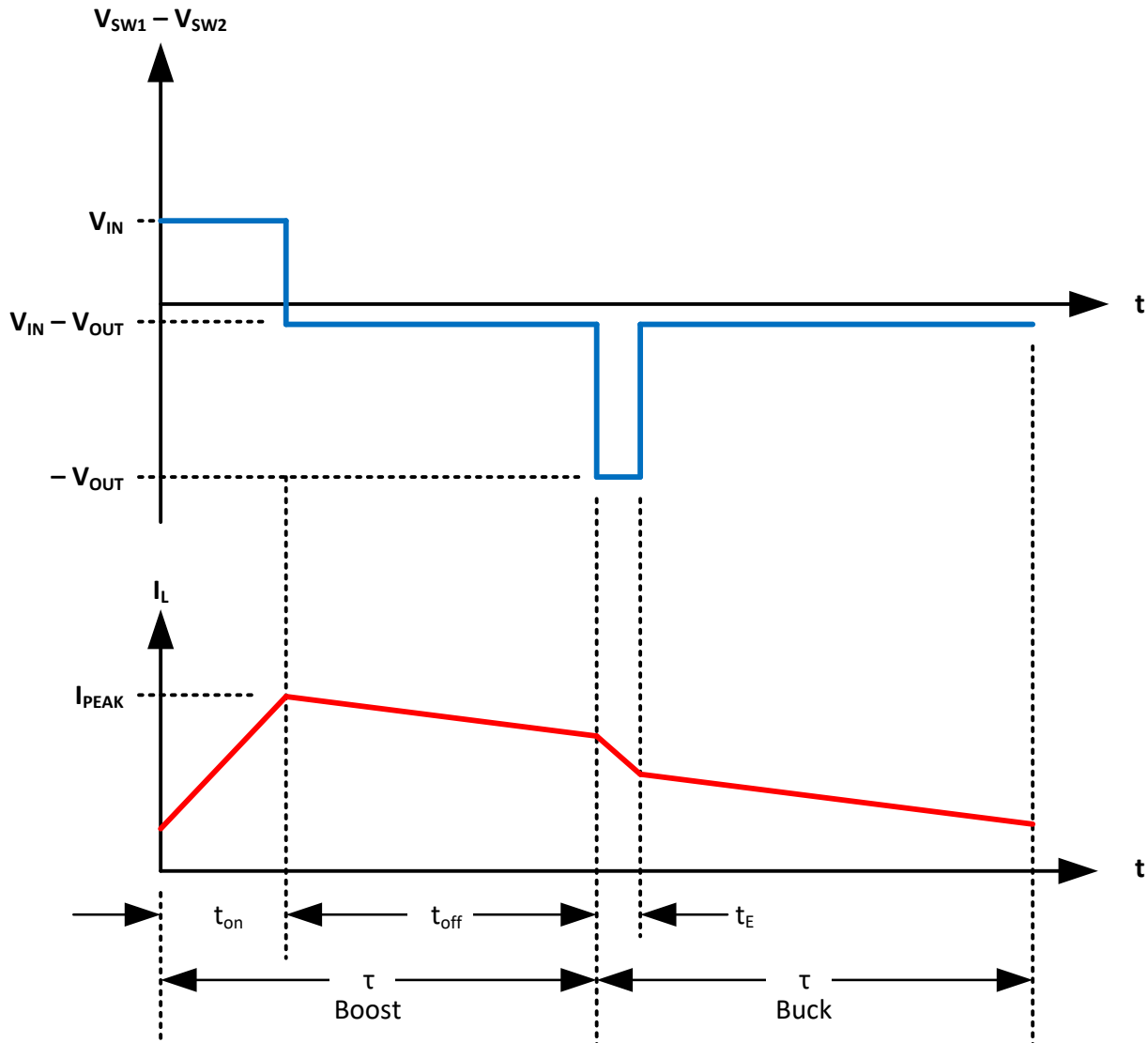


図 9-10. Boost Transition

### Boost State

When the input voltage  $V_{IN}$  is significantly less than the output voltage  $V_{OUT}$ , the converter enters the boost region of operation in which it performs an endless series of boost switching cycles **Boost State**. M1 and M5 are constantly on and M2 is constantly off. When the clock signals that a switching cycle has begun, the controller turns on M4 and turns off M3. This switch configuration corresponds to the on-time interval of a traditional boost converter. The voltage difference  $V_{SW1} - V_{SW2}$  across the inductor equals  $V_{IN}$ . The inductor current  $I_L$  ramps up until it reaches a threshold  $I_{PEAK}$  set by the error amplifiers. The controller then turns off M4 and turns on M3. This switch configuration corresponds to the off-time interval of a traditional boost converter. The voltage

difference  $V_{SW1} - V_{SW2}$  now equals  $V_{IN} - V_{OUT}$ , which is negative. The inductor current now ramps down until the converter clock signals that the end of the switching cycle has been reached.

The on-time  $t_{on}$  equals the time interval during which M4 conducts. The off-time  $t_{off}$  equals the time interval during which M3 conducts. Because the converter operates in FCCM, the period  $\tau$  equals the sum of  $t_{on}$  and  $t_{off}$ . During the boost state, the controller regulates power flow by adjusting the boost duty cycle  $D$ , which equals the ratio  $t_{on}/\tau$ .

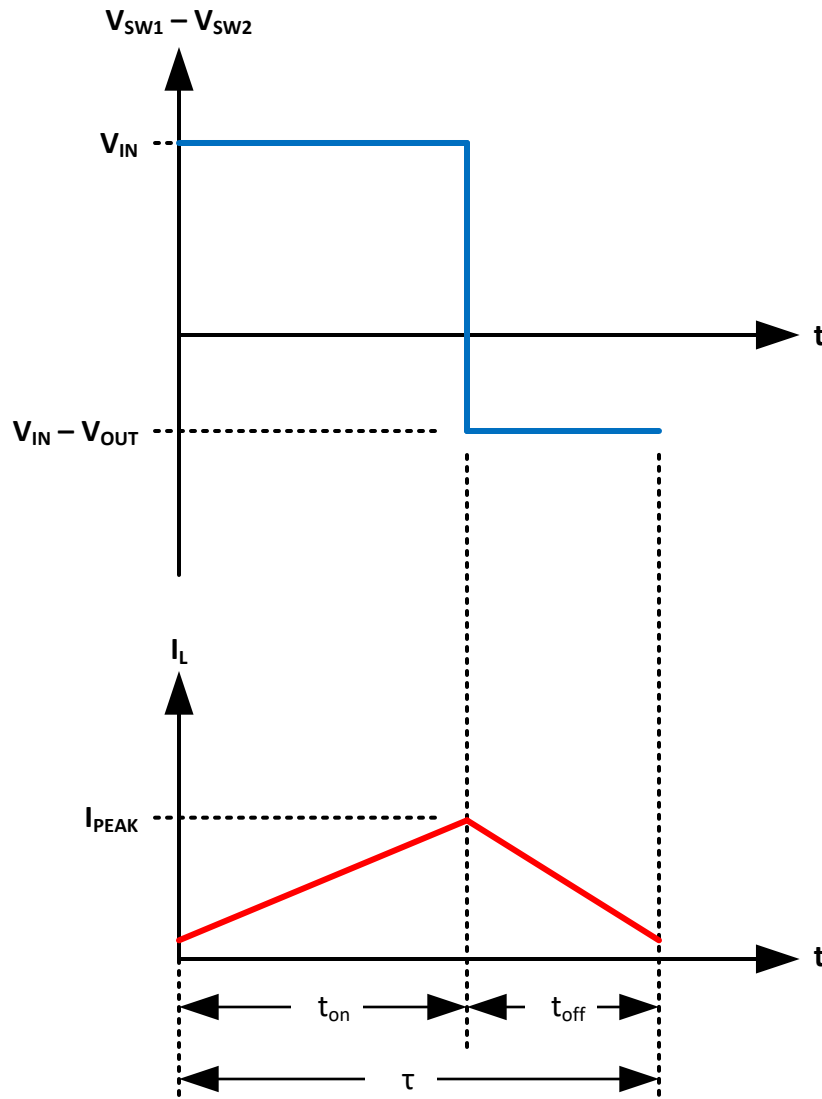


図 9-11. Boost State

### Boundaries of the Regions of Operation

**Regions of Operation** graphically depicts the four regions of operation and the boundaries between them. When  $V_{BUS} > kV_{IN}$ , the converter remains in the boost region of operation. The value  $k$  is 1.2. When  $V_{IN} < V_{BUS} < kV_{IN}$ , the converter enters the boost transition region of operation. When  $V_{IN}/k < V_{BUS} < V_{IN}$ , the converter enters the buck transition region of operation. When  $V_{BUS} < V_{IN}/k$ , the converter enters the buck region of operation. The converter will cease operating if  $V_{IN}$  exceeds the OVP threshold, which lies between 18 and 20 V. Similarly, the converter will also cease operating if  $V_{IN}$  drops below either the internal UVLO threshold, which lies between 5

and 5.5 V, or the user programmed EN/UVLO threshold (see [VIN UVLO and ENABLE/UVLO](#), whichever is greater).

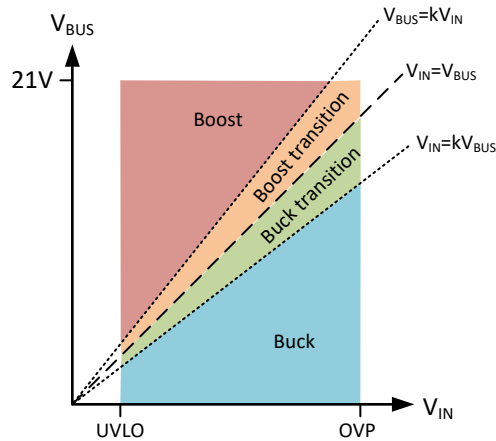


Figure 9-12. Regions of Operation

### 9.3.3.2 Switching Frequency, Frequency Dither, Phase-Shift and Synchronization

The PWM oscillator frequency ( $f_{sw}$ ) is programmed by firmware using the application configuration GUI. The switching converter is intended for operation below the AM radio band (520 kHz - 1730 kHz). Three nominal  $f_{sw}$  settings below are available: 300 kHz, 400 kHz and 450 kHz.

Frequency dithering can be enabled by firmware via the application GUI. When enabled, the nominal oscillator frequency is dithered by  $\pm FS_{SS}$  (approximately  $\pm 10\%$ ) using triangular waveform modulation (see [Dithering using triangular waveform modulation](#)). The dither period  $\tau_M$  is the reciprocal of the dither modulation frequency  $FS_{SS\_MOD}$ . Two firmware selectable dither modulation frequencies  $FS_{SS\_M}$  are available: 10 and 25 kHz. Dithering spreads the spectral peaks generated by switching, thereby reducing the peak harmonic levels and easing EMI filter design.

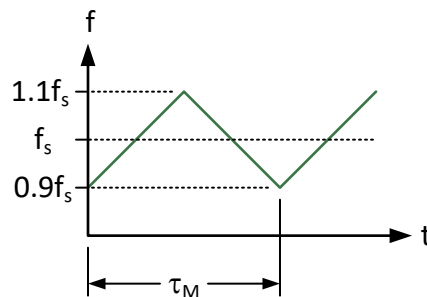


Figure 9-13. Dithering Using Triangular Waveform Modulation

Multiple converters can be synchronized using the SYNC pin. This pin can be firmware-configured as either an output SYNC(o) or an input SYNC(i).

- **SYNC(o):** The switching clock is placed on the SYNC(o) pin. This waveform will have a duty cycle of approximately 50%. If frequency dithering is configured by firmware, this signal will also exhibit dithering. Four phase settings are available by firmware configuration to shift the SYNC(o) output relative to the internal switching clock by 0°, 90°, 120°, or 180°. SYNC(o) is used to slave other DC/DC converter clocks to the switching converter clock inside the TPS25772-Q1. When two dc/dc converters operate out of phase, peak input current from the battery is reduced and total input bulk capacitance requirements decrease.

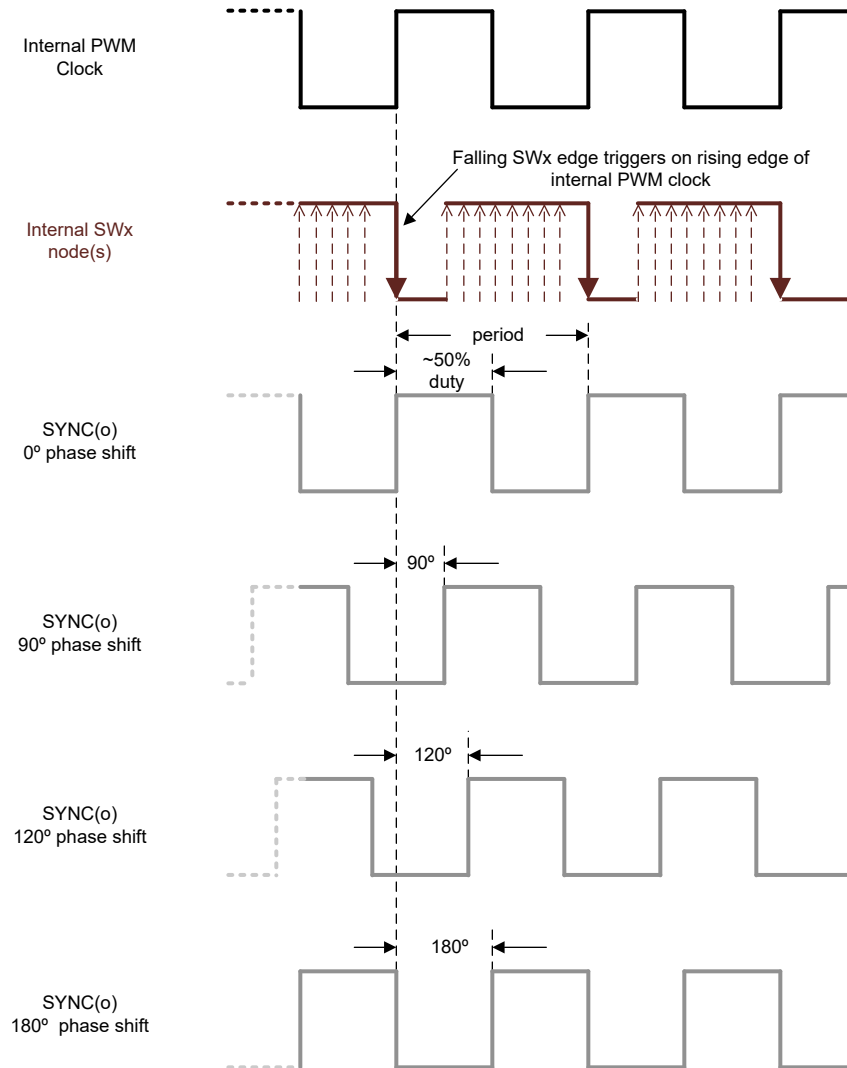


图 9-14. SYNC(o) Phase Shift

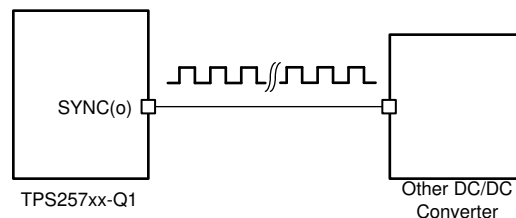


图 9-15. Using SYNC(o) to slave DC/DC Converter

- SYNC(i):** The internal clock is synchronized to the pulse train on the SYNC(i) pin. This feature is used to slave the TPS25772-Q1 to an external clock. The period of this clock must meet synchronization requirements in [SYNC\(i\) frequency ranges](#) or the TPS25772-Q1 will instead use its internal switching clock. If an external clock deviates outside of the acceptable frequency range and then returns to within the acceptable frequency range, the TPS25772-Q1 will resume operation from the external clock after counting 8 consecutive clocks meeting the criteria of [表 9-6](#). When SYNC(i) is configured, frequency dithering is disabled when operating from the internal clock following a failure of the external clock.

**表 9-6. SYNC(i) Frequency Ranges**

| f <sub>sw</sub> Firmware Setting | Allowed SYNC(i) Frequency Range |         |
|----------------------------------|---------------------------------|---------|
|                                  | MIN                             | MAX     |
| 300 kHz                          | 250 kHz                         | 353 kHz |
| 400 kHz                          | 334 kHz                         | 470 kHz |
| 450 kHz                          | 376 kHz                         | 530 kHz |

### 9.3.3.3 VIN Supply and VIN Over-Voltage Protection

#### V<sub>IN</sub> Supply

The voltage V<sub>IN</sub> at the input supply pin IN, measured with respect to AGND, must meet the following requirements:

- **Overvoltage:** The voltage V<sub>IN</sub> must never exceed an absolute maximum of 40 V, and should not exceed 36 V under anticipated operating conditions. Automotive applications will typically require an external transient suppressor to meet this requirement.
- **Load dump:** When the converter is running and V<sub>IN</sub> exceeds 18 V, the positive slew rate dV<sub>IN</sub>/dt must not exceed 200 V/ms.
- **Double battery:** When the converter is not running, the positive slew rate dV<sub>IN</sub>/dt must not exceed 10 V/μs. The input EMI filter can help mitigate input voltage slew rates.
- **Reverse battery:** The voltage V<sub>IN</sub> must never go below –0.3 V. Automotive applications will typically require external reverse voltage blocking circuitry.

The buck-boost switching converter is capable of delivering its full rated output power of 65 W over an input supply range 6.8 V < V<sub>IN</sub> < 18 V. The input voltage can dip down to the UVLO threshold providing that the output power level is appropriately derated.

#### V<sub>IN</sub> Overvoltage Protection Circuitry

The TPS25772-Q1 contains circuitry that protects the power train against load dump and double battery conditions. When VIN exceeds about 19 V, a comparator determines that an input overvoltage condition has occurred. This comparator sends a signal that shuts the switching converter down. Transistors M1, M2, and M3 in [Buck-Boost Internal Power FETs](#) are turned off, and transistor M4 is turned on. However, current is still flowing through the inductor. Two cases may exist: the current may flow forward (from SW1 to SW2) or in reverse (from SW2 to SW1). Reverse current flow will forward-bias the body diode of M1. The voltage across the inductor will then equal the sum of the forward voltage of this diode plus the input voltage, which is sufficient to cause the inductor voltage to rapidly ramp down to zero. Forward current flow will forward-bias the body diode of M2. After the inductor current is released, a small linear regulator biases SW1 to about 15 V. When the overvoltage condition is removed, the switching regulator may resume operation.

### 9.3.3.4 Feedback Paths and Error Amplifiers

The TPS25772-Q1 includes not only a programmable voltage feedback path, but also a programmable average current feedback path that can be used to limit the average current provided by the switching converter to the USB cable. The voltage feedback path also includes provision for cable droop compensation. [図 9-16](#) shows a simplified block diagram of the relevant portions of the integrated circuit.

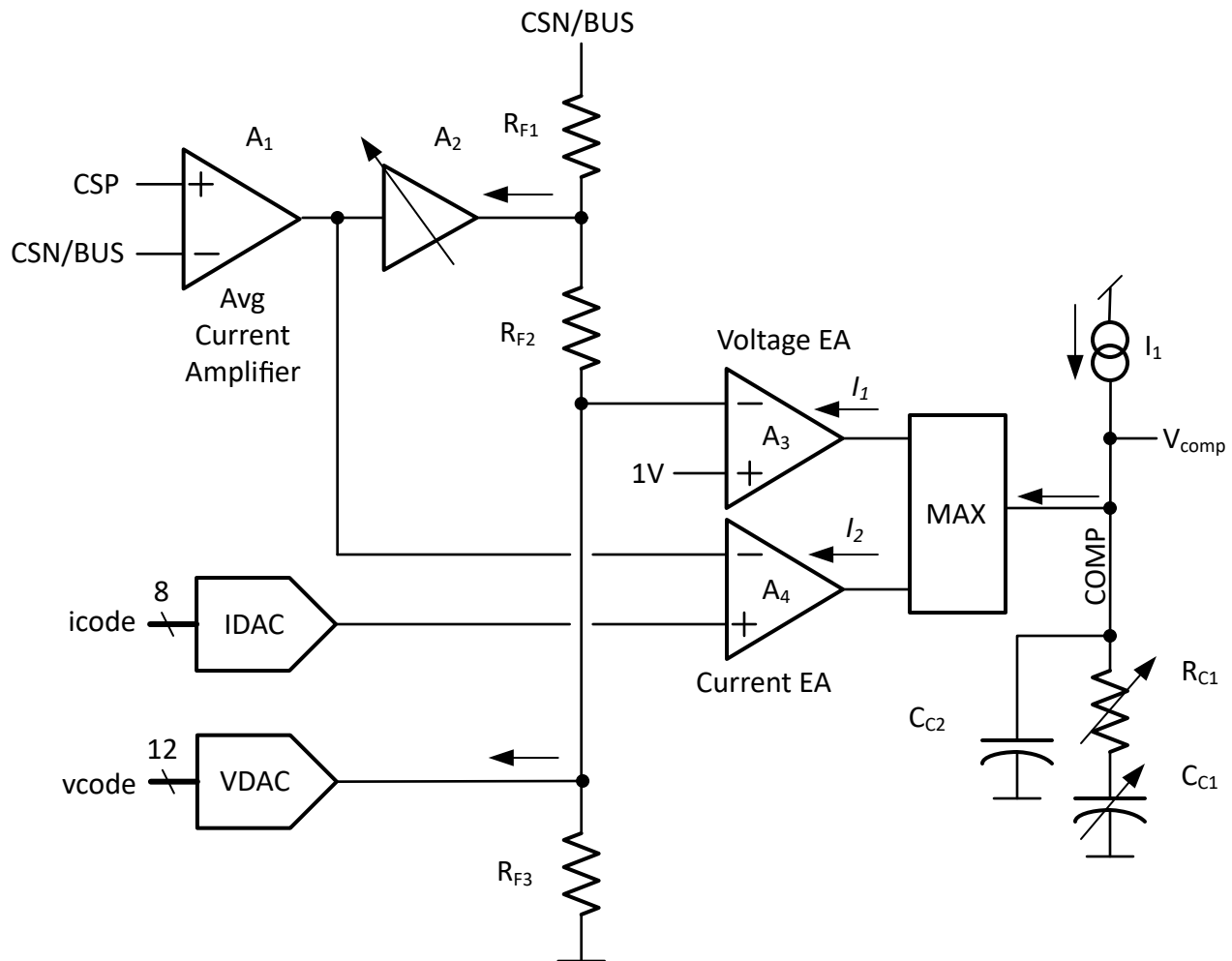


図 9-16. Simplified block diagram of feedback paths and error amplifiers.

### 9.3.3.5 Transconductors and Compensation

The TPS25772-Q1 is internally compensated. The overall slope compensation and loop compensation is internally fixed based on inductor and capacitance values shown in 表 10-1.

### 9.3.3.6 Output Voltage DAC, Soft-Start and Cable Droop Compensation

The buck-boost output voltage is regulated at the CSN/VBUS pin. A 12-bit digital-to-analog converter, VDAC, provides  $\pm 20$ -mV step voltage adjustments of  $V_{\text{CSN/BUS}}$  as commanded by device firmware.

After a successful cable detect event, firmware sets the VDAC to output 5 V as measured on the  $V_{\text{CSN/BUS}}$  output. An internal clock steps up the VDAC codes from an initial 0 V to final 5-V setting producing a monotonic ramp of  $V_{\text{CSN/BUS}}$  to 5 V at  $t_{\text{SS}}$ .

In some applications, the USB-PD controller may be located 1 m, or more, from the USB receptacle. When configured and enabled by firmware, cable droop compensation will increase the  $V_{\text{CSN/BUS}}$  linearly with increasing load current independent of the VDAC setting. Four selectable  $V_{\text{OUT\_CDC}}$  ranges are available. 500 mV is the maximum supported cable droop voltage and it is disabled by default during USB-PD PPS contracts.

### 9.3.3.7 $V_{\text{BUS}}$ Overvoltage Protection

A fixed threshold overvoltage comparator monitors the CSN/BUS pin for overvoltage conditions. When the  $V_{\text{CSN/BUS\_OVP\_R}}$  threshold is exceeded, output OV protection circuitry turns off the internal MOSFETs. Switching resumes when  $V_{\text{CSN/BUS}}$  decreases below  $V_{\text{CSN/BUS\_OVP\_F}}$ .

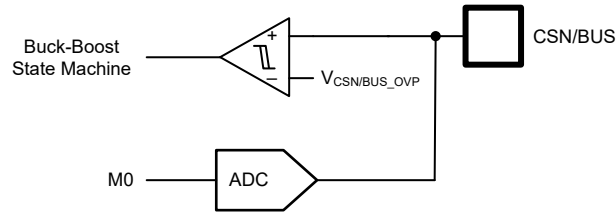


図 9-17.  $V_{BUS}$  OVP and UVP

#### 9.3.3.8 $V_{BUS}$ Undervoltage Protection

PA\_VBUS and PB\_VBUS undervoltage conditions are monitored by the internal ADC. In accordance with USB Power Delivery specifications, the TPS25772-Q1 firmware configures the threshold based on USB PD contract with the attached sink device.

#### 9.3.3.9 Current Sense Resistor ( $R_{SNS}$ ) and Current Limit Operation

The CSP and CSN/BUS pins are the positive and negative inputs to the average current sense amplifier (CSA). The TPS25772-Q1 devices sense port A load current across sense resistor,  $R_{SNS}$ , located between the CSP and CSN/BUS pins. A 10-m $\Omega$ , 1%, power resistor provides a 0 - 50-mV sense voltage over the range  $0 \leq I_{OUT} \leq 5$  A.

A seven bit digital-to-analog converter, IDAC, provides  $\pm 50$ -mA step current limit adjustments and is automatically programmed by device firmware.

#### 9.3.3.10 Buck-Boost Peak Current Limits

The buck and boost peak current limits are adjustable by firmware using the application configuration GUI. Refer to the BUCK-BOOST PEAK CURRENT LIMITS in セクション 7.6 of the *Electrical Characteristics* tables for selectable values.

In most applications it is desirable to limit input current to the automotive USB module to protect module components, connectors and wiring from over-current conditions. The worst case input current condition occurs when  $V_{IN}$  is minimum and  $V_{CSN/BUS}$  is maximum (21 V) while supplying maximum 3.25 A output current. When  $V_{IN} < V_{BUS}$ , the internal DC/DC converter is operating in boost mode. Refer to the 表 10-6 tables in the *Inductor Currents* section to estimate the peak current versus recommended inductor value for the application.

The buck peak current limit setting selection should be just lower than the boost peak current limit. Set as close to the boost peak current limit as selections allow to prevent the possibility of limit cycling between the two peak current limits under extreme transients.  $I_{PEAK(BUCK)} \cong I_{PEAK(BOOST)}$ .

When selecting an inductor, it is important select one with an appropriate saturation current rating,  $I_{L(SAT)}$ . The inductor  $I_{L(SAT)}$  rating should larger than the maximum (MAX)  $I_{PEAK(BOOST)}$  limit from the *Electrical Characteristics* tables to avoid excessive current flow in the TPS25772-Q1 or the inductor.

### 9.3.4 USB-PD Physical Layer

図 9-18 shows the USB PD physical layer block surrounded by a simplified version of the analog plug and orientation detection block. This block applies to Port A and Port B.

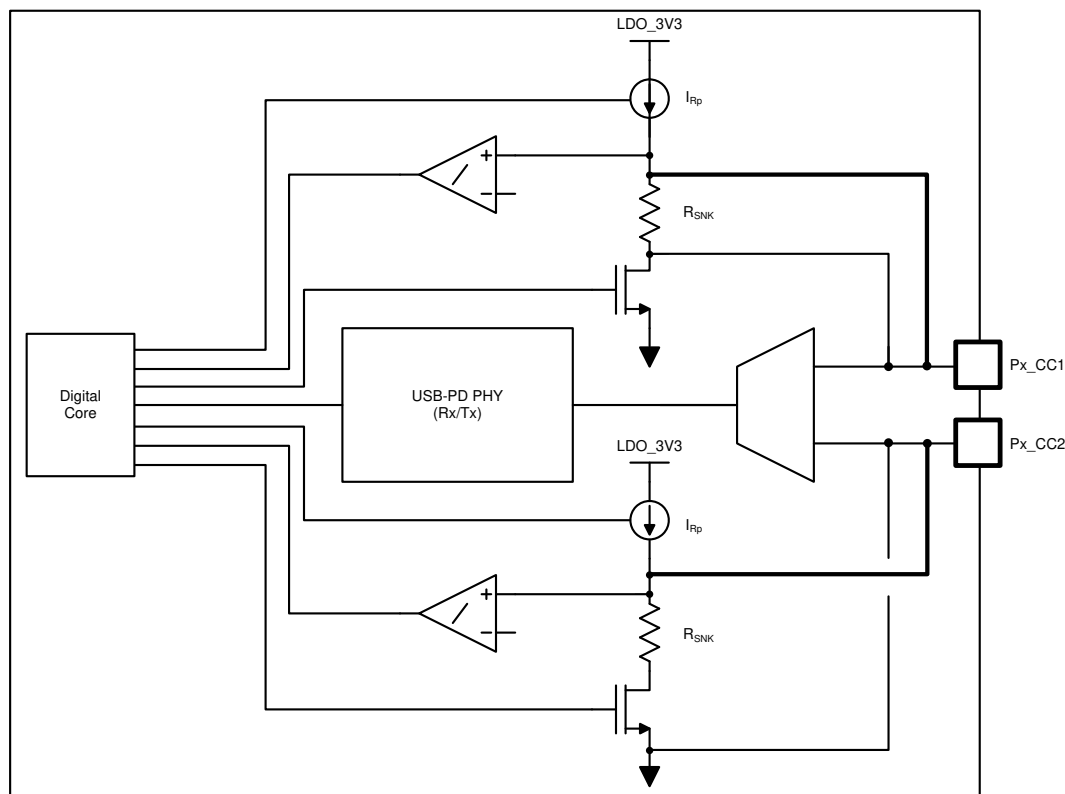


図 9-18. USB-PD Physical Layer and Simplified Plug and Orientation Detection Circuitry

USB-PD messages are transmitted in a USB Type-C system using a BMC (Biphase Mark Coding) signaling. The BMC signal is output on the same pin (Px\_CC1 or Px\_CC2) that is DC biased due to the  $R_p$  (or  $R_d$ ) cable attach mechanism discussed in the [USB-PD BMC Transmitter](#) section.

#### 9.3.4.1 USB-PD Encoding and Signaling

図 9-19 illustrates the high-level block diagram of the baseband USB-PD transmitter. 図 9-20 illustrates the high-level block diagram of the baseband USB-PD receiver.

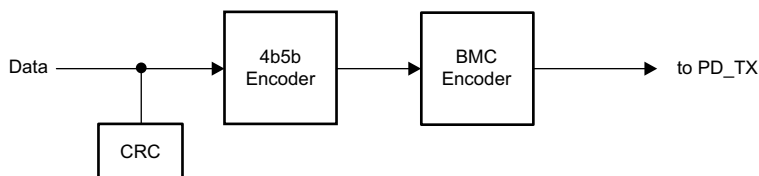


図 9-19. USB-PD Baseband Transmitter Block Diagram

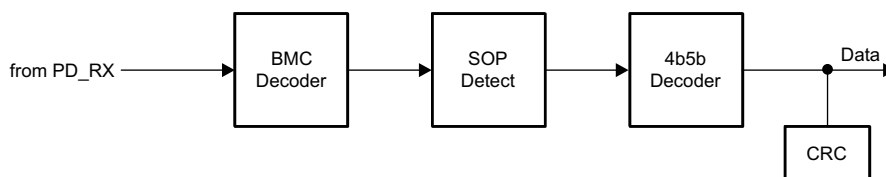
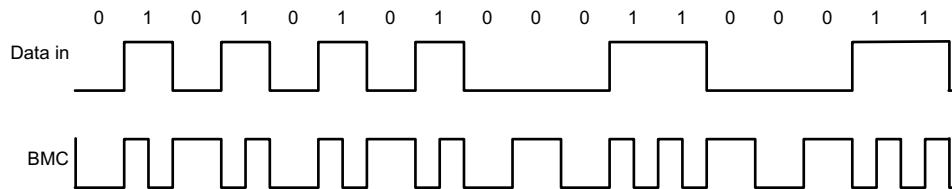


図 9-20. USB-PD Baseband Receiver Block Diagram

### 9.3.4.2 USB-PD Bi-Phase Marked Coding

The USB-PD physical layer implemented in the TPS25772-Q1 is compliant to the [USB-PD Specifications](#). The encoding scheme used for the baseband PD signal is a version of Manchester coding called Biphas Mark Coding (BMC). In this code, there is a transition at the start of every bit time and there is a second transition in the middle of the bit cell when a 1 is transmitted. This coding scheme is nearly DC balanced with limited disparity (limited to 1/2 bit over an arbitrary packet, so a very low DC level). [Figure 9-21](#) illustrates Biphas Mark Coding.



**Figure 9-21. Biphas Mark Coding Example**

The USB PD baseband signal is driven onto the Px\_CC1 or Px\_CC2 pin with a tri-state driver. The tri-state driver controls slew rate to limit coupling to D+/D– and to other signal lines in the Type-C fully featured cables. When sending the USB-PD preamble, the transmitter starts by transmitting a low level. The receiver at the other end tolerates the loss of the first edge. The transmitter terminates the final bit by an edge to ensure the receiver clocks the final bit of EOP.

### 9.3.4.3 USB-PD Transmit (TX) and Receive (Rx) Masks

The USB-PD driver meets the defined USB-PD BMC TX masks. Since a BMC coded “1” contains a signal edge at the beginning and middle of the UI, and the BMC coded “0” contains only an edge at the beginning, the masks are different for each. The USB-PD receiver meets the defined USB-PD BMC Rx masks. The boundaries of the Rx outer mask are specified to accommodate a change in signal amplitude due to the ground offset through the cable. The Rx masks are therefore larger than the boundaries of the TX outer mask. Similarly, the boundaries of the Rx inner mask are smaller than the boundaries of the TX inner mask. Triangular time masks are superimposed on the TX outer masks and defined at the signal transitions to require a minimum edge rate that has minimal impact on adjacent higher speed lanes. The TX inner mask enforces the maximum limits on the rise and fall times. Refer to the [USB-PD Specifications](#) for more details.

### 9.3.4.4 USB-PD BMC Transmitter

The TPS25772-Q1 transmits and receives USB-PD data over one of the Px\_CCy pins for a given CC pin pair (one pair per USB Type-C port). The Px\_CCy pins are also used to determine the cable orientation (see the [Cable Plug and Orientation Detection](#) section) and maintain cable/device attach detection. Thus, a DC bias exists on the Px\_CCy pins. The transmitter driver overdrives the Px\_CCy DC bias while transmitting, but returns to a Hi-Z state allowing the DC voltage to return to the Px\_CCy pin when not transmitting. While either Px\_CC1 or Px\_CC2 may be used for transmitting and receiving, during a given connection only the one that mates with the CC pin of the plug is used; so there is no dynamic switching between Px\_CC1 and Px\_CC2. [Figure 9-22](#) shows the USB-PD BMC TX and RX driver block diagram.

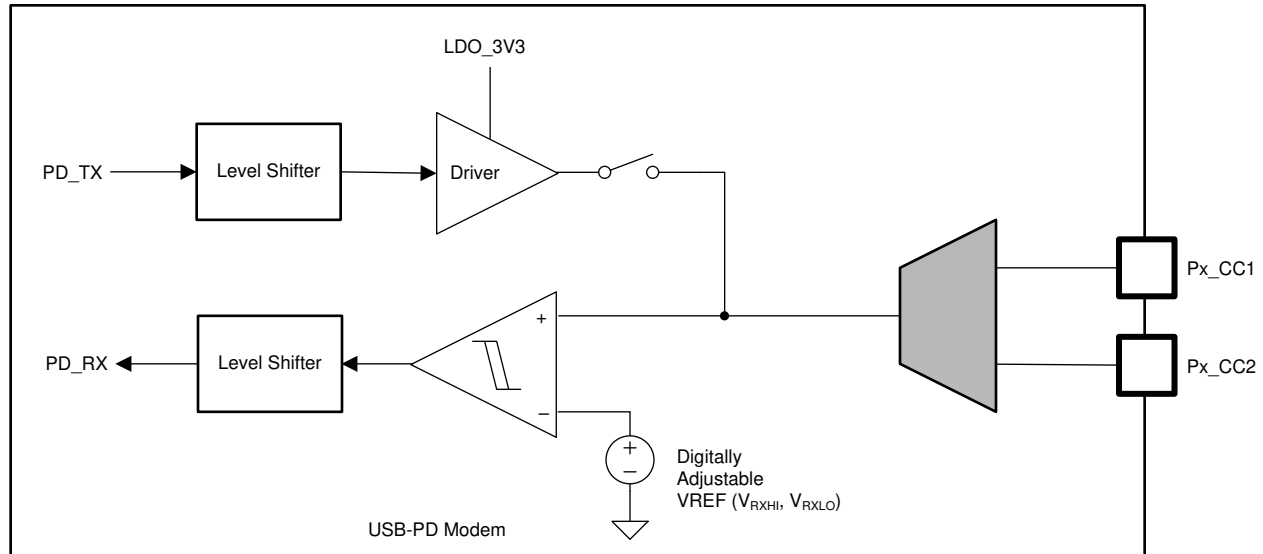


図 9-22. USB-PD BMC TX/Rx Block Diagram

図 9-23 shows the transmission of the BMC data on top of the DC bias. Note, The DC bias can be anywhere between the minimum threshold for detecting a UFP attach and the maximum threshold for detecting a Sink attach to a Source. This means that the DC bias can be above or below the  $V_{OH}$  of the transmitter driver.

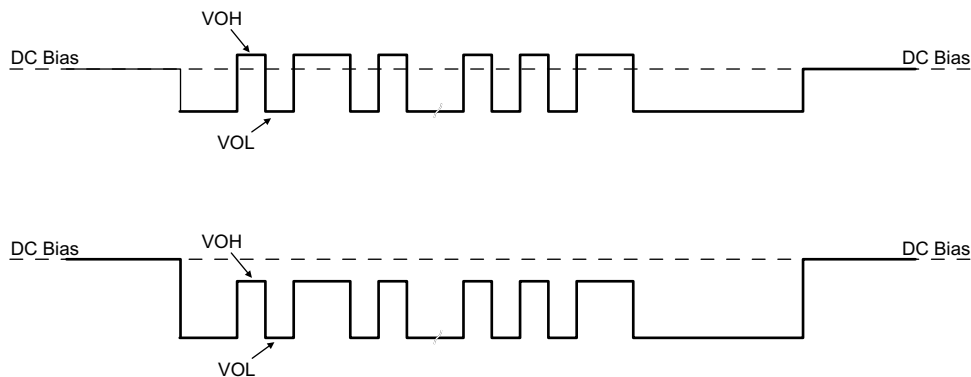


図 9-23. TX Driver Transmission with DC Bias

The transmitter drives a digital signal onto the Px\_CCy lines. The signal peak,  $V_{TXHI}$ , is set to meet the TX masks defined in the [USB-PD Specifications](#). Note that the TX mask is measured at the far-end of the cable.

When driving the line, the transmitter driver has an output impedance of  $Z_{DRIVER}$ .  $Z_{DRIVER}$  is determined by the driver resistance and the shunt capacitance of the source and is frequency dependent.  $Z_{DRIVER}$  impacts the noise ingress in the cable.

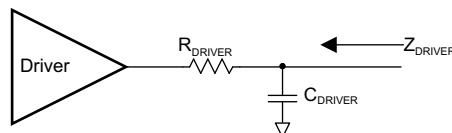
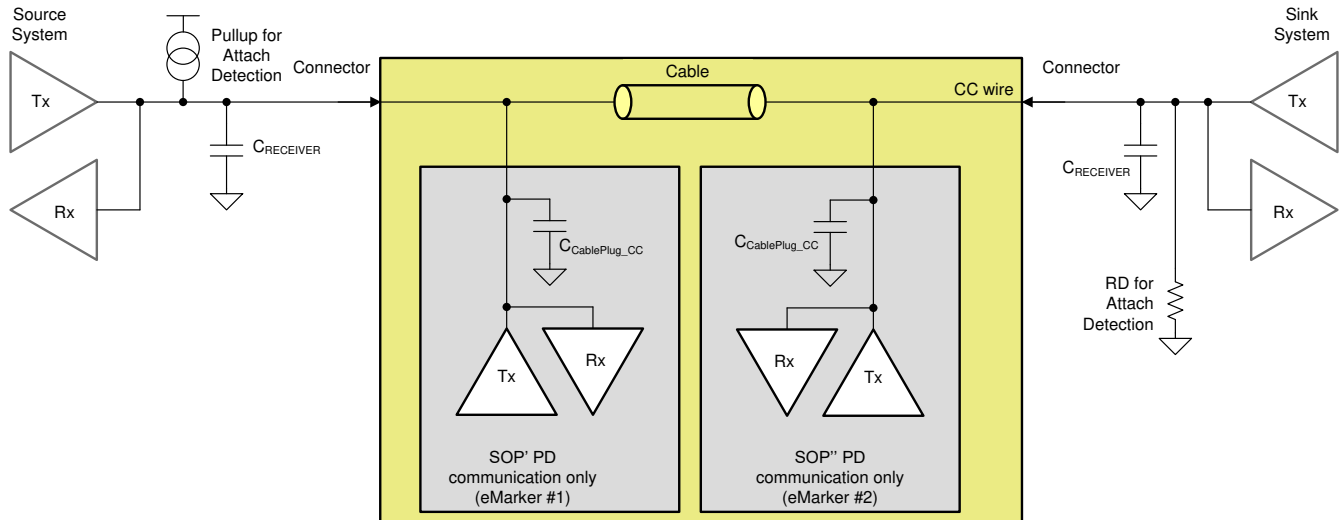


図 9-24. ZDRIVER Circuit

#### 9.3.4.5 USB-PD BMC Receiver

The receiver block of the TPS25772-Q1 receives a signal that falls within the allowed Rx masks defined in the USB PD specification. The receive thresholds and hysteresis come from this mask.

Figure 9-25 shows an example of a multi-drop USB-PD connection (only the CC wire). This connection has the typical Sink (device) to Source (host) connection, but also includes cable USB-PD Tx/Rx blocks. Only one system can be transmitting at a time. All other systems are Hi-Z ( $Z_{BMCRX}$ ). The [USB-PD Specification](#) also specifies the capacitance that can exist on the wire as well as a typical DC bias setting circuit for attach detection.



**Figure 9-25. Example USB-PD Multi-Drop Configuration**

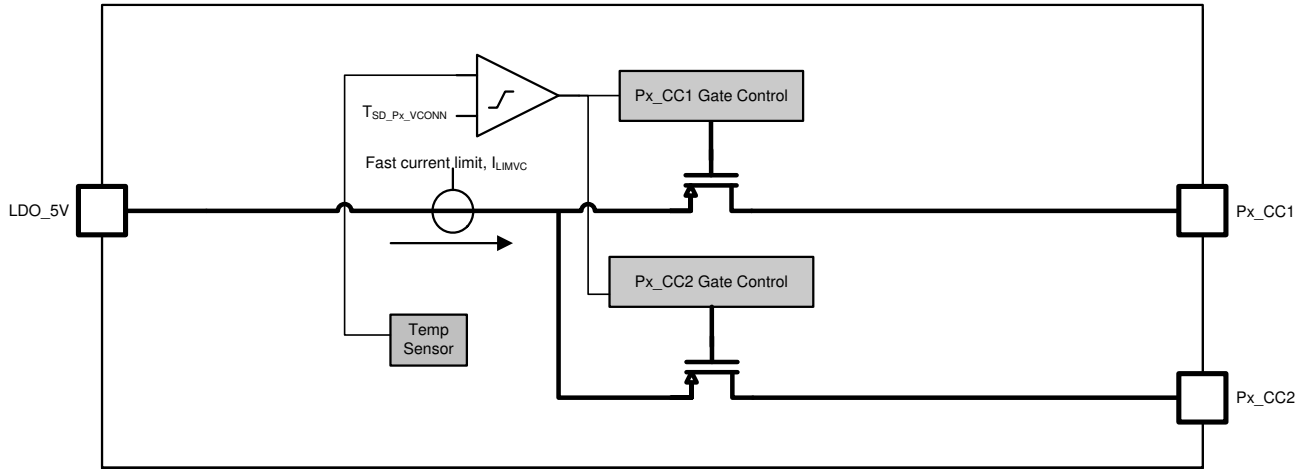
#### 9.3.4.6 Squelch Receiver

The TPS25772-Q1 has a squelch receiver to monitor for the bus idle condition as defined by the USB PD specification. The squelch receiver output reflects the state of the CC pin regardless of the source of the transmission.

#### 9.3.5 VCONN

Internal VCONN sourcing power paths are firmware configurable. Using only the internal LDO\_5V supply, both Port A and Port B are able to draw 20 mA continuously. If an external 5-V regulator is connected to the LDO\_5V pin and the application GUI settings are enabled, both Port A and Port B are able to draw 200 mA continuously. When disabled, blocking FETs in the both Port A and Port B VCONN paths protect the LDO\_5V rail from high-voltage and reverse current.

When VCONN power is enabled and provided, the internal VCONN power switches have a current limit of  $I_{LIMVC}$ . If the VCONN load current exceeds  $I_{LIMVC}$ , the current clamping circuit activates within  $t_{IOS\_PP\_CABLE}$  and the switch behaves as a constant current source. Reverse current blocking is disabled when current is flowing to Px\_CC1 or Px\_CC2.



9-26. VCONN Power Switches

When operating in current limit, the VCONN FET temperature rises. Local temperature sensors disable the Px\_VCONN path in current limit when  $T_{\text{sensor}} > T_{\text{SD\_Px\_VCONN}}$  within  $t_{\text{PP\_CABLE\_off}}$ . The application firmware enters USB Type-C Error Recovery on the affected port.

LDO\_5V must remain above its under voltage lock out threshold ( $V_{\text{LDO\_5V(UVLO\_F)}}$ ) for Px\_VCONN operation. If the  $V_{\text{LDO\_5V(UVLO\_F)}}$  threshold is reached, Px\_VCONN paths are automatically disabled within  $t_{\text{PP\_CABLE\_off}}$ .

### 9.3.6 Cable Plug and Orientation Detection

9-27 shows the plug and orientation detection block at each Px\_CCy pin (PA\_CC1, PA\_CC2, PB\_CC1, PB\_CC2). Each CC pin has identical detection circuitry.

When the port is operating as a Type-C source, the  $V_{\text{REFx}}$  nodes are multiplexed to the  $V_{\text{SRC}}$  thresholds corresponding to the advertised Type-C source capability current,  $I_{\text{Rp\_}}$ .

When the port is operating as a Type-C sink, the  $V_{\text{REFx}}$  nodes are multiplexed to the  $V_{\text{SNK}}$  thresholds corresponding to sink detection.

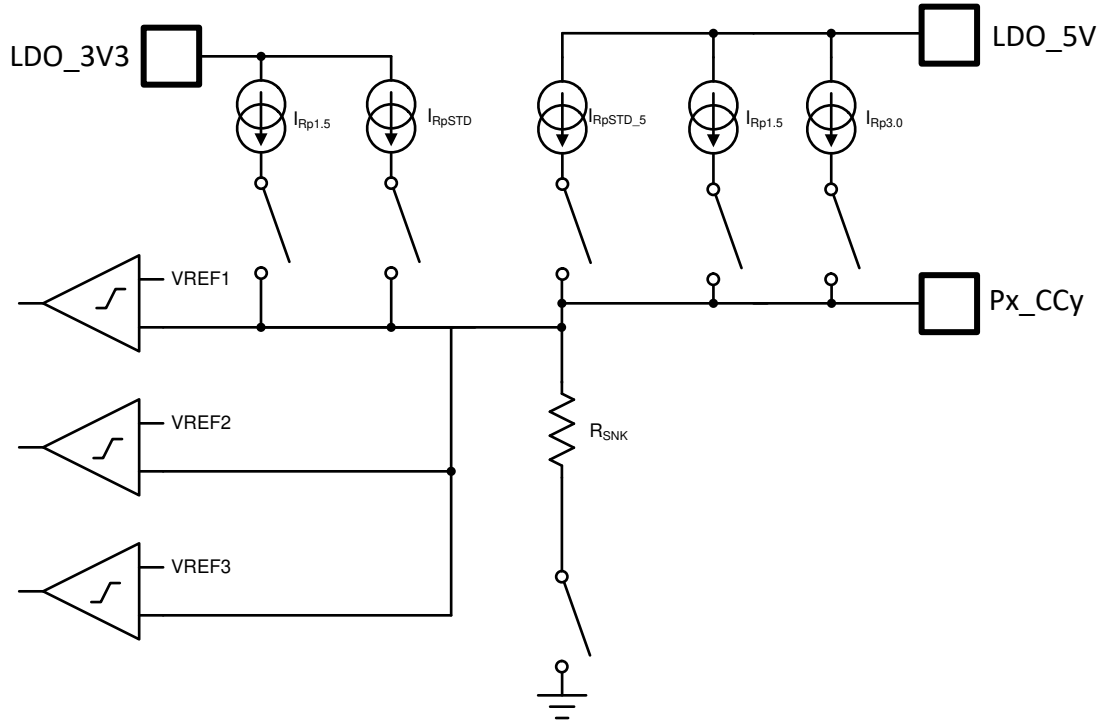


図 9-27. Plug and Orientation Detection Block

### 9.3.6.1 Configured as a Source

When either of the PA or PB ports is configured as a Source, the device detects when a cable or a Sink is attached using the Px\_CC1 and Px\_CC2 pins. When in a disconnected state, the device monitors the voltages on these pins to determine what, if anything, is connected. See [USB Type-C Specification](#) for more information.

表 9-7 shows the Cable Detect States for a Source.

表 9-7. Cable Detect States for a Source

| Px_CC1 | Px_CC2 | CONNECTION STATE              | RESULTING ACTION                                                                                                         |
|--------|--------|-------------------------------|--------------------------------------------------------------------------------------------------------------------------|
| Open   | Open   | Nothing attached              | Continue monitoring both Px_CCy pins for attach. Power is not applied to Px_VBUS or VCONN.                               |
| Rd     | Open   | Sink attached                 | Monitor Px_CC1 for detach. Power is applied to Px_VBUS but not to VCONN (Px_CC2).                                        |
| Open   | Rd     | Sink attached                 | Monitor Px_CC2 for detach. Power is applied to Px_VBUS but not to VCONN (Px_CC1).                                        |
| Ra     | Open   | Powered Cable-No UFP attached | Monitor Px_CC2 for a Sink attach and Px_CC1 for cable detach. Power is not applied to Px_VBUS or VCONN (Px_CC1).         |
| Open   | Ra     | Powered Cable-No UFP attached | Monitor Px_CC1 for a Sink attach and Px_CC2 for cable detach. Power is not applied to Px_VBUS or VCONN (Px_CC2).         |
| Ra     | Rd     | Powered Cable-UFP Attached    | Provide power on Px_VBUS and VCONN (Px_CC1) then monitor Px_CC2 for a Sink detach. Px_CC1 is not monitored for a detach. |
| Rd     | Ra     | Powered Cable-UFP attached    | Provide power on Px_VBUS and VCONN (Px_CC2) then monitor Px_CC1 for a Sink detach. Px_CC2 is not monitored for a detach. |

When a port is configured as a Source, a current  $I_{Rp1.5A}$  is driven out of each Px\_CCy pin and each pin is monitored for different states. When a Sink is attached to the pin a pull-down resistance of  $R_d$  to GND exists. The current  $I_{Rp1.5A}$  is then forced across the resistance  $R_d$  generating a voltage at the Px\_CCy pin. The device

applies the configured  $I_{Rp1.5A}$  until the buck-boost regulator is enabled and operating at 5 V, at which time application firmware may remain at  $I_{Rp1.5A}$  or change to  $I_{Rp3.0A}$ .

When the Px\_CCy pin is connected to an electronically marked cable VCONN input, the pull-down resistance is different ( $R_a$ ). In this case the voltage on the Px\_CCy pin will pull below  $V_{RDstd}$  and the system recognizes the electronically marked cable.

The  $V_{Dstd1.5}$  or  $V_{D3.0}$  threshold is monitored to detect a disconnection depending upon which Rp current source is active. When a connection has been recognized and the voltage on Px\_CCy subsequently rises above the disconnect threshold for  $t_{CC}$ , the system registers a disconnection.

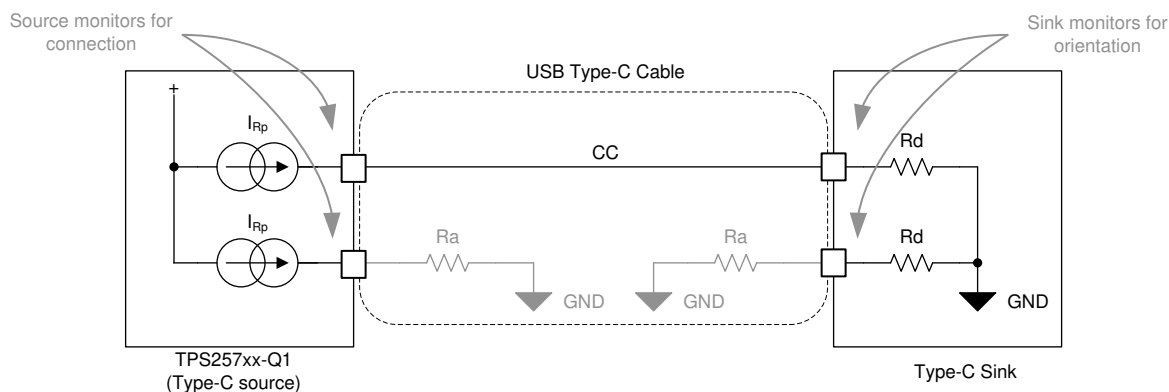


図 9-28. Type-C Cable

### 9.3.6.2 Configured as a Sink

When the TPS25772-Q1 port is configured as a Sink, such as in Firmware Update Mode with TVSP Index 8, the device presents a pull-down resistance  $R_{SNK}$  on each PA\_CCy pin and waits for a Source to attach and pull-up the voltage on the pin. The Source pulls-up the PA\_CCy pin by applying either a resistance or a current. The Sink detects an attachment by the presence of VBUS. The Sink determines the advertised current from the Source by the pull-up applied to the PA\_CCy pin.

### 9.3.6.3 Overvoltage Protection (Px\_CC1, Px\_CC2)

Comparators on the Px\_CCy pins detect when the voltage on CC1 or CC2 is too high, or there is reverse current into the LDO\_5V output. During an overvoltage event, VCONN is disabled within tPP\_CABLE\_FSD and the associated USB PD transmitter is disabled.

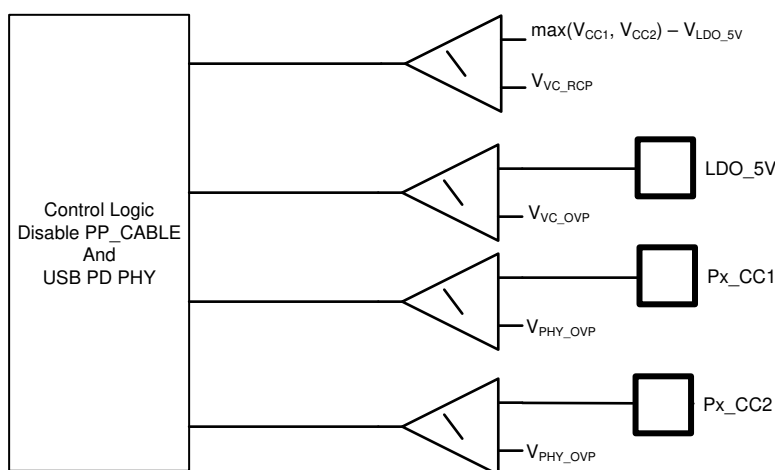


図 9-29. Over-voltage and Reverse Current Protection

### 9.3.7 ADC

The ADC is shown in 図 9-30. The ADC is an 8-bit successive approximation ADC. The input to the ADC is an analog input mux that supports multiple inputs from various voltages and currents in the device. The output from the ADC is available to be read and used by application firmware.

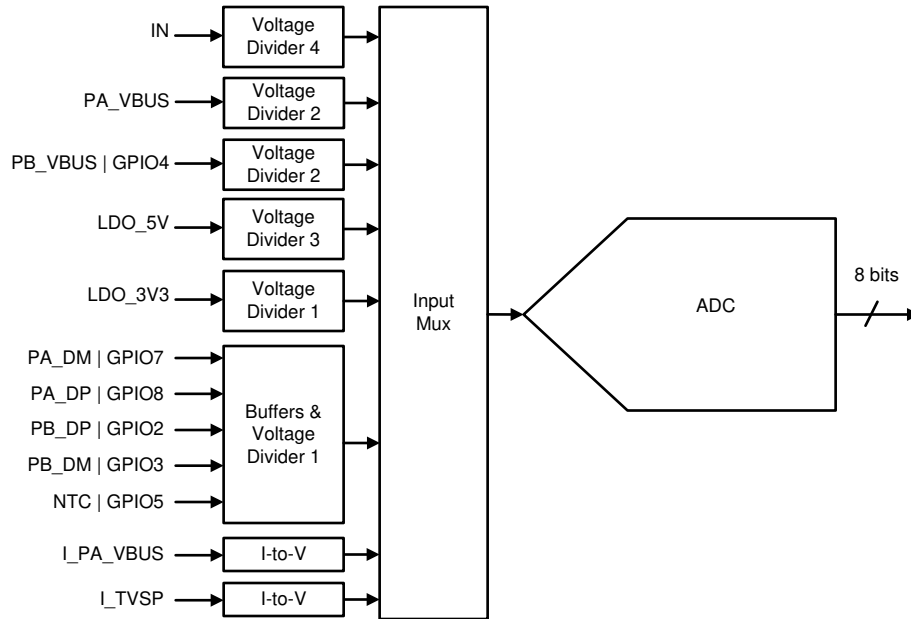


図 9-30. SAR ADC

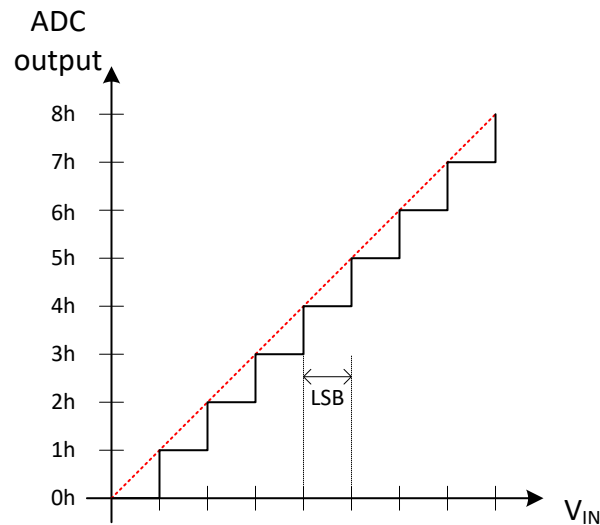


図 9-31. ADC Conversion

#### 9.3.7.1 ADC Divider Ratios

The ADC voltage inputs are each divided down to the full-scale input of 1.2 V. The ADC current sensing elements are not divided.

表 9-8 shows the divider ratios for each ADC input. The application firmware may select any group of channels to be auto-sequenced in the round robin automatic readout mode.

表 9-8. ADC Inputs

| CHANNEL | SIGNAL          | TYPE    | DIVIDER RATIO | BUFFERED |
|---------|-----------------|---------|---------------|----------|
| 0       | I_TVSP          | Current | n/a           | No       |
| 1       | IN              | Voltage | 17            | No       |
| 2       | LDO_3V3         | Voltage | 3             | No       |
| 3       | PA_VBUS         | Voltage | 21            | No       |
| 4       | GPIO4   PB_VBUS | Voltage | 21            | No       |
| 5       | I_PA_VBUS       | Current | n/a           | No       |
| 6       | GPIO2   PB_DP   | Voltage | 3             | Yes      |
| 7       | GPIO3   PB_DM   | Voltage | 3             | Yes      |
| 8       | GPIO5   NTC     | Voltage | 3             | Yes      |
| 9       | GPIO7   PA_DM   | Voltage | 3             | Yes      |
| 10      | GPIO8   PA_DP   | Voltage | 3             | Yes      |
| 11      | LDO_5V          | Voltage | 5             | No       |

### 9.3.8 BC 1.2, Legacy and Fast Charging Modes (Px\_DP, Px\_DM)

BC 1.2 downstream port charger emulation is application GUI configurable. The following charging modes can be enabled or disabled:

- DCP (Dedicated Charging Port) Shorted Mode
- Divider-3 Mode
- 1.2-V Mode
- HVDCP (High Voltage Dedicated Charging Port) Mode

The following table shows voltage sources, resistors and comparator hardware used in each mode. Symbol "X" represents that the corresponding module is implemented.

| Application | 2.7-V SRC | 1.2-V SRC | R <sub>DCP_DAT</sub> | R <sub>DM_DWN</sub><br>(20 kΩ) | V <sub>DAT_REF</sub> | V <sub>SEL_REF</sub> |
|-------------|-----------|-----------|----------------------|--------------------------------|----------------------|----------------------|
| DCP         |           |           | X                    |                                |                      |                      |
| Divider-3   | X         |           |                      |                                |                      |                      |
| 1.2 V       |           | X         | X                    |                                |                      |                      |
| HVDCP       |           |           |                      | X                              | X                    | X                    |

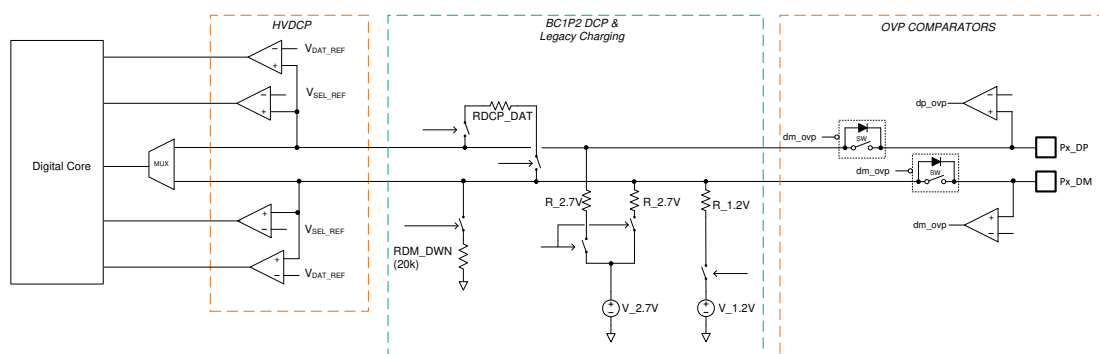


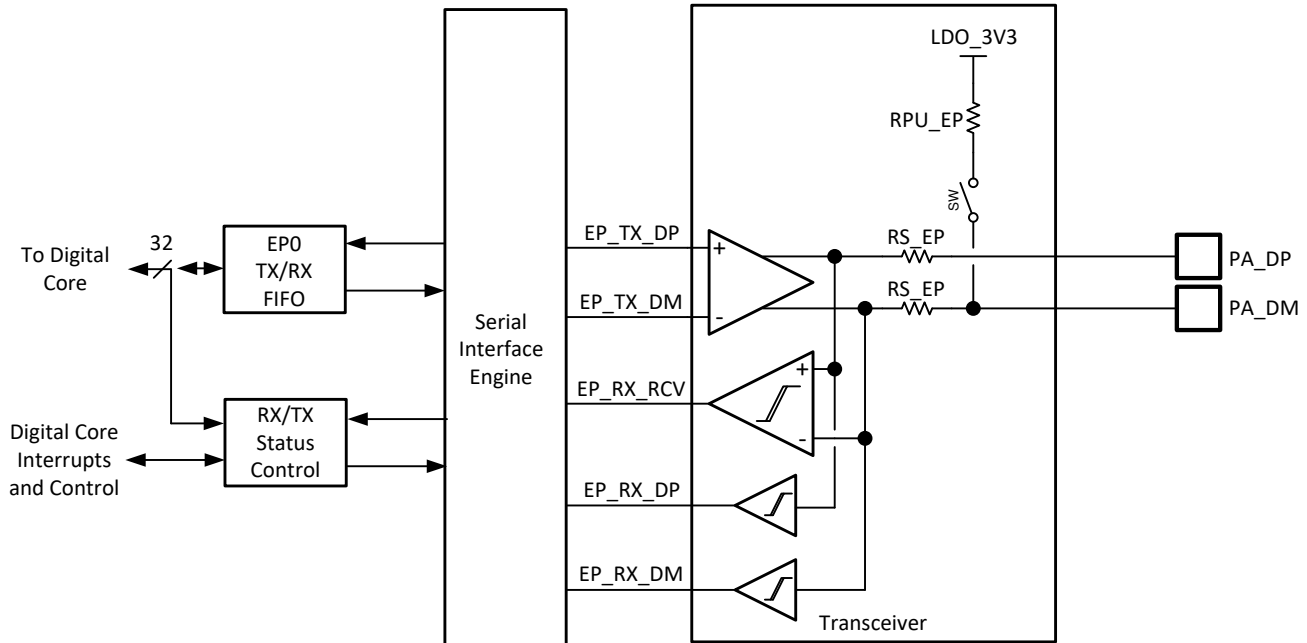
図 9-32. BC1P2 Functional Diagram

### 9.3.9 USB2.0 Low-Speed Endpoint

The USB low-speed Endpoint is a USB 2.0 low-speed (1.5 Mbps) interface used to support HID class based accesses. The TPS25772-Q1 supports control of endpoint EP0. This endpoint enumerates to a USB 2.0 host

during firmware update mode. Firmware update mode is entered with when the device is powered on with an  $R_{TVSP}$  corresponding to TVSP Index 8.

☒ 9-33 shows the USB Endpoint physical layer. The physical layer consists of the analog transceiver, the Serial Interface Engine, and the Endpoint FIFOs and supports low-speed USB operation.



☒ 9-33. USB Endpoint PHY

The transceiver is made up of a fully differential output driver, a differential to single-ended receive buffer and two single-ended receive buffers on the D+/D– independently. The output driver drives the D+/D– through a source resistance  $RS_{EP}$ .  $RPU_{EP}$  is disconnected during transmit mode of the transceiver.

When the endpoint is in receive mode, the resistance  $RPU_{EP}$  is connected to the PA\_DM pin. The  $RPU_{EP}$  resistance advertises low speed mode only.

### 9.3.10 Digital Interfaces

The TPS25772-Q1 contains one I<sup>2</sup>C controller which used for communicating with I<sup>2</sup>C target devices. Depending upon application GUI firmware configuration, an I<sup>2</sup>C target and GPIOs may be available.

#### 9.3.10.1 General GPIO

An application configuration GUI manages the multi-function pins which contain General Purpose Input/Output functionality. Each buffer is configurable to be a push-pull output or open drain output. When configured as an input, the signal can be a de-glitched digital input or an analog input to the ADC (only designated pins). The push-pull output is a simple CMOS totem-pole structure. Independent pull-up and pull-down enables can be configured using the application GUI. When interfacing with non 3.3-V I/O devices the output buffer should be configured as an open drain output and an external pull-up resistor attached to the GPIO pin.

#### 9.3.10.2 I<sup>2</sup>C Buffer

The TPS25772-Q1 features two I<sup>2</sup>C interfaces that each use an I<sup>2</sup>C I/O driver like the one shown in ☒ 9-34. This I/O consists of an open-drain output and an input comparator with de-glitching.

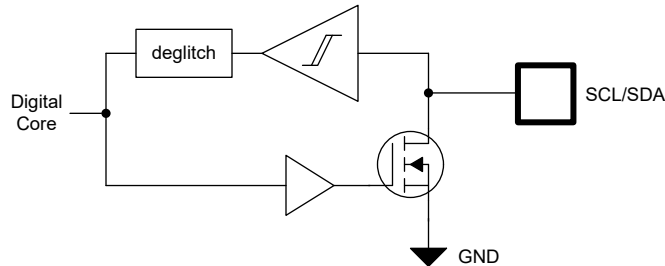


図 9-34. I<sup>2</sup>C Driver

### 9.3.11 I<sup>2</sup>C Interface

The TPS25772-Q1 has two I<sup>2</sup>C ports. I<sup>2</sup>C1 is a controller interface. I<sup>2</sup>C2 is a target interface.

I<sup>2</sup>C1 is used to read from or write to external target devices. During boot I<sup>2</sup>C1 is configured to read firmware patch and application configuration data from an external EEPROM with target address 0x50.

Depending upon application configuration, the TPS25772-Q1 may expose target port, I<sup>2</sup>C2, using multi-function pins: GPIO2 (I<sup>2</sup>C\_SCL2), GPIO3 (I<sup>2</sup>C\_SDA2). When the TPS257xx-Q1 is used in systems with a HUB or MCU, the I<sup>2</sup>C2 port can provide connection status and telemetry information as well as transfer firmware updates from the HUB or MCU to an EEPROM connected on I<sup>2</sup>C1.

$\overline{\text{IRQ}}$  functionality depends upon firmware application configuration.  $\overline{\text{IRQ}}$  is not always available on both I<sup>2</sup>C1 and I<sup>2</sup>C2 simultaneously. the IRQ is available as follows:

- Multi-function pin GPIO9:  $\overline{\text{IRQ1}}(\text{i})$ ,  $\overline{\text{IRQ1}}(\text{o})$ ,  $\overline{\text{IRQ2}}(\text{o})$
- Multi-function pin GPIO1:  $\overline{\text{IRQ2}}(\text{o})$

Where (i) = operates as an input, and (o) = operates as output.

In HUB applications where I<sup>2</sup>C control is not used, GPIO9 can be configured as a simple  $\overline{\text{FAULT}}$  pin reporting port over-current conditions as required by the USB 2.0 specifications.

表 9-9. I<sup>2</sup>C Summary

| I <sup>2</sup> C Bus | Type       | Typical Usage                                                                                                                                                                                                                                                 | Max Bus Frequency      |
|----------------------|------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------------|
| I <sup>2</sup> C1c   | Controller | Connect to I <sup>2</sup> C EEPROM, USB Type-C mux, I <sup>2</sup> C temperature sensor, I <sup>2</sup> C GPIO expander, or other I <sup>2</sup> C target. Use LDO_5V or LDO_3V3 pin as the pull-up voltage. Multi-controller configuration is not supported. | 1 MHz (Fast Mode Plus) |
| I <sup>2</sup> C2t   | Target     | Connect to I <sup>2</sup> C capable USB HUB, MCU or automotive processor.                                                                                                                                                                                     | 1 MHz (Fast Mode Plus) |

#### 9.3.11.1 I<sup>2</sup>C Interface Description

The I<sup>2</sup>C1 and I<sup>2</sup>C2 ports support Standard, Fast Mode, and Fast Mode Plus I<sup>2</sup>C interfaces. The bidirectional I<sup>2</sup>C bus consists of the serial clock (SCL) and serial data (SDA) lines. Both lines must be connected to a supply through a pull-up resistor. Data transfer may be initiated only when the bus is not busy.

A controller sending a Start condition, a high-to-low transition on the SDA input/output, while the SCL input is high initiates I<sup>2</sup>C communication. After the Start condition, the device address byte is sent, most significant bit (MSB) first, including the data direction bit (R/W).

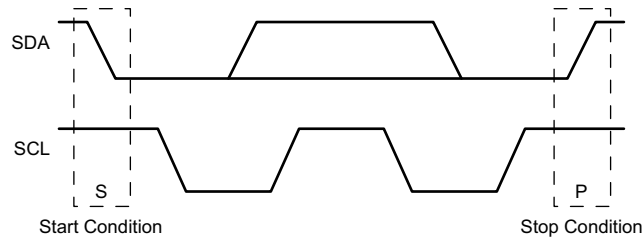
After receiving the valid address byte, this device responds with an acknowledge (ACK), a low on the SDA input/output during the high of the ACK-related clock pulse. On the I<sup>2</sup>C bus, only one data bit is transferred during each clock pulse. The data on the SDA line must remain stable during the high pulse of the clock period as changes in the data line at this time are interpreted as control commands (Start or Stop). The controller sends a Stop condition, a low-to-high transition on the SDA input/output while the SCL input is high.

Any number of data bytes can be transferred from the transmitter to receiver between the Start and the Stop conditions. Each byte of eight bits is followed by one ACK bit. The transmitter must release the SDA line before the receiver can send an ACK bit. The device that acknowledges must pull down the SDA line during the ACK

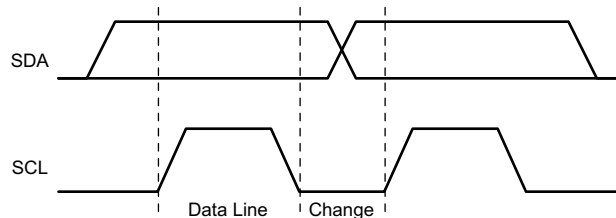
clock pulse, so that the SDA line is stable low during the high pulse of the ACK-related clock period. When a target receiver is addressed, it must generate an ACK after each byte is received. Similarly, the controller must generate an ACK after each byte that it receives from the target transmitter. Setup and hold times must be met to ensure proper operation.

A controller receiver signals an end of data to the target transmitter by not generating an acknowledge (NACK) after the last byte has been clocked out of the target. The controller receiver holding the SDA line high does this. In this event, the target transmitter must release the data line to enable the controller to generate a Stop condition.

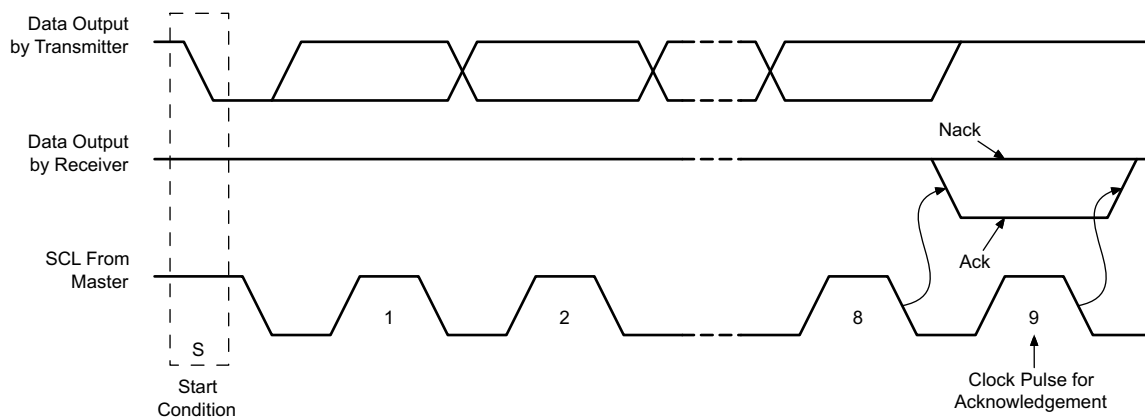
☒ 9-35 shows the start and stop conditions of the transfer. ☒ 9-36 shows the SDA and SCL signals for transferring a bit. ☒ 9-37 shows a data transfer sequence with the ACK or NACK at the last clock pulse.



☒ 9-35. I<sup>2</sup>C Definition of Start and Stop Conditions



☒ 9-36. I<sup>2</sup>C Bit Transfer



☒ 9-37. I<sup>2</sup>C Acknowledgment

### 9.3.11.2 I<sup>2</sup>C Clock Stretching

Clock stretching for I<sup>2</sup>C2. The target I<sup>2</sup>C port may hold the clock line (SCL) low after receiving (or sending) a byte, indicating that it is not yet ready to process more data. The controller communicating with the target must not finish the transmission of the current bit and must wait until the clock line actually goes high. When the target is clock stretching, the clock line remains low.

The controller must wait until it observes the clock line transitioning high plus an additional minimum time (4  $\mu$ s for standard 100-kbps I<sup>2</sup>C) before pulling the clock low again.

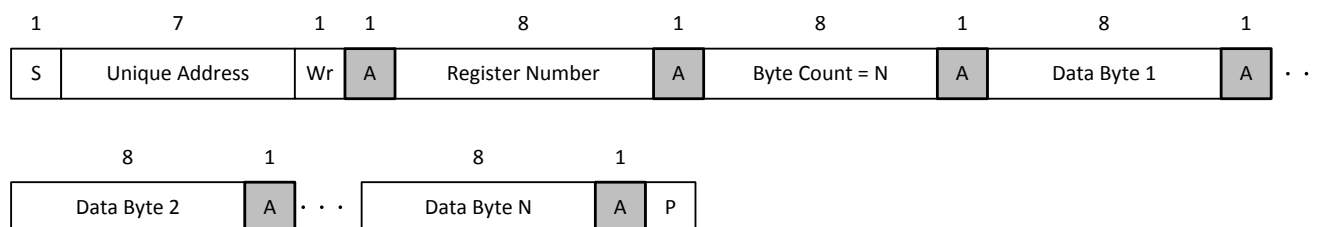
Any clock pulse may be stretched but typically it is the interval before or after the acknowledgment bit.

### 9.3.11.3 I<sup>2</sup>C Address Setting

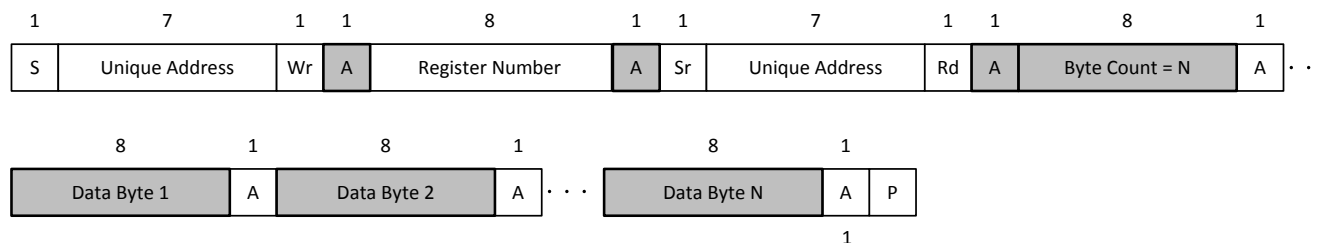
A HUB, MCU, or automotive processor host should only use I<sup>2</sup>C\_SCL2 and I<sup>2</sup>C\_SDA2 for loading a firmware patches or general status communication. Once the boot process is complete, each I<sup>2</sup>C port is assigned a unique target address as determined by the TVSP pin. The target address used by each port on the I<sup>2</sup>C2s bus are determined from the application configuration.

### 9.3.11.4 Unique Address Interface

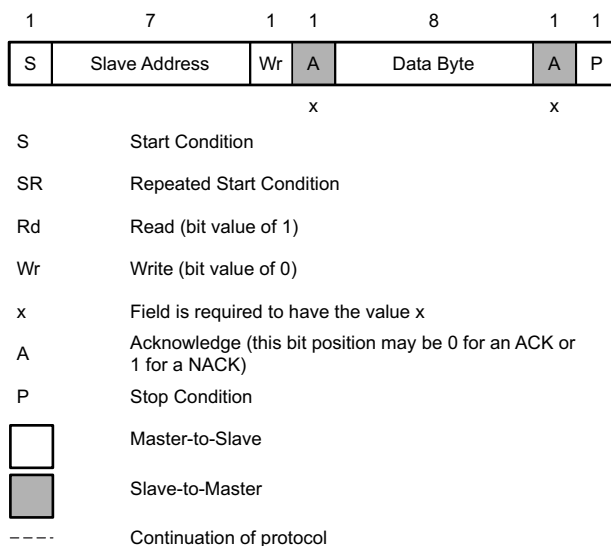
The Unique Address Interface allows for complex interaction between an I<sup>2</sup>C controller and a single TPS25772-Q1. The I<sup>2</sup>C target sub-address is used to receive or respond to Host Interface protocol commands. [Figure 9-38](#) and [Figure 9-39](#) show the write and read protocol for the I<sup>2</sup>C target interface, and a key is included in [Figure 9-40](#) to explain the terminology used. The TPS25772-Q1 host interface utilizes a different unique address to identify each of the two USB Type-C ports controlled by the TPS25772-Q1. The key to the protocol diagrams is in the SMBus Specification and is repeated here in part.



**Figure 9-38. I<sup>2</sup>C Unique Address Write Register Protocol**



**Figure 9-39. I<sup>2</sup>C Unique Address Read Register Protocol**



### ❏ 9-40. I<sup>2</sup>C Read/Write Protocol Key

#### 9.3.11.5 I<sup>2</sup>C Pullup Resistor Calculation

Typical value for  $R_P$ , the I<sup>2</sup>C pullup resistor is given by:

$$R_P = t_r / (0.8473 \times C_b)$$

Refer to 表 9-10 for values of  $t_r$ ,  $C_b$  and  $V_{OL}$ .

### 表 9-10. Parametrics from I2C Specifications

| Parameter        |                                                                        | Standard Mode<br>(Max) | Fast Mode<br>(Max)    | Fast Mode Plus<br>(Max) | Unit |
|------------------|------------------------------------------------------------------------|------------------------|-----------------------|-------------------------|------|
| f <sub>SCL</sub> | SCL clock frequency                                                    | 100                    | 400                   | 1000                    | kHz  |
| t <sub>r</sub>   | Rise time of both SDA and SCL signals                                  | 1000                   | 300                   | 120                     | ns   |
| C <sub>b</sub>   | Capacitive load for each bus line                                      | 400                    | 400                   | 550                     | pF   |
| V <sub>OL</sub>  | Low-level output voltage (at 3-mA current sink, V <sub>DD</sub> > 2 V) | 0.4                    | 0.4                   | 0.4                     | V    |
|                  | Low-level output voltage (at 2-mA current sink, V <sub>DD</sub> ≤ 2 V) | –                      | 0.2 × V <sub>DD</sub> | 0.2 × V <sub>DD</sub>   | V    |

For additional background regarding I2C pullup resistor calculations, please refer to application report, [I2C Bus Pullup Resistor Calculation](#).

### 9.3.12 Digital Core

Figure 9-41 shows a simplified block diagram of the digital core.

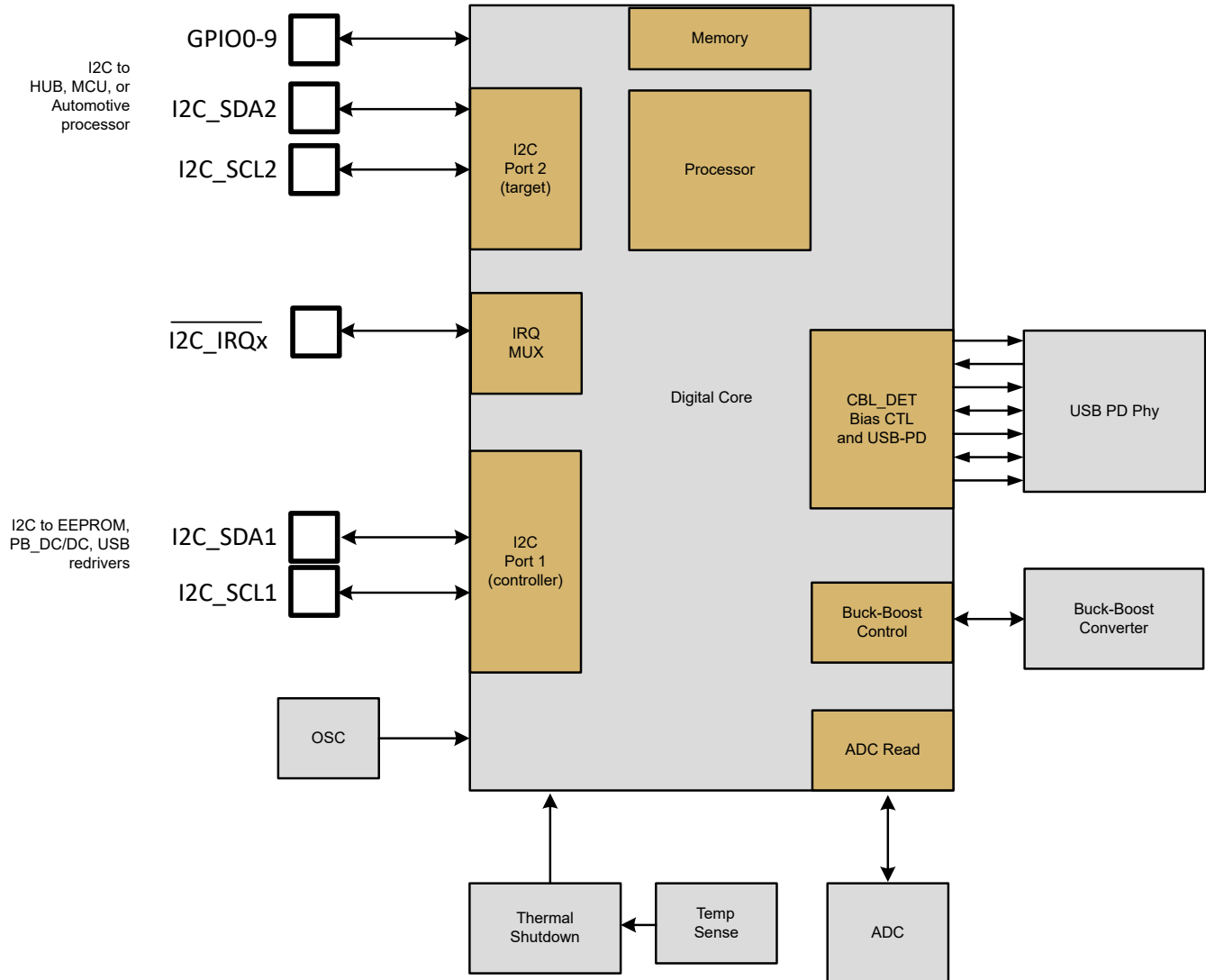


図 9-41. Digital Core Simplified Block Diagram

### 9.3.12.1 Device Memory

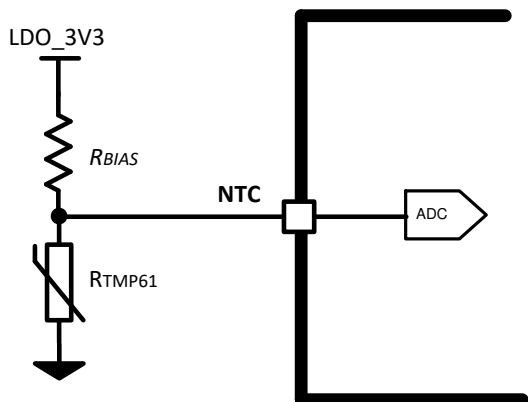
The digital core contains a combination of ROM, SRAM, and OTP. ROM and SRAM function as the storage and operational space for application firmware. OTP contains boot configuration settings. There are 27 kBytes of SRAM, 160 kBytes of ROM, and 512 bytes of OTP.

### 9.3.12.2 Core Microprocessor

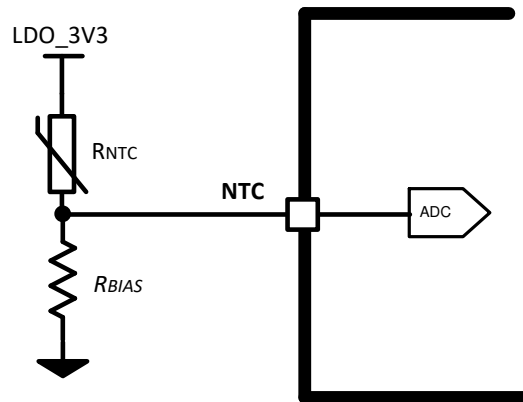
The digital core is an ARM M0+ clocked at 24MHz with zero wait states.

### 9.3.13 NTC Input

The NTC pin is used by the device firmware to monitor system temperature. Rising or falling voltages on the NTC pin indicate increasing or decreasing system temperatures, respectively. To achieve a positive temperature slope on the TPS25772-Q1 NTC pin, thermistors should be connected to LDO\_3V3 as shown in 図 9-42.



(a) TI TMP61 Sensor



(b) NTC Connection

図 9-42. Thermistor Connections (a) PTC, (b) NTC

See 図 9-43 and 図 9-44. Using the application configuration GUI, the user can configure system power policy management responses for up to three  $V_{NTC}$  voltages.

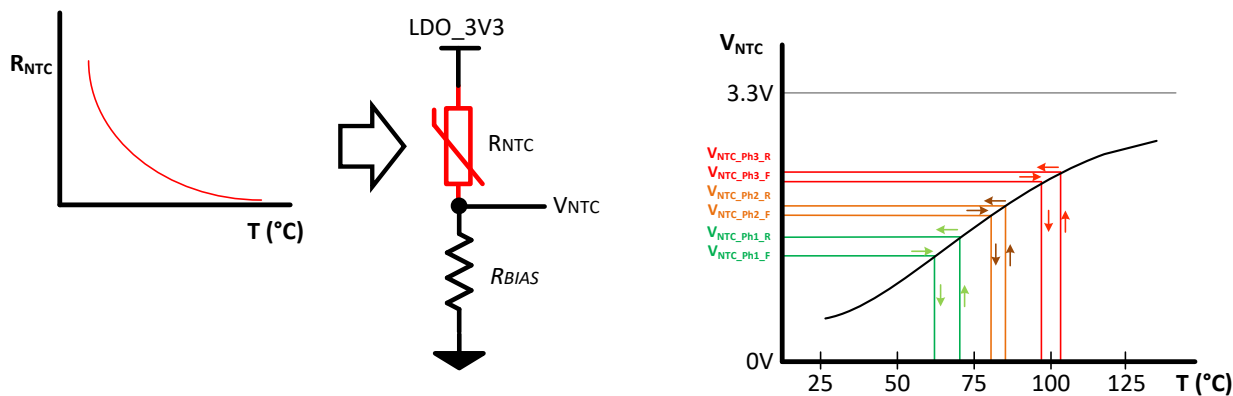


図 9-43. NTC Response Curve

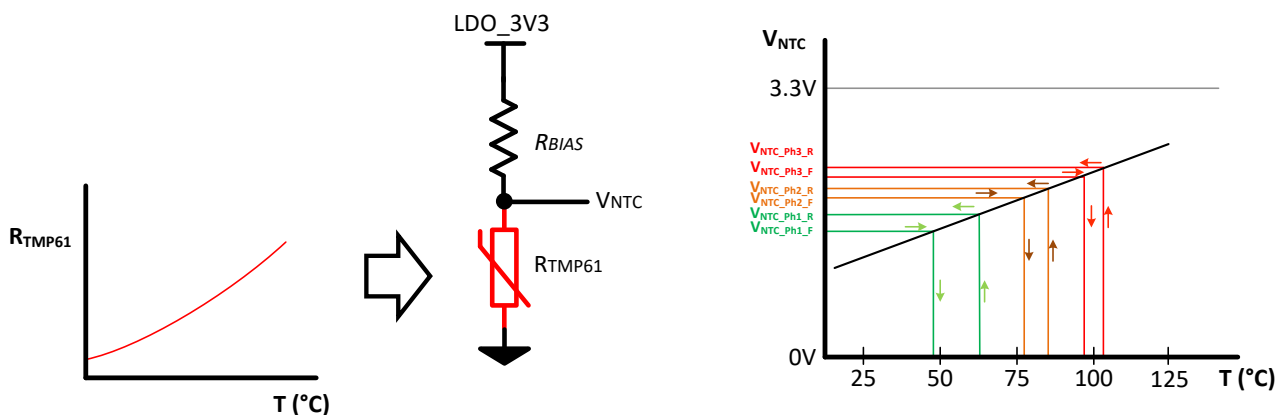


図 9-44. TMP61 PTC Response Curve

## 注

For optimum accuracy, use the  $V_{LDO\_3V3}$  specifications in *Electrical Characteristics* tables when performing resistor divider calculations.

### 9.3.14 Thermal Sensors and Thermal Shutdown

There are five internal thermal sensors in the TPS25772-Q1 devices:

- $T_{SD\_BB}$ . Two diode OR'ed thermal sensors to monitor buck-boost power FETs. Disables buck-boost regulator when asserted. USB-PD engine enters error recovery.
- $T_{SD\_PA\_VCONN}$ . One thermal sensor located in the PA\_VCONN path. Opens PA\_VCONN FET during over-temperature event. USB-PD engine enters error recovery.
- $T_{SD\_PB\_VCONN}$ . Applicable to dual port devices. One thermal sensor located in the PB\_VCONN path. Opens PB\_VCONN FET during over-temperature event. USB-PD engine enters error recovery.
- $T_{SD\_PA\_VBUS\_DISCH}$ . One thermal sensor located in the PA\_VBUS discharge path. Opens PA\_VBUS discharge FET during over-temperature. Closes PA\_VBUS discharge FET when temperature decreases below falling hysteresis. ( $T_{SD\_HYS}$ ) if PA\_VBUS is above discharge threshold set by firmware during decreasing VBUS transition.
- $T_{SD\_LDO5V}$ . One thermal sensor located in the LDO\_5V regulator. Operates as master thermal shutdown. Disables device completely during over-temperature events causing M0 to hard reset. Allows device operation when temperature decreases below falling hysteresis ( $T_{SD\_HYS}$ ).

## 9.4 Device Functional Modes

### Shutdown Mode

The EN/UVLO pin provides electrical ON and OFF control for the TPS25772-Q1. When  $V_{EN/UVLO}$  is below 1.15 V (typ), the device is in shutdown mode in which the Cortex M0 is disabled and only minimal analog functions are operating. Refer to [VIN UVLO and Enable/UVLO](#) section for the detailed description of the EN/UVLO pin functionality.

### Active Mode

The TPS25772-Q1 enters active mode when  $V_{EN/UVLO}$  is above its rising threshold,  $V_{EN(OPER)}$ , and the supply voltage on the IN pin is above the  $V_{IN}$  undervoltage lockout threshold,  $V_{IN(UVLO\_R)}$ . In active mode, the internal analog circuits are fully operational with the M0 enabled and executing firmware from ROM.

At the onset of active mode, firmware boot code will attempt to measure the resistance on the TVSP pin and decode a TVSP Index value. Upon successful configuration and firmware patch load, the device is ready to begin operation per configuration settings stored on the external EEPROM. If the configuration and patch data do not load successfully due to communications error the device will continue to operate with only Port A enabled with standard Type-C functionality. Index value 8 is reserved for use when updating device configuration and firmware patch information through the TPS25772-Q1 GUI and Port A connection. Once device boot is complete, device firmware will control and manage USB connections in accordance with loaded application configuration settings.

## 10 Application and Implementation

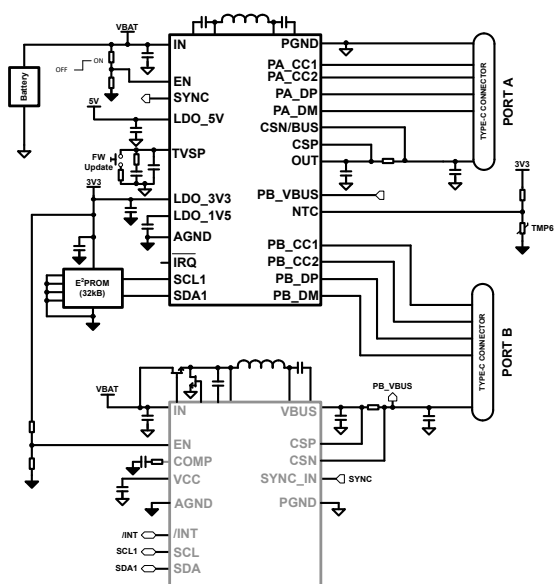
注

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## 10.1 Application Information

The TPS25772-Q1 application GUI provides default settings suitable for most applications.

The most common implementations are dual port USB PD charger and dual port USB PD with USB HUB. Consult the [TPS2576x](#), [TPS2577x Configuration GUI User's Guide](#) and application [GUI](#) for additional configurations.



### 10-1. Simplified Dual USB PD Charger

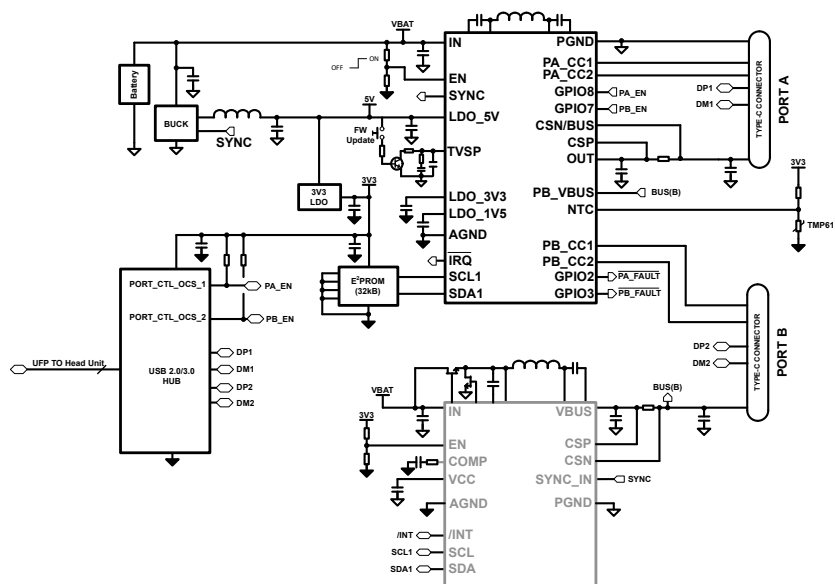


Figure 10-2. Simplified Dual USB PD with HUB

*Typical Application* describes a detailed step-by-step design procedure for a typical charger application circuit.

## 10.2 Typical Application

Figure 10-3 Shows a typical example of a 65 W output automotive USB Type-C Power Delivery port. The device is internally compensated and optimized for components shown in Table 10-1.

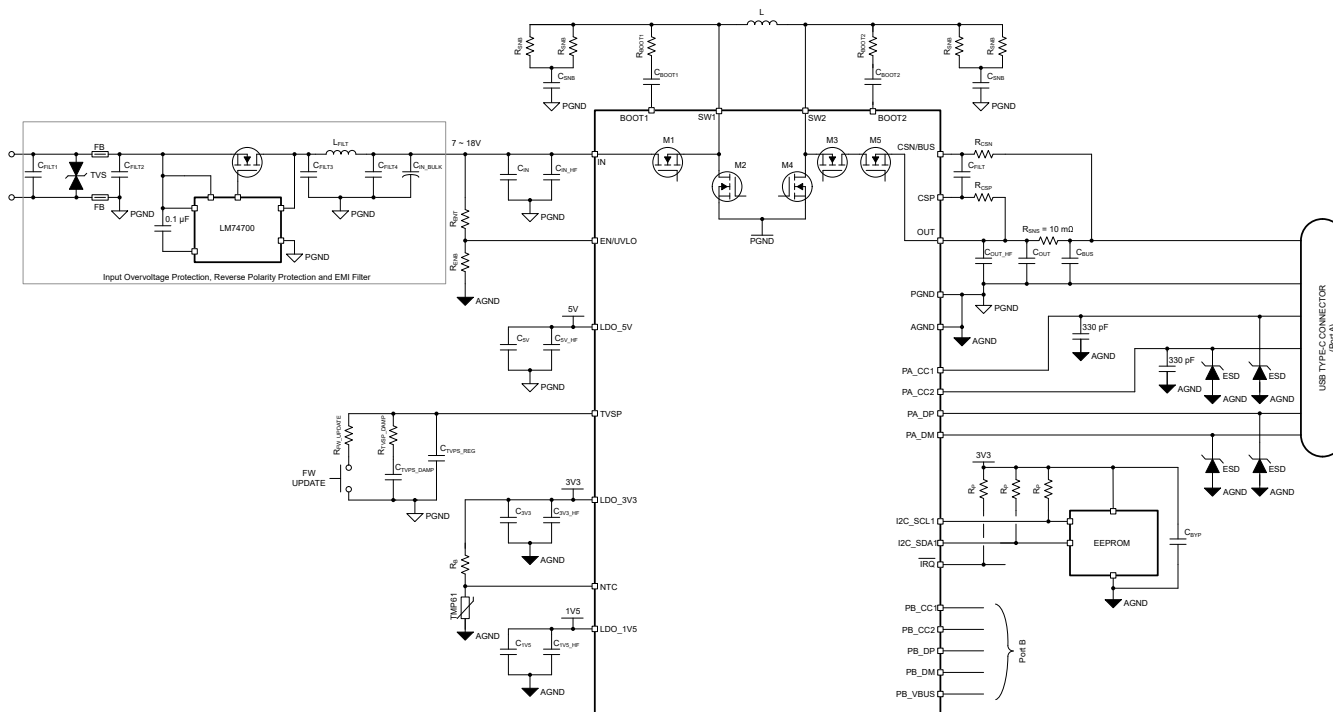
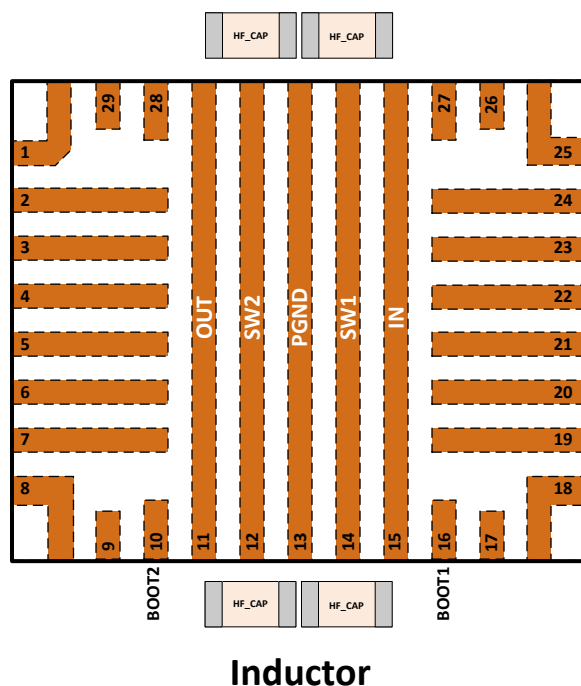


Figure 10-3. TPS25772-Q1 Application Schematic

**表 10-1. Recommended Inductors, Input and Output Capacitance**

| $f_{sw}$ | $C_{IN} + C_{HF}$                 | L           | MIN of $C_{OUT} + C_{BUS}$ | $C_{OUT} + C_{HF}$                | $C_{BUS}$                          |
|----------|-----------------------------------|-------------|----------------------------|-----------------------------------|------------------------------------|
| 300      | $22\ \mu F + 2 \times 0.1\ \mu F$ | 4.7 $\mu H$ | 160 $\mu F$                | $30\ \mu F + 2 \times 0.1\ \mu F$ | $130\ \mu F + 2 \times 0.1\ \mu F$ |
| 400      | $22\ \mu F + 2 \times 0.1\ \mu F$ | 4.7 $\mu H$ | 120 $\mu F$                | $30\ \mu F + 2 \times 0.1\ \mu F$ | $90\ \mu F + 2 \times 0.1\ \mu F$  |
| 400      | $22\ \mu F + 2 \times 0.1\ \mu F$ | 3.3 $\mu H$ | 140 $\mu F$                | $30\ \mu F + 2 \times 0.1\ \mu F$ | $110\ \mu F + 2 \times 0.1\ \mu F$ |
| 450      | $22\ \mu F + 2 \times 0.1\ \mu F$ | 3.3 $\mu H$ | 140 $\mu F$                | $30\ \mu F + 2 \times 0.1\ \mu F$ | $110\ \mu F + 2 \times 0.1\ \mu F$ |

- 50 V rated capacitors recommended.



**図 10-4. Input and Output  $C_{HF}$  Capacitor Placement**

To ensure adequate decoupling of  $V_{IN}$  and  $V_{OUT}$  and robust device operation, use two 0.1  $\mu F$ ,  $C_{HF}$  capacitors per node, placed on opposite sides of the IC package, as close to the pins as possible. Typically, the inductor is placed on the same PCB layer (top or bottom) as the IC package. The  $C_{HF}$  capacitors on the inductor end of the IC package may be placed on the opposite side of the PCB (bottom or top) using vias to minimize trace length from the inductor side IN and OUT pins to the physical location of these capacitors.

**表 10-2. Recommended SWx Snubber and Current Sense Filter Components**

| SW1 <sup>(1)</sup>                  |                  | SW2 <sup>(2)</sup>                  |                  | CSP & CSN Filter <sup>(3)</sup> |                   |                  |
|-------------------------------------|------------------|-------------------------------------|------------------|---------------------------------|-------------------|------------------|
| $R_{SNB}$ (0.25 W)                  | $C_{SNB}$ (50 V) | $R_{SNB}$ (0.25 W)                  | $C_{SNB}$ (50 V) | $R_{CSP}$ (0.1 W)               | $R_{CSN}$ (0.1 W) | $C_{FLT}$ (50 V) |
| $2.2\ \Omega \parallel 2.2\ \Omega$ | 1 nF             | $2.2\ \Omega \parallel 2.2\ \Omega$ | 3.3 nF           | 10 $\Omega$                     | 0 $\Omega$        | 0.22 $\mu F$     |

1. As needed for EMI mitigation - user optional. (Use of this snubber can also aid in supporting devices with high initial inrush load current that exceeds the power delivery specification.)
2. **Required** for robust device operation.
3. **Required** to meet USB-IF current regulation requirements.

### 10.2.1 Design Requirements

For this example, 表 10-3 are used as the target parameters.

**表 10-3. Design Inputs**

| DESIGN PARAMETER                  | EXAMPLE VALUE                                                             |
|-----------------------------------|---------------------------------------------------------------------------|
| Input Voltage Range               | 6.8 V to 18 V (transients to 36 V)                                        |
| UVLO Turn on Voltage              | 6.5 V                                                                     |
| USB PD Power                      | 65 W                                                                      |
| USB PD $V_{BUS}$ Voltages         | 5 V, 9 V, 15 V, 20 V and 3.3 to 21 V (PPS)                                |
| Output                            | 3.3 - 21 V                                                                |
| Load Current                      | PDO: 5 V, 3 A; 9 V, 3 A; 15 V, 3 A, 20 V, 3.25 A<br>APDO: 3.3 - 21 V, 3 A |
| Switching Frequency               | 400 kHz                                                                   |
| $V_{CONN}$                        | 0.1 W                                                                     |
| Automotive Module Maximum Current | 15 A                                                                      |

## 10.2.2 Detailed Design Procedure

### 10.2.2.1 Application GUI Selections

Use the application GUI to select the desired operating conditions. Once complete, save the settings to the programming PC, flash the firmware to EEPROM, and power cycle device. Once complete the TPS25772-Q1 will be ready for operation.

**表 10-4. Application GUI Selections**

| PARAMETER                             | GUI SELECTION                                                            |
|---------------------------------------|--------------------------------------------------------------------------|
| <b>BUCK-BOOST AND USB INPUTS</b>      |                                                                          |
| Port A $V_{BUS}$ Power                | 65 W                                                                     |
| Port A PDOs and APDOs                 | PDO: 5 V, 3 A; 9 V, 3 A; 15 V, 3 A; 20 V, 3.25 A<br>APDO: 3.3 - 21 V, 3A |
| Port A $V_{CONN}$ Power               | 0.1 W                                                                    |
| $f_{SW}$ Switching Frequency          | 400 kHz                                                                  |
| L Inductor                            | 4.7 $\mu$ H                                                              |
| Automotive Module Maximum Current     | 15 A                                                                     |
| <b>LOW BATTERY INPUTS</b>             |                                                                          |
| Engine ON voltage                     | 12.5 V                                                                   |
| Engine OFF voltage                    | 11 V                                                                     |
| Run timer after engine off            | 600 seconds                                                              |
| <b>THERMAL MANAGEMENT INPUTS</b>      |                                                                          |
| $V_{NTC\_PHASE1}$                     | 1.65 V                                                                   |
| NTC_PHASE1 Power as Percentage of MAX | 50 %                                                                     |
| $V_{NTC\_PHASE2}$                     | 2.1 V                                                                    |
| NTC_PHASE2 Power as Percentage of MAX | 30 %                                                                     |
| $V_{NTC\_PHASE3}$                     | 2.4 V                                                                    |
| NTC_PHASE3 Power as Percentage of MAX | 0 % (disable PA_VBUS)                                                    |

#### 10.2.2.2 EEPROM Selection

An EEPROM is required to store user application configuration data as any firmware patch updates released by Texas Instruments during the life of the product.

Basic requirements:

- 32kB (256kb)
- 7 Bit I2C address (0x50)

- Organization: 32kb x 8 (totals 256kb)
- Active firmware image is stored in one 16kb x 8 partition. The previous firmware image is retained in the other 16kb x 8 partition for reliability.
- Page size/buffer should be 64b

**表 10-5. Suggested EEPROMs**

| Manufacturer | Part Number   |
|--------------|---------------|
| On Semi      | CAV24C256     |
| Microchip    | 24LC256       |
| ST Micro     | M24256        |
| Rohm         | BRA24T512=3AM |

### 10.2.2.3 EN/UVLO

The TPS25772-Q1 has a fixed  $V_{IN(UVLO)}$  with rising and falling thresholds between 5 and 5.5 V, refer to [セクション 7.6](#) for exact values. The falling threshold,  $V_{IN(UVLO\_F)}$ , disables the device when the battery voltage is too low for continued operation. To establish a turn on voltage higher than  $V_{IN(UVLO\_R)}$ , connect a resistor divider from the IN supply voltage to the EN/UVLO pin. When  $V_{EN/UVLO} > V_{EN(OPER)}$ , nominally 1.25 V, the device exits low power shutdown and begins to startup.

In this example a  $V_{IN}$  turn on voltage of approximately 6.5 V is required. Use the equations and examples below to determine the required resistor values.

- Choose standard value  $R_{ENB} = 22\text{ k}\Omega$ .
- Calculate  $R_{ENT}$

$$R_{ENT} = \left( \frac{V_{ON}}{V_{EN(OPER)}} - 1 \right) \times R_{ENB} \quad (3)$$

$$R_{ENT} = \left( \frac{6.5\text{ V}}{1.25\text{ V}} - 1 \right) \times 22\text{ k}\Omega = 92.4\text{ k}\Omega \quad (4)$$

- Select a standard value of 91 k $\Omega$ .
- Using 22 k $\Omega$  and 91 k $\Omega$ . Rearranging [式 3](#) results in

$$V_{ON} = \left( \frac{R_{ENT}}{R_{ENB}} + 1 \right) \times V_{EN(OPER)} \quad (5)$$

$$V_{ON} = \left( \frac{91\text{ k}\Omega}{22\text{ k}\Omega} + 1 \right) \times 1.25\text{ V} = 6.42\text{ V} \quad (6)$$

- Calculate  $V_{OFF}$

$$V_{OFF} = \left( 1 - \frac{V_{EN(HYS)}}{V_{EN(OPER)}} \right) \times V_{ON} \quad (7)$$

$$V_{OFF} = \left( 1 - \frac{0.1\text{ V}}{1.25\text{ V}} \right) \times 6.42\text{ V} = 5.91\text{ V} \quad (8)$$

- Lastly, confirm the selected resistors do not trigger the EN/UVLO pin MAX clamp voltage. Assuming 36 V as a maximum  $V_{IN}$  transient.

$$V_{EN/UVLO(MAX)} = \left( \frac{V_{IN(MAX)} \times R_{ENB}}{R_{ENT} + R_{ENB}} \right) \quad (9)$$

$$V_{EN/UVLO(MAX)} = \left( \frac{36\text{ V} \times 22\text{ k}\Omega}{22\text{ k}\Omega + 91\text{ k}\Omega} \right) = 7\text{ V} \quad (10)$$

- The result, 7 V, is less than the EN/UVLO pin maximum clamp voltage.

#### 10.2.2.4 Sense Resistor, $R_{SNS}$ , $R_{CSP}$ , $R_{CSN}$ and $C_{FILT}$

The TPS25772-Q1 requires a 10-mΩ resistance between the CSP and CSN/BUS pins. For accurate current limit regulation, ±1% precision or better is required. For a DC output current of 3.25 A, the power dissipation in the resistor is

$$I^2R, \text{ or } (3.25 \text{ A})^2 \times 0.01 \, \Omega = 0.106 \text{ W.}$$

A power resistor with 0.33-W rating, ± 1% tolerance and 2010 case is chosen. *Check the manufacturers power derating curves when selecting the component. Most derate maximum power above 70°C.*

An RC filter network is required on the CSP and CSN/BUS pins for proper USB PD PPS current limit accuracy. A filter network with  $R_{CSP} = 10 \, \Omega$ ,  $R_{CSN} = 0 \, \Omega$ , and filter capacitor,  $C_{FILT} = 0.22 \, \mu\text{F}$  is recommended. Suggested RC filter component ratings are shown in 表 10-2.  $R_{CSN}$  must be zero ohm to avoid interfering with the  $V_{BUS}$  discharge functionality.

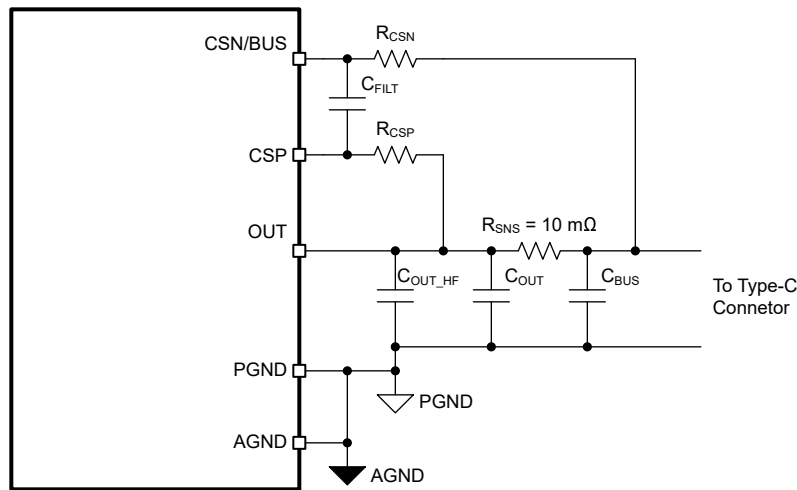


図 10-5. Current Sense Amplifier: RC Filter Components

#### 10.2.2.5 Inductor Currents

表 10-1 lists recommended inductor values based on desired switching frequency,  $f_{SW}$ . The following equations were used to derive the values in the *Buck Calculation* and *Boost Calculation* results tables below.

$$D_{BUCK} = \frac{V_{OUT}}{V_{IN(MAX)} \times \eta} \quad (11)$$

$$D_{BOOST} = 1 - \frac{V_{IN(MIN)} \times \eta}{V_{OUT}} \quad (12)$$

where

- $V_{IN(MAX)}$  = maximum input voltage
- $V_{IN(MIN)}$  = minimum input voltage
- $V_{OUT}$  = output voltage
- $D_{BUCK}$  = minimum duty cycle for buck mode
- $D_{BOOST}$  = maximum duty cycle for boost mode
- $\eta$  = estimated efficiency calculated at  $V_{IN}$ ,  $V_{OUT}$ , and  $I_{OUT}$

Buck Mode

$$I_{SW\_BUCK(MAX)} = \frac{\Delta I_{L\_BUCK(MAX)}}{2} + I_{OUT} \quad (13)$$

$$\Delta I_{L\_BUCK(MAX)} = \frac{(V_{IN(MAX)} - V_{OUT(MIN)}) \times D_{BUCK}}{f_{SW} \times L} \quad (14)$$

where

- $V_{IN(MAX)}$  = maximum input voltage
- $V_{OUT(MIN)}$  = minimum output voltage
- $I_{OUT}$  = maximum DC output current
- $\Delta I_{L\_BUCK(MAX)}$  = maximum ripple current through the inductor when in buck operation
- $I_{SW\_BUCK(MAX)}$  = maximum switch current when in buck operation
- $D_{BUCK}$  = minimum duty cycle for buck operation
- $f_{SW}$  = switching frequency of the converter
- $L$  = selected inductor value

$$I_{MAXOUT(BUCK)} = I_{PEAK(BUCK)} - \frac{\Delta I_{L\_BUCK(MAX)}}{2} \quad (15)$$

where

- $I_{MAXOUT(BUCK)}$  = maximum deliverable current through inductor by the converter
- $I_{PEAK(BUCK)}$  = buck switch peak current limit from *Electrical Characteristics* table
- $\Delta I_{L\_BUCK(MAX)}$  = Ripple current through the inductor calculated in 式 14.

Boost Mode

$$I_{SW\_BOOST(MAX)} = \frac{\Delta I_{L\_BOOST(MAX)}}{2} + \frac{I_{OUT}}{1 - D_{BOOST}} \quad (16)$$

$$\Delta I_{L\_BOOST(MAX)} = \frac{V_{IN(MIN)} \times D_{BOOST}}{f_{SW} \times L} \quad (17)$$

where

- $V_{IN(MIN)}$  = minimum input voltage
- $V_{OUT(MAX)}$  = desired output voltage
- $I_{OUT}$  = desired output current
- $\Delta I_{L\_BOOST(MAX)}$  = maximum ripple current through the inductor in boost operation
- $I_{SW\_BOOST(MAX)}$  = maximum switch current in boost operation
- $D_{BOOST}$  = maximum duty cycle for boost operation
- $f_{SW}$  = switching frequency of the converter
- $L$  = selected inductor value

$$I_{MAXOUT(BOOST)} = \left( I_{PEAK(BOOST)} - \frac{\Delta I_{L\_BOOST(MAX)}}{2} \right) \times (1 - D_{BOOST}) \quad (18)$$

where

- $I_{MAXOUT(BOOST)}$  = maximum deliverable current through inductor by the converter
- $D_{BOOST}$  = maximum duty cycle for boost mode
- $I_{PEAK(BOOST)}$  = boost switch peak current limit from *Electrical Characteristics* table
- $\Delta I_{L\_MAX(BOOST)}$  = Ripple current through the inductor calculated in 式 17.

### Buck Operation

表 10-6 provides the tabulated  $\Delta I_{L\_BUCK(MAX)}$  and  $I_{SW\_BUCK(MAX)}$  for the conditions below.

- $\eta = 0.95$
- $V_{IN(MAX)} = 18\text{ V}$
- $V_{OUT(MIN)} = 3.3\text{ V}$
- $D_{BUCK(MIN)} = 0.193$

**表 10-6. Buck Calculation Results ( $L = 4.7\text{ }\mu\text{H}$ ),  $I_{BUS} = 3\text{ A}$**

| $f_{sw}$<br>(kHz) | $I_{OUT}$<br>(A) | $\Delta I_{L\_BUCK(MAX)}$<br>(A) | $I_{SW\_BUCK(MAX)}$<br>(A) |
|-------------------|------------------|----------------------------------|----------------------------|
| 300               | 3.00             | 2.87                             | 4.44                       |
| 400               | 3.00             | 2.15                             | 4.08                       |
| 450               | 3.00             | 1.91                             | 3.96                       |
| 300               | 3.00             | 2.01                             | 4.01                       |
| 400               | 3.00             | 1.51                             | 3.76                       |
| 450               | 3.00             | 1.34                             | 3.67                       |

### Boost Operation

表 10-7 provides the tabulated  $\Delta I_{L\_BOOST(MAX)}$ ,  $I_{SW\_BOOST(MAX)}$ , suggested GUI  $I_{PEAK(BOOST)}$  (MIN) settings for the maximum output power conditions shown below.

If  $I_{SW\_BOOST(MAX)} > I_{PEAK(BOOST)} \text{ (MIN)} \rightarrow V_{BUS}$  dropout likely.

If  $I_{SW\_BOOST(MAX)} < I_{PEAK(BOOST)} \text{ (MIN)} \rightarrow V_{BUS}$  regulates normally.

- $\eta = 0.95$
- $V_{IN(MIN)} = 5.5\text{ V to }9\text{ V}$
- $V_{OUT(MAX)} = 21\text{ V}$
- $I_{OUT} = 3\text{ A}$

To be noted, the calculation here uses 21V 3 A instead of 20 V 3.25A because 21 V 3A has bigger inductor peak current.

**表 10-7. Boost Calculation Results ( $L = 4.7\text{ }\mu\text{H}$ ),  $I_{BUS} = 3\text{ A}$**

| $f_{sw}$<br>(kHz) | $V_{IN(MIN)}$<br>(V) | $D_{BOOST(MAX)}$ | $\Delta I_{L\_BOOST(MAX)}$<br>(A) | $I_{SW\_BOOST(MAX)}$<br>(A) | GUI <sup>(1)</sup><br>$I_{PEAK(BOOST)}$<br>(A) |
|-------------------|----------------------|------------------|-----------------------------------|-----------------------------|------------------------------------------------|
| 300               | 5.5                  | 0.751            | 2.93                              | 13.51                       | 12.3                                           |
|                   | 6                    | 0.729            | 3.10                              | 12.62                       | 12.3                                           |
|                   | 6.5                  | 0.706            | 3.25                              | 11.83                       | 12.3                                           |
|                   | 7                    | 0.683            | 3.39                              | 11.16                       | 12.3                                           |
|                   | 7.5                  | 0.661            | 3.52                              | 10.61                       | 10.8                                           |
|                   | 8                    | 0.638            | 3.62                              | 10.10                       | 10.8                                           |
|                   | 8.5                  | 0.615            | 3.71                              | 9.65                        | 10.8                                           |
|                   | 9                    | 0.593            | 3.79                              | 9.27                        | 9.3                                            |

**表 10-7. Boost Calculation Results (L = 4.7 μH), I<sub>BUS</sub> = 3 A (続き)**

| f <sub>sw</sub><br>(kHz) | V <sub>IN(MIN)</sub><br>(V) | D <sub>BOOST(MAX)</sub> | ΔI <sub>L_BOOST(MAX)</sub><br>(A) | I <sub>SW_BOOST(MAX)</sub><br>(A) | GUI <sup>(1)</sup><br>I <sub>PEAK(BOOST)</sub><br>(A) |
|--------------------------|-----------------------------|-------------------------|-----------------------------------|-----------------------------------|-------------------------------------------------------|
| 400                      | 5.5                         | 0.751                   | 2.20                              | 13.15                             | 12.3                                                  |
|                          | 6                           | 0.729                   | 2.33                              | 12.24                             | 12.3                                                  |
|                          | 6.5                         | 0.706                   | 2.44                              | 11.42                             | 12.3                                                  |
|                          | 7                           | 0.683                   | 2.54                              | 10.73                             | 10.8                                                  |
|                          | 7.5                         | 0.661                   | 2.64                              | 10.17                             | 10.8                                                  |
|                          | 8                           | 0.638                   | 2.71                              | 9.64                              | 10.8                                                  |
|                          | 8.5                         | 0.615                   | 2.78                              | 9.18                              | 9.3                                                   |
|                          | 9                           | 0.593                   | 2.84                              | 8.79                              | 9.3                                                   |
| 450                      | 5.5                         | 0.751                   | 1.95                              | 13.02                             | 12.3                                                  |
|                          | 6                           | 0.729                   | 2.07                              | 12.11                             | 12.3                                                  |
|                          | 6.5                         | 0.706                   | 2.17                              | 11.29                             | 12.3                                                  |
|                          | 7                           | 0.683                   | 2.26                              | 10.59                             | 10.8                                                  |
|                          | 7.5                         | 0.661                   | 2.34                              | 10.02                             | 10.8                                                  |
|                          | 8                           | 0.638                   | 2.41                              | 9.49                              | 9.3                                                   |
|                          | 8.5                         | 0.615                   | 2.47                              | 9.03                              | 9.3                                                   |
|                          | 9                           | 0.593                   | 2.51                              | 8.63                              | 9.3                                                   |

(1) MIN value of boost peak ILIM shown. See electrical characteristics table for MIN, TYP, MAX values.

### 10.2.2.6 Output Capacitor

In the boost mode, the output capacitor conducts high ripple current. The output capacitor RMS ripple current is given by 式 19 where the minimum V<sub>IN</sub> corresponds to the maximum capacitor current.

$$I_{\text{COUT(RMS)}} = I_{\text{OUT}} \times \sqrt{\frac{V_{\text{OUT}}}{V_{\text{IN}}} - 1} \quad (19)$$

In this example the maximum output ripple RMS current is I<sub>COUT(RMS)</sub> = 3.18 A. A 5-mΩ output capacitor ESR causes an output ripple voltage of 34 mV as given by:

$$\Delta V_{\text{RIPPLE(ESR)}} = \frac{I_{\text{OUT}} \times V_{\text{OUT}}}{V_{\text{IN(MIN)}}} \times \text{ESR} \quad (20)$$

A 140 μF output capacitor (C<sub>OUT</sub> + C<sub>BUS</sub>) causes a capacitive ripple voltage of 26 mV as given by:

$$\Delta V_{\text{RIPPLE(COUT)}} = \frac{I_{\text{OUT}} \times \left(1 - \frac{V_{\text{IN(MIN)}}}{V_{\text{OUT}}}\right)}{C_{\text{OUT}} \times F_{\text{sw}}} \quad (21)$$

Typically a combination of ceramic and bulk capacitors is needed to provide low ESR and high ripple current capacity. The complete schematic in [Typical Application](#) section provides C<sub>OUT</sub> and C<sub>BUS</sub> recommendations suitable for most applications.

### 10.2.2.7 Input Capacitor

In the buck mode, the input capacitor supplies high ripple current. The RMS current in the input capacitor is given by:

$$I_{CIN(RMS)} = I_{OUT} \sqrt{D \times (1-D)} \quad (22)$$

The maximum RMS current occurs at  $D = 0.5$ , which gives  $I_{CIN(RMS)} = I_{OUT}/2 = 1.5$  A. A combination of ceramic and bulk capacitors should be used to provide short path for high di/dt current and to reduce the output voltage ripple. 表 10-1 in the *Typical Application* section is a good starting point for  $C_{IN}$  selection.

## 10.2.3 Application Curves

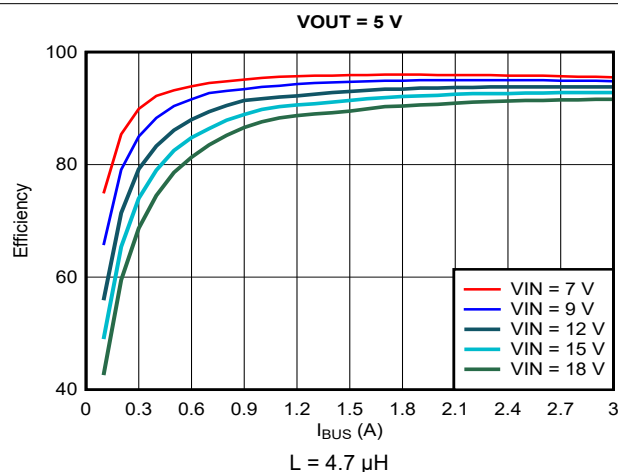


FIG 10-6. Efficiency vs Output Current ( $I_{OUT}$ ),  $V_{OUT} = 5 V$

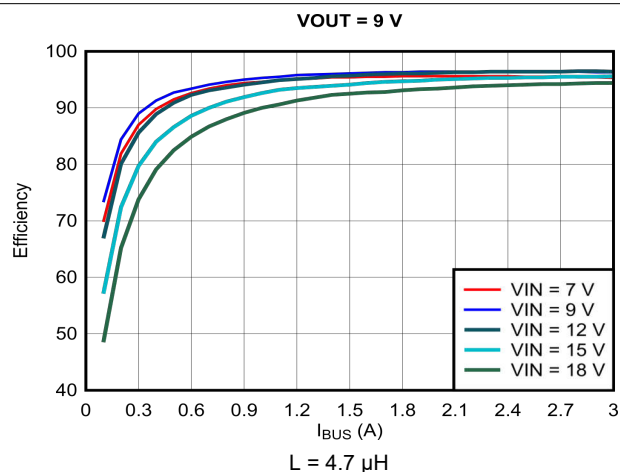


FIG 10-7. Efficiency vs Output Current ( $I_{OUT}$ ),  $V_{OUT} = 9 V$

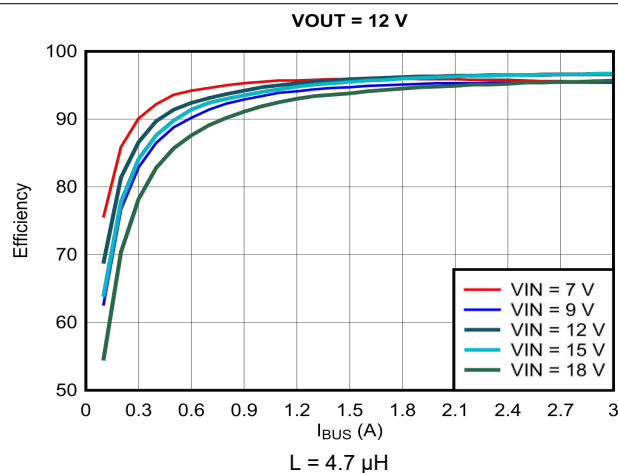


FIG 10-8. Efficiency vs Output Current ( $I_{OUT}$ ),  $V_{OUT} = 12 V$

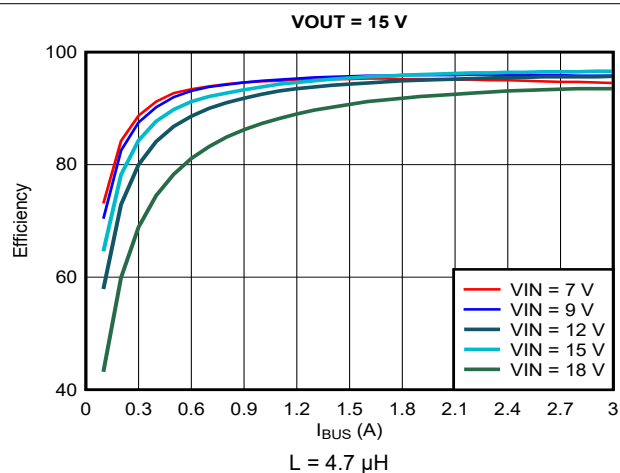


FIG 10-9. Efficiency vs Output Current ( $I_{OUT}$ ),  $V_{OUT} = 15 V$

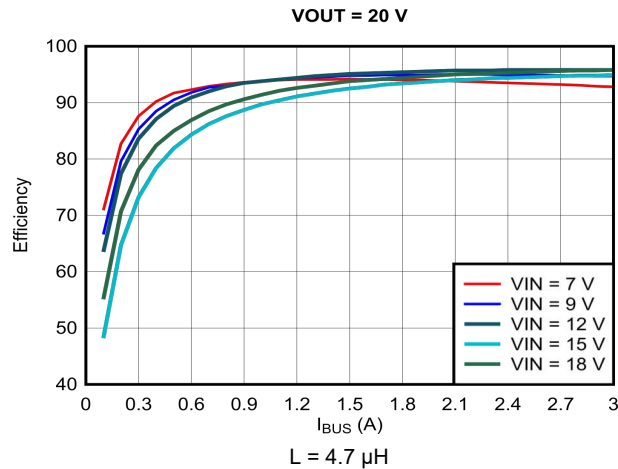


Figure 10-10. Efficiency vs Output Current ( $I_{OUT}$ ),  $V_{OUT} = 20 V$

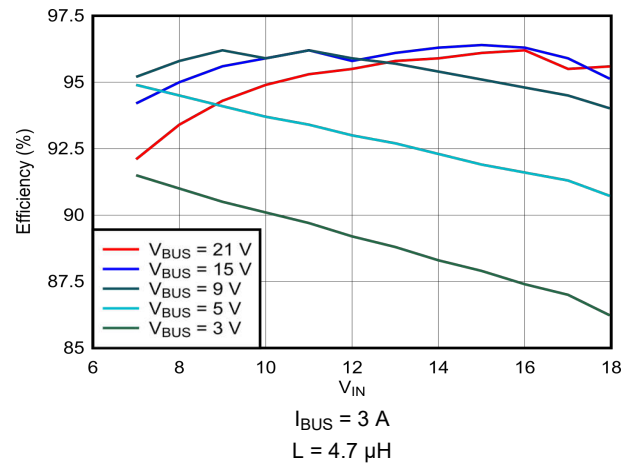


Figure 10-11. Efficiency vs Input Voltage

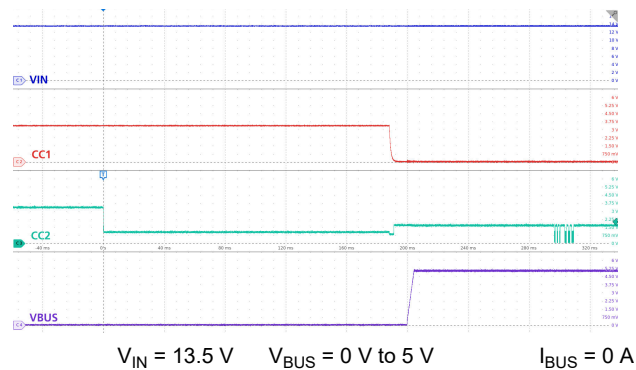


Figure 10-12. Type-C Attach

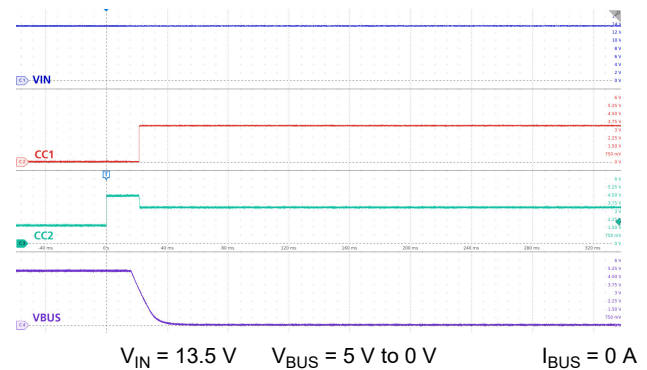
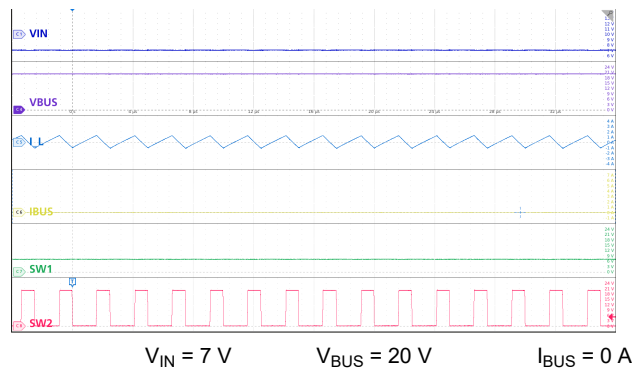
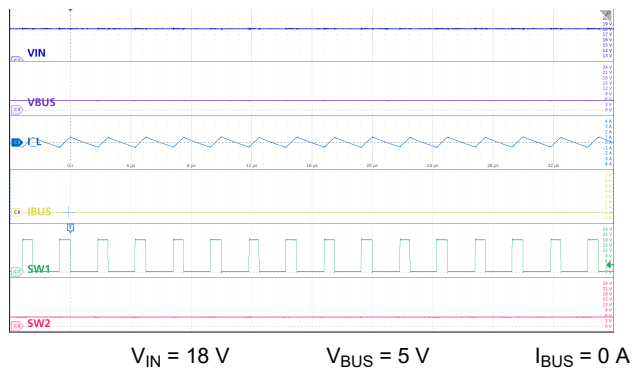


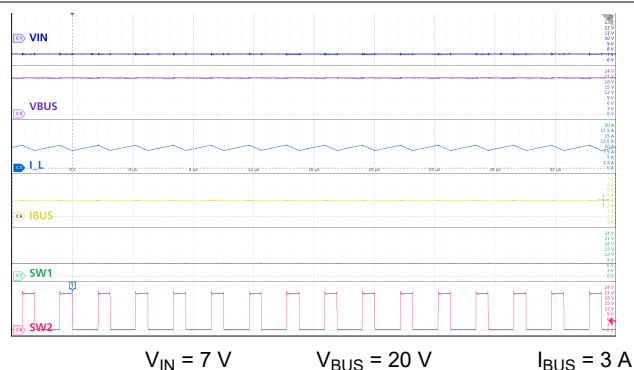
Figure 10-13. Type-C Detach



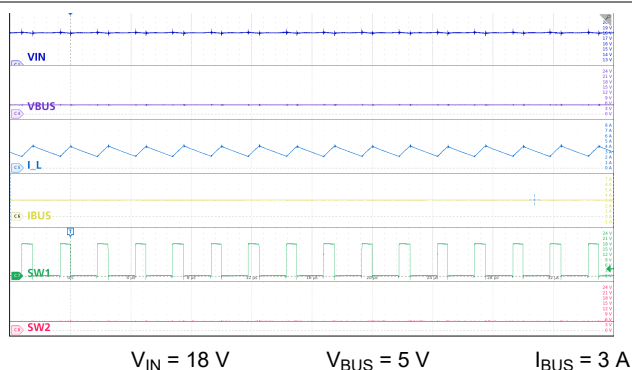
10-14. Boost Mode: Low  $V_{IN}$ , No Load



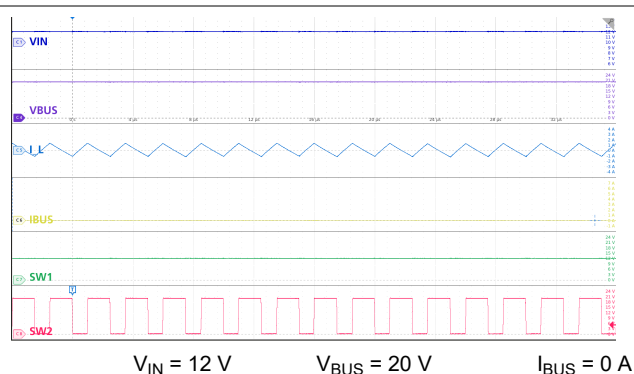
10-15. Buck Mode: High  $V_{IN}$ , No Load



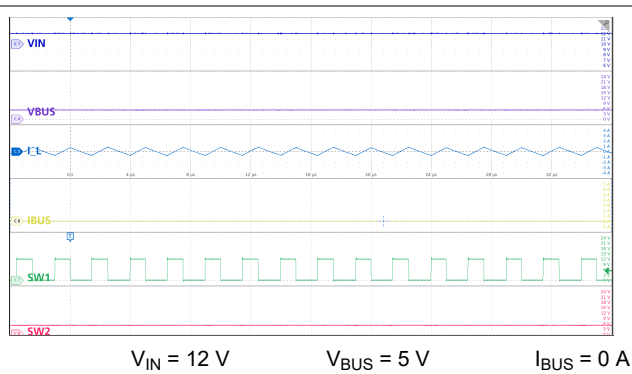
10-16. Boost Mode: Low  $V_{IN}$ , 3 A Load



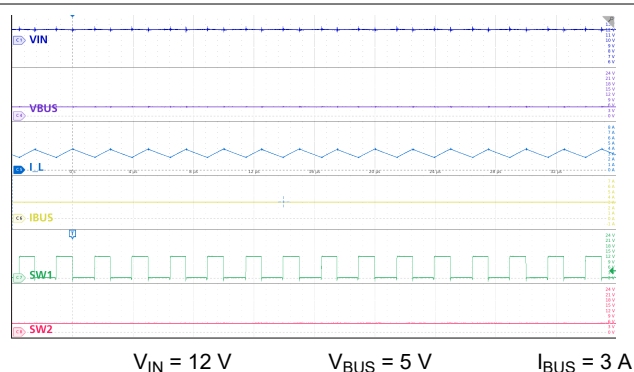
10-17. Buck Mode: High  $V_{IN}$ , 3 A load



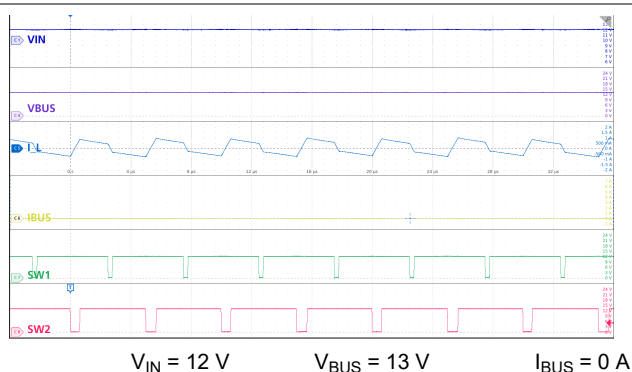
10-18. Boost Mode: Nominal  $V_{IN}$ , No Load



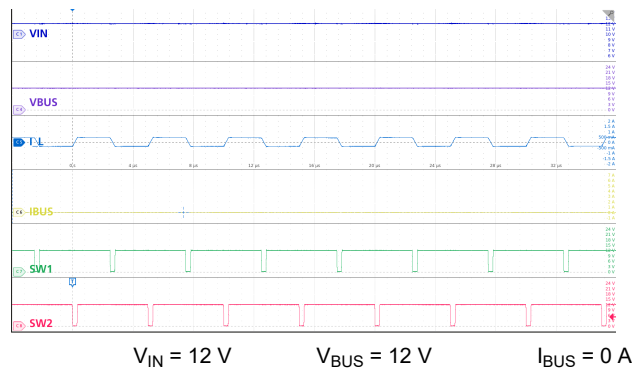
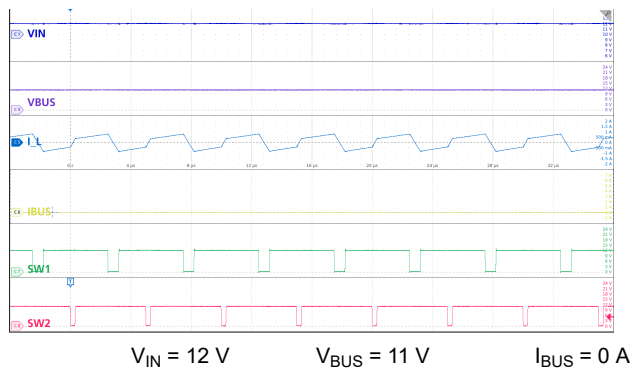
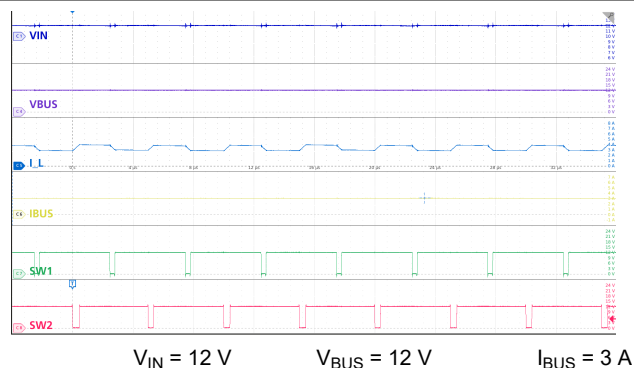
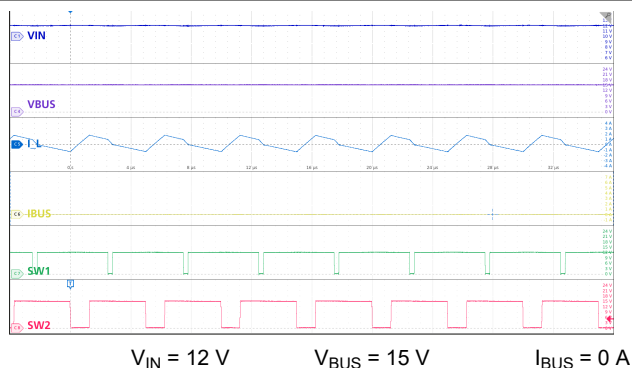
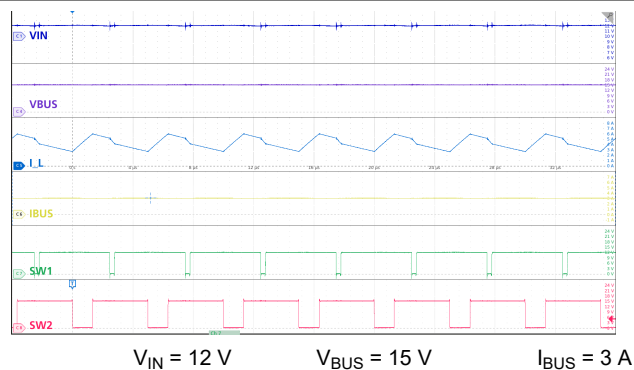
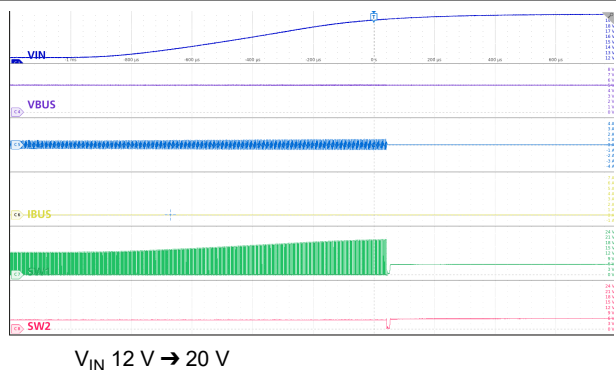
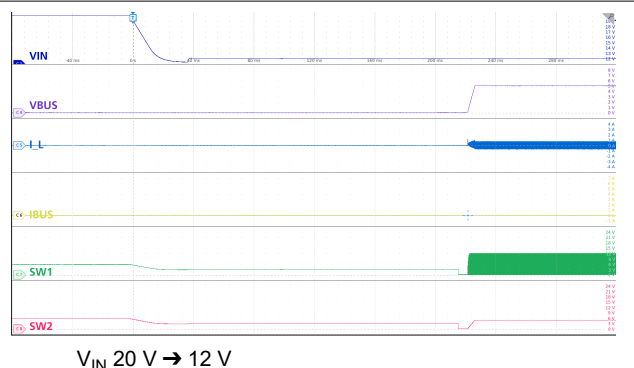
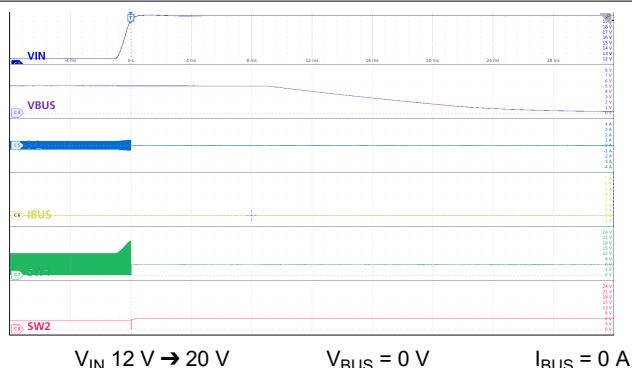
10-19. Buck Mode: Nominal  $V_{IN}$ , No Load



10-20. Buck Mode: nominal  $V_{IN}$ , 3 A Load



10-21. Buck-Boost Mode:  $V_{IN} \neq V_{BUS}$ , No Load


 **10-22. Buck-Boost Mode:  $V_{IN} = V_{BUS}$ , No Load**

 **10-23. Buck-Boost Mode:  $V_{IN} \neq V_{BUS}$ , No Load**

 **10-24. Buck-Boost Mode:  $V_{IN} = V_{BUS}$ , 3 A Load**

 **10-25. Buck-Boost Mode: Nominal  $V_{IN}$ , No Load**

 **10-26. Buck-Boost Mode: Nominal  $V_{IN}$ , 3 A Load**

 **10-27.  $V_{IN(OVP)}$  Entry**

 **10-28.  $V_{IN(OVP)}$  Recovery**

 **10-29.  $V_{IN(OVP)}$  Showing  $V_{BUS}$  Discharge**

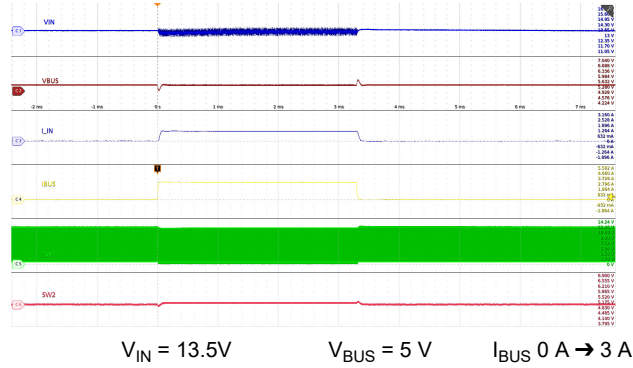


図 10-30. Load Transient (Buck):  $V_{BUS} = 5V$

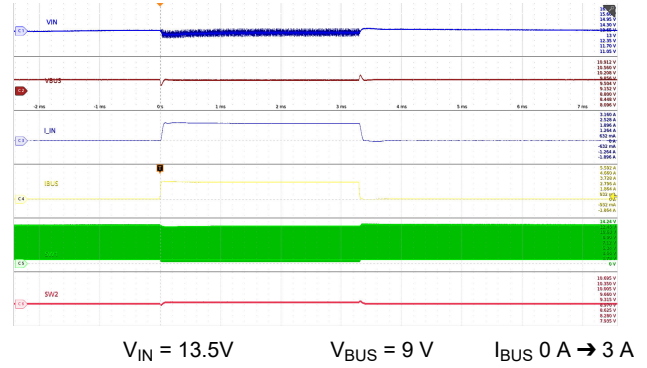


図 10-31. Load Transient (Buck):  $V_{BUS} = 9V$

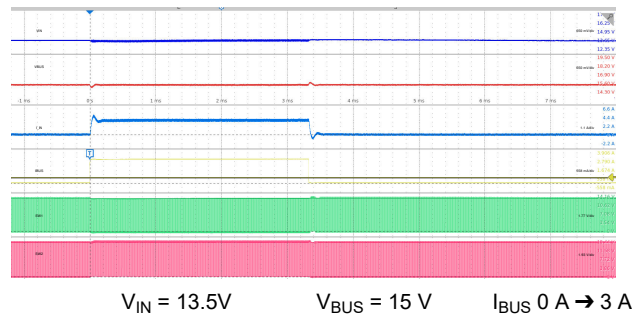


図 10-32. Load Transient (Buck-Boost):  $V_{BUS} = 15V$

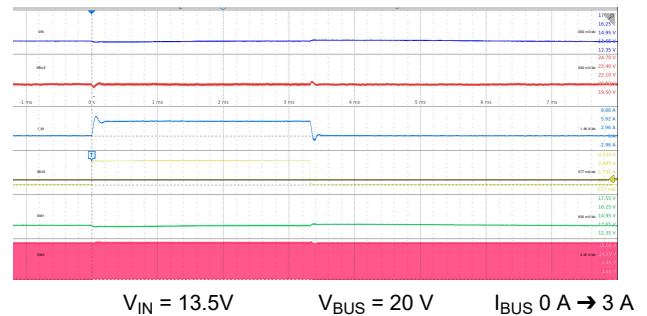


図 10-33. Load Transient (Boost):  $V_{BUS} = 20V$

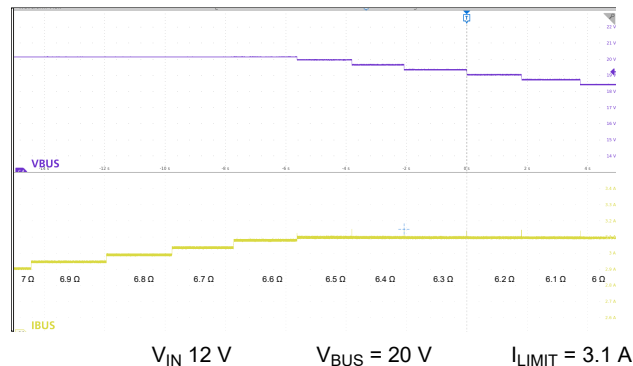


図 10-34. Current Limit: Stepped Resistive Load

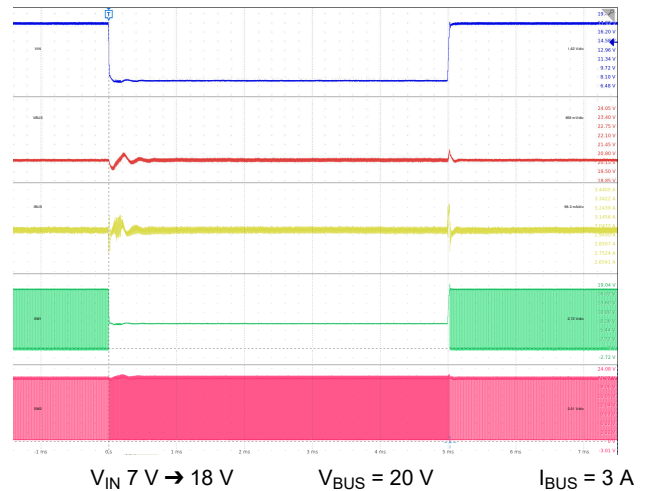
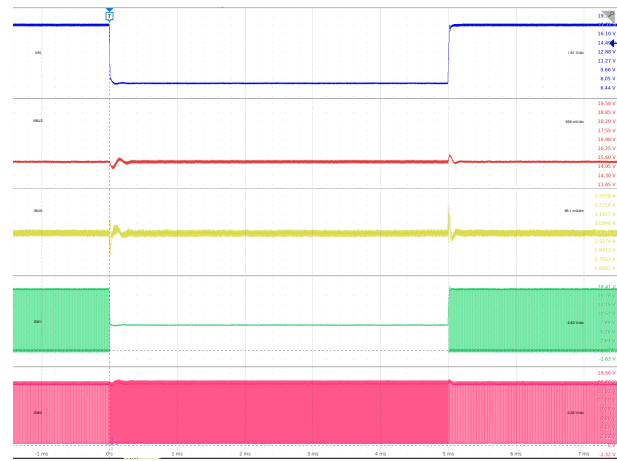
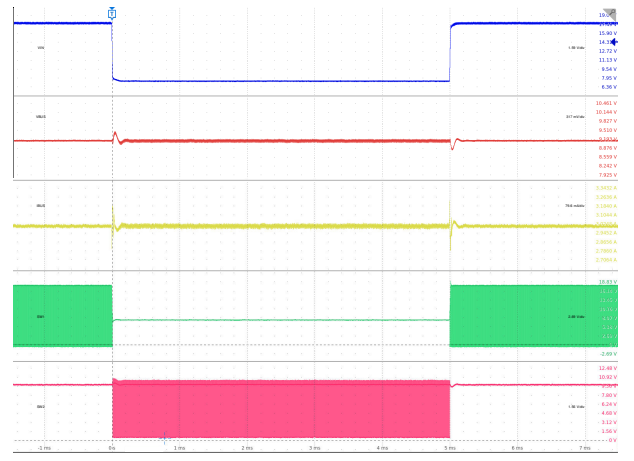
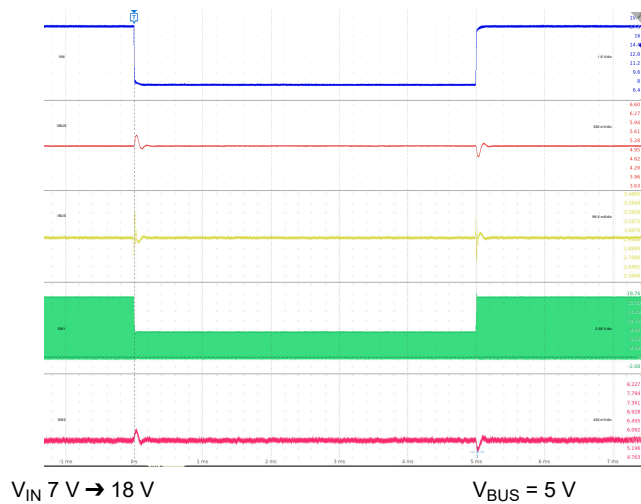


図 10-35. Line Transient:  $V_{BUS} = 20V$


 $V_{IN} 7\text{ V} \rightarrow 18\text{ V}$      $V_{BUS} = 15\text{ V}$      $I_{BUS} = 3\text{ A}$ 
**図 10-36. Line Transient:  $V_{BUS} = 15\text{ V}$** 

 $V_{IN} 7\text{ V} \rightarrow 18\text{ V}$      $V_{BUS} = 9\text{ V}$      $I_{BUS} = 3\text{ A}$ 
**図 10-37. Line Transient:  $V_{BUS} = 9\text{ V}$** 

 $V_{IN} 7\text{ V} \rightarrow 18\text{ V}$      $V_{BUS} = 5\text{ V}$      $I_{BUS} = 3\text{ A}$ 
**図 10-38. Line Transient:  $V_{BUS} = 5\text{ V}$**

## 10.3 Power Supply Recommendations

The TPS25772-Q1 is a power management device typically operated from an automotive battery, though the power supply for the device can be any dc voltage source within the specified  $V_{IN}$  input range. The supply should be capable of supplying sufficient current based on the maximum inductor current in boost mode operation. The input supply should be bypassed with bulk capacitors at the input of the application board to avoid ringing due to parasitic impedance of the connecting cables. A typical choice is an aluminum electrolytic capacitor of 47 to 100  $\mu$ F.

## 10.4 Layout

### 10.4.1 Layout Guidelines

The basic PCB board layout requires separation of sensitive signal and power paths. This checklist must be followed to get good performance for a well designed board.

- Use a combination of bulk capacitors and smaller ceramic capacitors with low series impedance for the IN, OUT, and  $V_{BUS}$  capacitors. Place the smaller capacitors closer to the IC to provide a low impedance path for high di/dt switching currents.
- Refer to 表 10-1 for suggested  $C_{IN}$  values. Place the input bypass capacitors,  $C_{IN}$  and  $C_{IN\_HF}$ , as close to the IN and PGND pins as possible to minimize the loop area for input switching current in buck operation. The  $C_{IN\_HF}$  capacitors should be as close as possible - see 図 10-4. The IN and PGND pins transverse the package and it is highly recommended to split  $C_{IN}$  and  $C_{IN\_HF}$  such that capacitors can be placed on either side.
- Place the output filter capacitors,  $C_{OUT}$  and  $C_{OUT\_HF}$ , as close to the OUT and PGND pins as possible to minimize the loop area for output switching current in boost operation. Refer to 表 10-1 for suggested  $C_{OUT}$  and  $C_{OUT\_HF}$  values.
- Place the current sense resistor and filter components.  $R_{SNS}$ ,  $R_{CSP}$ ,  $R_{CSN}$ , and  $C_{FLT}$ . Place the filter capacitor for the current sense signal as close to the IC CSP and CSN/BUS as possible. Use Kelvin connections between  $R_{SNS}$  through the CSP and CSN resistors and to the CSP and CSN/BUS pins to avoid creating offsets in the current sense amplifier. Avoid crossing noisy areas such as SW1 and SW2 nodes. The recommended values in 表 10-2 provide a good starting point but may require some fine adjustment to meet PPS current limit accuracy requirements. When deviating from recommended values,  $R_{CSP}$  must not be larger than 10 ohms.  $R_{CSN}$  must be 0 ohms.  $C_{FLT}$  should not be larger than 0.33  $\mu$ F.
- Place  $C_{BUS}$  between the  $R_{SNS}$  and the USB Type-C connector. See 表 10-1 for suggested  $C_{BUS}$  values. .
- Place the  $C_{IN}$ ,  $C_{OUT}$ , and  $C_{BUS}$  ground connections as close as possible to the IC with thick ground trace and/or planes on multiple layers.
- Minimize the SW1 and SW2 loop areas as these are high dv/dt nodes.
- Place the LDO\_5V bypass capacitors,  $C_{5V}$  and  $C_{5V\_HF}$  close to the IC pin, between the LDO\_5V and PGND pins. A 4.7  $\mu$ F and 0.1  $\mu$ F ceramic capacitors are typically used. LDO\_5V supplies LDO\_3V3 and LDO\_1V5 as well as the low side buck and boost MOSFETs.
- Place the LDO\_3V3 bypass capacitors,  $C_{3V3}$  and  $C_{3V3\_HF}$  close to the IC pin, between the LDO\_3V3 and AGND pins. A 4.7  $\mu$ F and 0.1  $\mu$ F ceramic capacitors are typically used. LDO\_3V3 supplies the analog IO circuits.
- Place the LDO\_1V5 bypass capacitors,  $C_{1V5}$  and  $C_{1V5\_HF}$  close to the IC pin, between the LDO\_1V5 and AGND pins. A 4.7  $\mu$ F and 0.1  $\mu$ F ceramic capacitors are typically used. LDO\_3V3 supplies the Cortex M0 and digital circuits.
- Place the BOOT1 bootstrap capacitor close to the IC and connect directly to the BOOT1 to SW1 pins. For EMI mitigation, a series resistor  $R_{BOOT1}$  may be added.
- Place the BOOT2 bootstrap capacitor close to the IC and connect directly to the BOOT2 to SW2 pins. For EMI mitigation, a series resistor  $R_{BOOT2}$  may be added.
- Bypass the TVSP pin to PGND with a low ESR ceramic capacitor,  $C_{TVSP}$  located close to the IC. A 0.1  $\mu$ F ceramic capacitor is typically used.  $R_{TVSP\_DAMP}$  and  $C_{TVSP\_DAMP}$  should be added in parallel close to  $C_{TVSP}$ . 10  $\Omega$  and 0.47  $\mu$ F are recommended values.

- Use care to separate the power and signal paths so that no power or switching current flows through the AGND connections which can either corrupt the USB PD modem or GPIO signals. The PGND and AGND traces can be connected near the AGND pin.
- USB data lines, DP and DM should be differentially routed between the IC pins and USB connector. Impedance control is based on the PCB stack-up. 90  $\Omega$  differential is recommended. Route the DP and DM USB signals using a minimum of vias and corners which will reduce signal reflections and impedance changes. When a via must be used, increase the clearance size around it to minimize its capacitance. Each via introduces discontinuities in the signal's transmission line and increases the chance of picking up interference from the other layers of the board. Be careful when designing test points on twisted pair lines; through-hole pins are not recommended. When it becomes necessary to turn 90°, use two 45° turns or an arc instead of making a single 90° turn. This reduces reflections on the signal traces by minimizing impedance discontinuities. Avoid stubs on the high-speed USB signals because they cause signal reflections. If a stub is unavoidable, then the stub should be less than 200 mm.
- CC lines should be routed with a 10-mil trace to ensure the needed current for supporting powered Type-C cables through VCONN. For more information on VCONN refer to the Type-C specifications. For the 330 pF CC capacitor GND pins use a 16-mil trace if possible.
- GPIO signals can be fanned out on the top or bottom layer using either a 8-mil or 10-mil trace.

#### 10.4.2 Layout Example

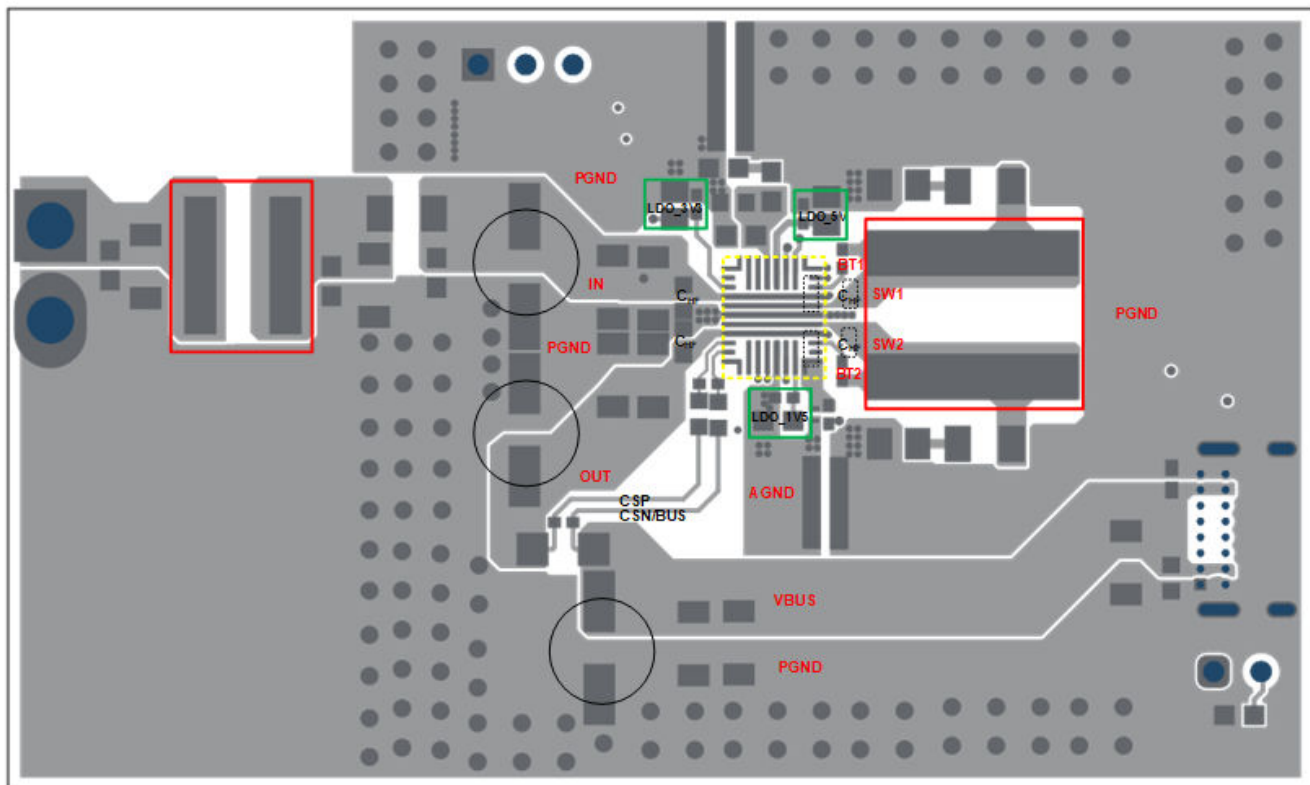


図 10-39. TPS25772-Q1 Power Stage Layout

## 11 Device and Documentation Support

### 11.1 Documentation Support

#### 11.1.1 Related Documentation

Please visit TI homepage for latest technical document including application notes, user guides, and reference designs.

IC Package Thermal Metrics application report, [Semiconductor and IC Package Thermal Metrics](#).

### 11.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、[ti.com](#) のデバイス製品フォルダを開いてください。「更新の通知を受け取る」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

### 11.3 サポート・リソース

[TI E2E™ サポート・フォーラム](#)は、エンジニアが検証済みの回答と設計に関するヒントをエキスパートから迅速かつ直接得ることができる場所です。既存の回答を検索したり、独自の質問をしたりすることで、設計に必要な支援を迅速に得ることができます。

リンクされているコンテンツは、該当する貢献者により、現状のまま提供されるものです。これらは TI の仕様を構成するものではなく、必ずしも TI の見解を反映したものではありません。TI の[使用条件](#)を参照してください。

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### 11.5 静電気放電に関する注意事項



この IC は、ESD によって破損する可能性があります。テキサス・インスツルメンツは、IC を取り扱う際には常に適切な注意を払うことを推奨します。正しい取り扱いおよび設置手順に従わない場合、デバイスを破損するおそれがあります。

ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずかに変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

### 11.6 用語集

[テキサス・インスツルメンツ用語集](#)

この用語集には、用語や略語の一覧および定義が記載されています。

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable part number             | Status<br>(1) | Material type<br>(2) | Package   Pins     | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|-----------------------------------|---------------|----------------------|--------------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">TPS25772CAQRQLRQ1</a> | Active        | Production           | VQFN-HR (RQL)   29 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | TPS25772<br>CA      |
| TPS25772CAQRQLRQ1.A               | Active        | Production           | VQFN-HR (RQL)   29 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | TPS25772<br>CA      |
| <a href="#">TPS25772CQRQLRQ1</a>  | Active        | Production           | VQFN-HR (RQL)   29 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | TPS25772<br>C       |
| TPS25772CQRQLRQ1.A                | Active        | Production           | VQFN-HR (RQL)   29 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | TPS25772<br>C       |
| <a href="#">TPS25772DQRQLRQ1</a>  | Active        | Production           | VQFN-HR (RQL)   29 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | T25772<br>D         |
| TPS25772DQRQLRQ1.A                | Active        | Production           | VQFN-HR (RQL)   29 | 3000   LARGE T&R      | Yes         | NIPDAU                               | Level-2-260C-1 YEAR               | -40 to 125   | T25772<br>D         |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

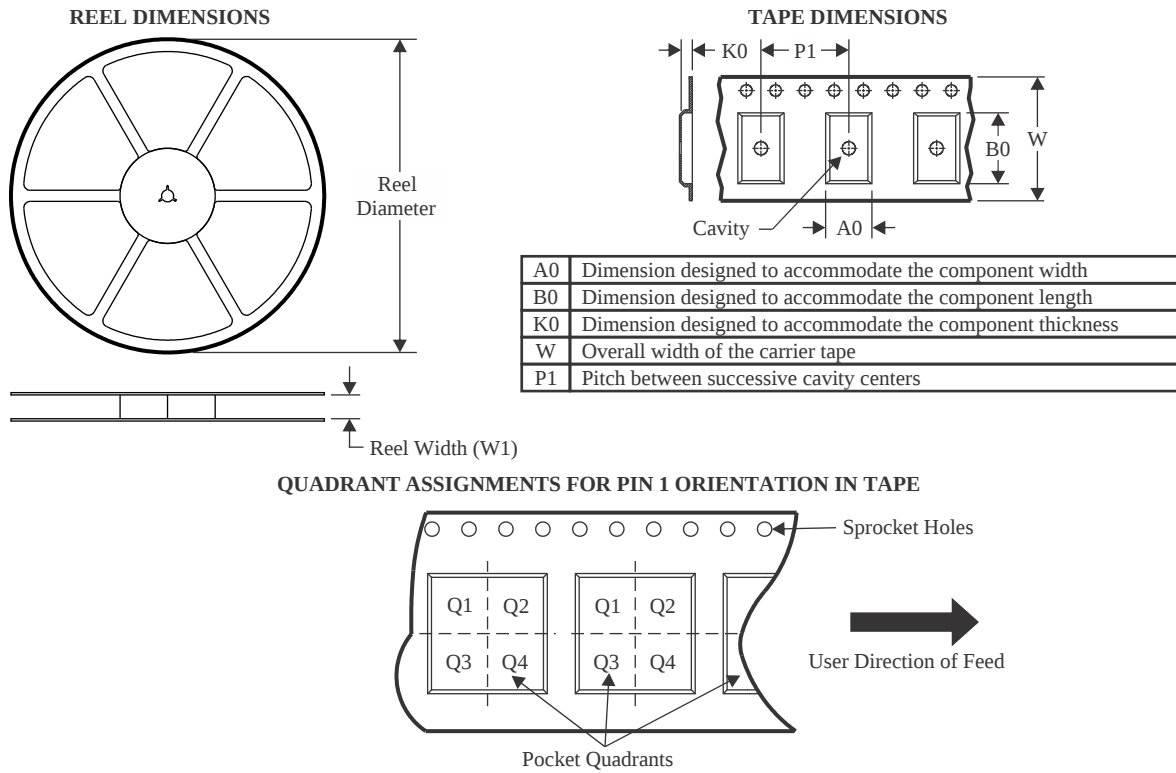
<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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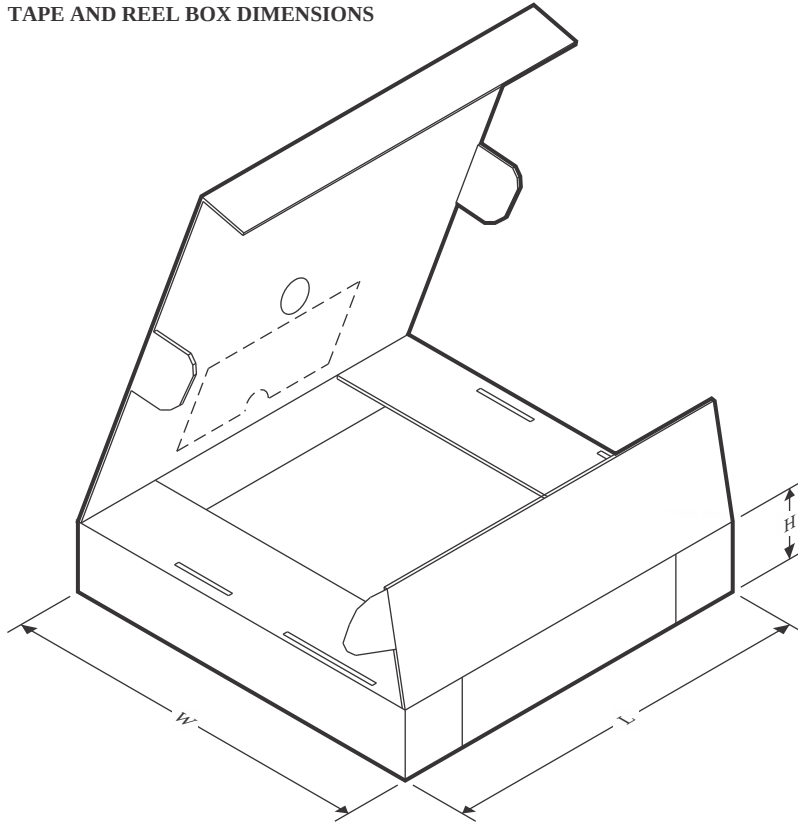
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

| Device            | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-------------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPS25772CAQRQLRQ1 | VQFN-HR      | RQL             | 29   | 3000 | 330.0              | 12.4               | 5.3     | 6.3     | 1.15    | 8.0     | 12.0   | Q2            |
| TPS25772CQRQLRQ1  | VQFN-HR      | RQL             | 29   | 3000 | 330.0              | 12.4               | 5.3     | 6.3     | 1.15    | 8.0     | 12.0   | Q2            |
| TPS25772DQRQLRQ1  | VQFN-HR      | RQL             | 29   | 3000 | 330.0              | 12.4               | 5.3     | 6.3     | 1.15    | 8.0     | 12.0   | Q2            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device           | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPS25772CAQRQRQ1 | VQFN-HR      | RQL             | 29   | 3000 | 367.0       | 367.0      | 35.0        |
| TPS25772CQRQRQ1  | VQFN-HR      | RQL             | 29   | 3000 | 367.0       | 367.0      | 35.0        |
| TPS25772DQRQRQ1  | VQFN-HR      | RQL             | 29   | 3000 | 367.0       | 367.0      | 35.0        |

## GENERIC PACKAGE VIEW

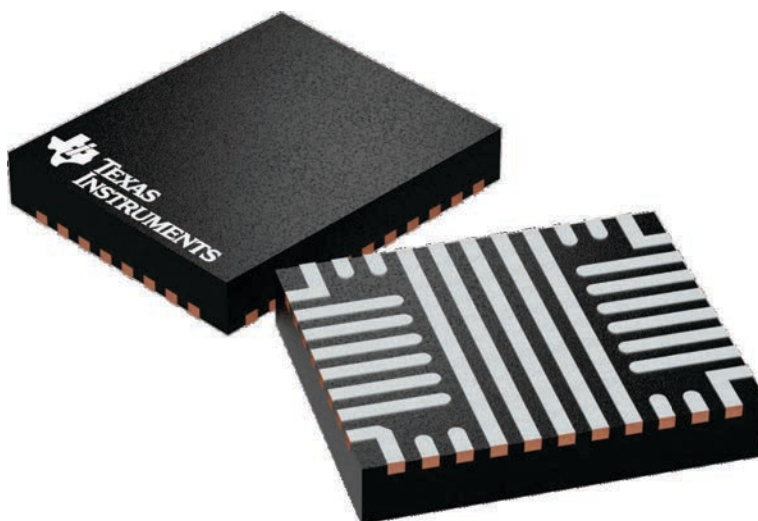
**RQL 29**

**VQFN-HR - 1 mm max height**

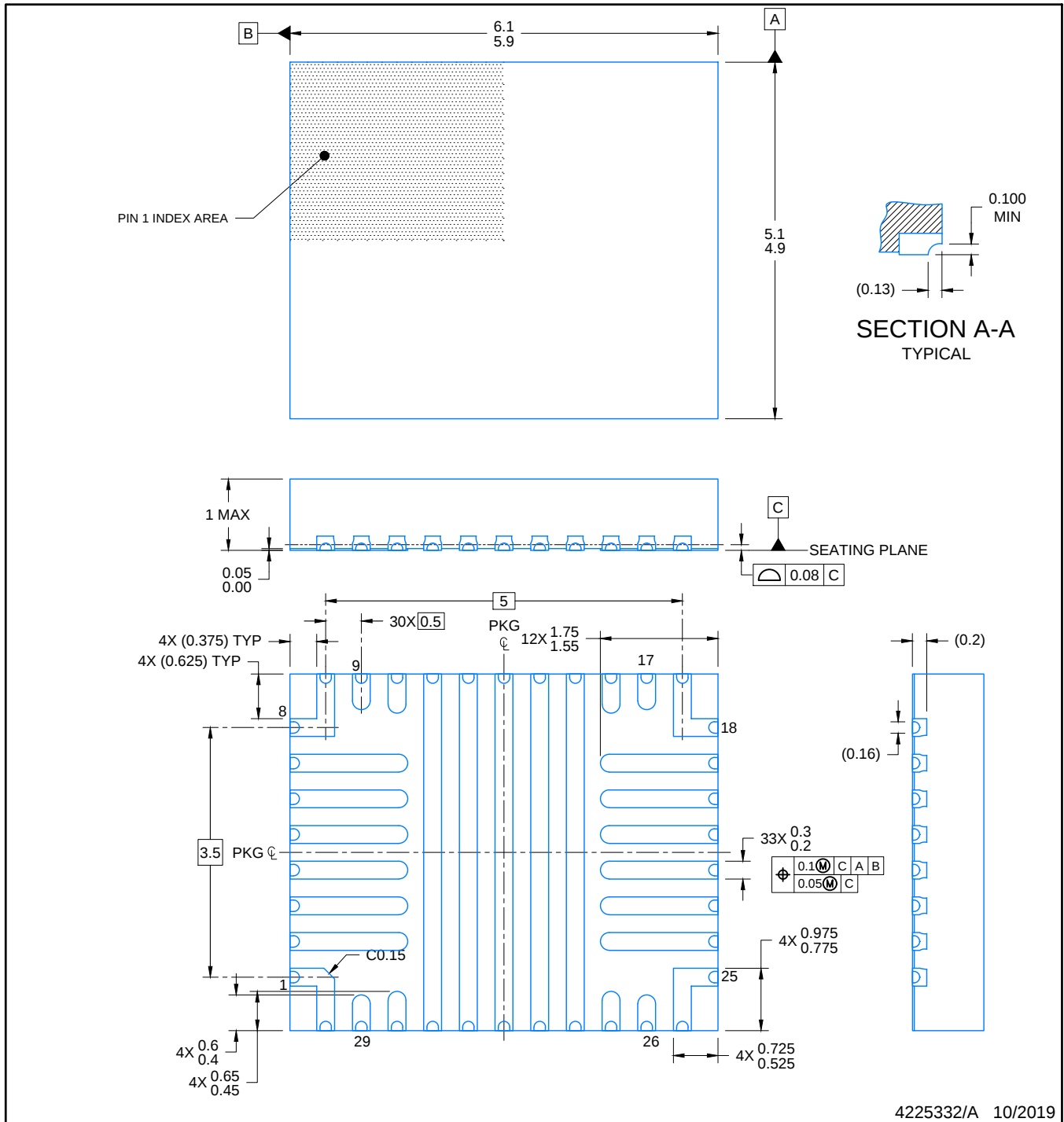
5 x 6, 0.5 mm pitch

VERY THIN QUAD FLATPACK-HotRod

This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



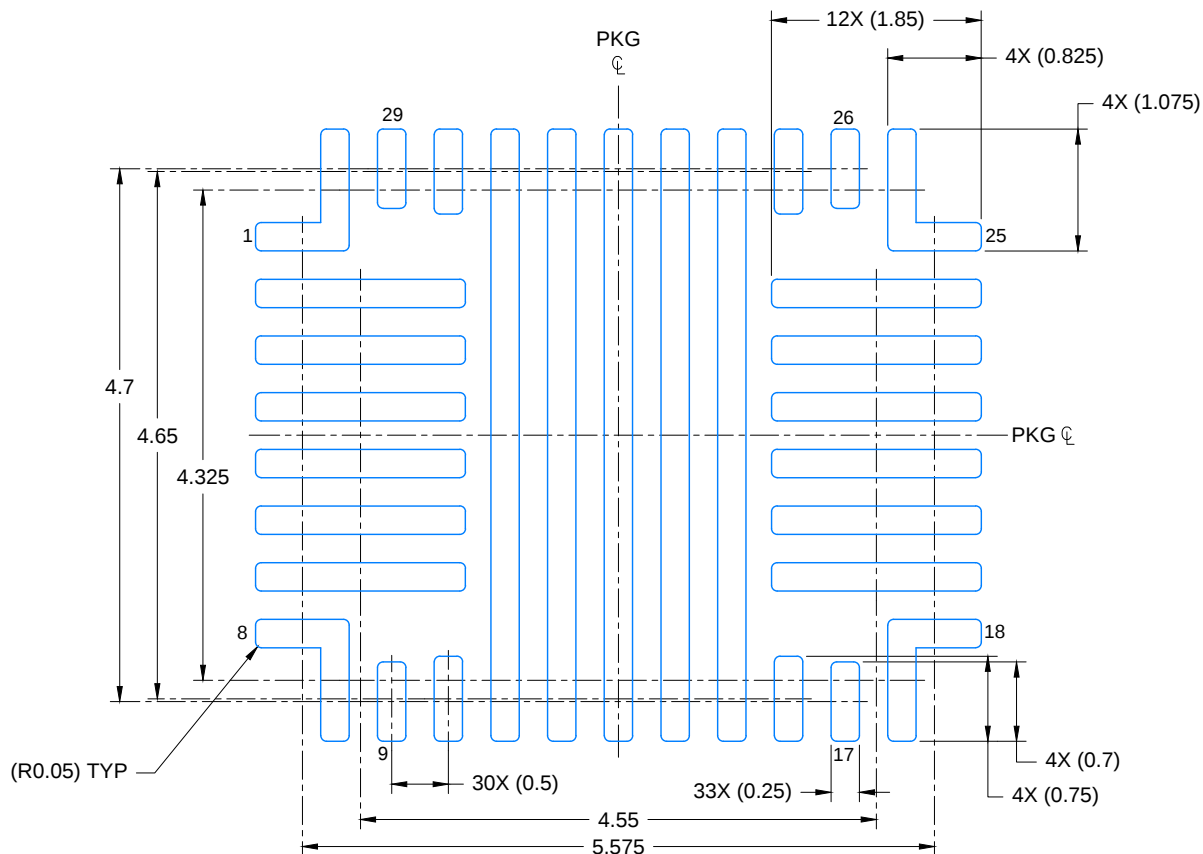
4225475/A



4225332/A 10/2019

## NOTES:

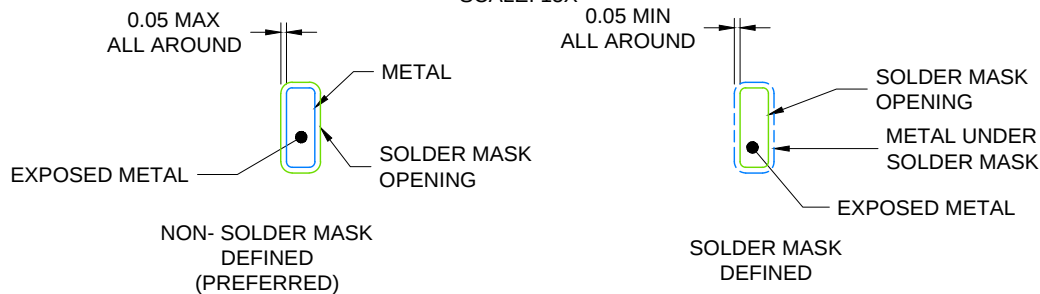
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.



## LAND PATTERN EXAMPLE

EXPOSED METAL SHOWN

SCALE: 15X



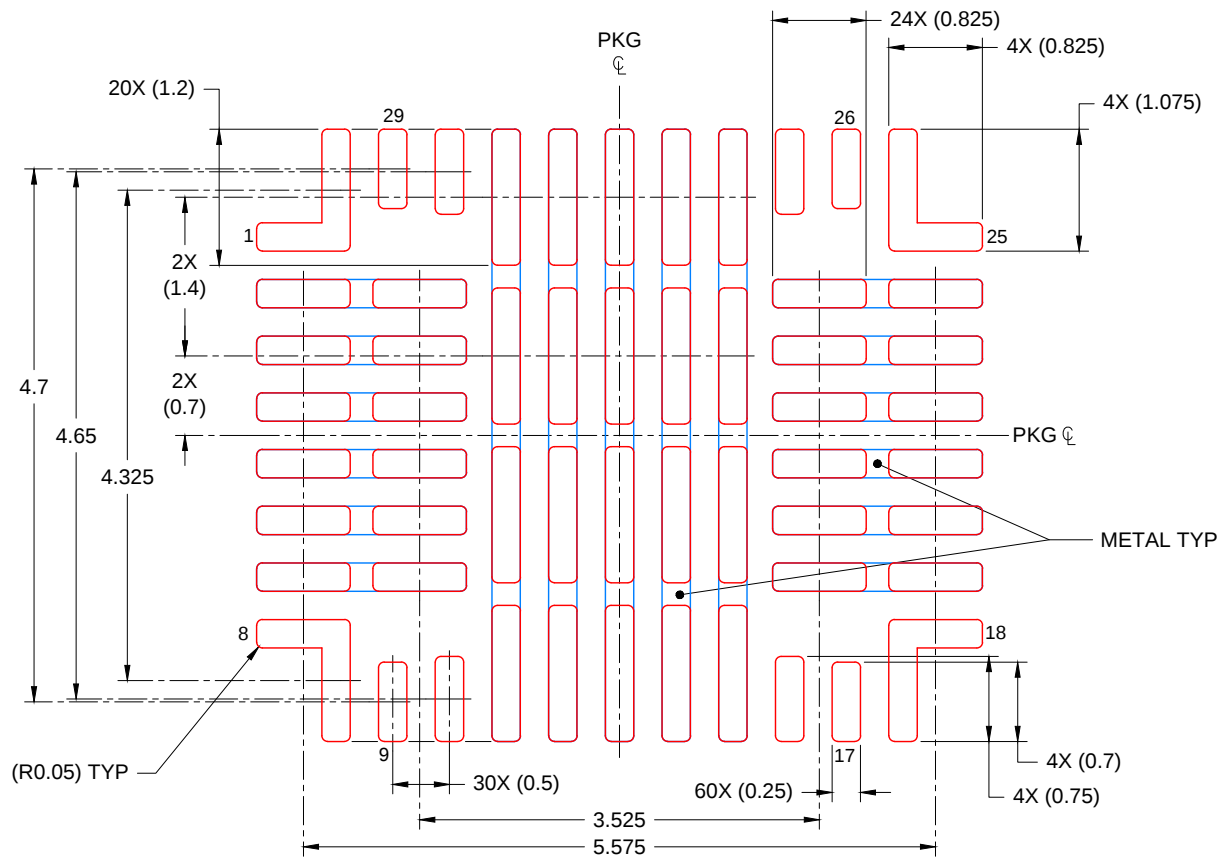
## SOLDER MASK DETAILS

NOT TO SCALE

4225332/A 10/2019

NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/sluea271](http://www.ti.com/lit/sluea271)).
4. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



## SOLDER PASTE EXAMPLE BASED ON 0.1 mm THICK STENCIL

PADS 2-7 & 19-24: 89%

PADS 11-15: 88%

SCALE: 15X

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NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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